



# State-of-the-Art Superconducting RF Technology for Accelerators

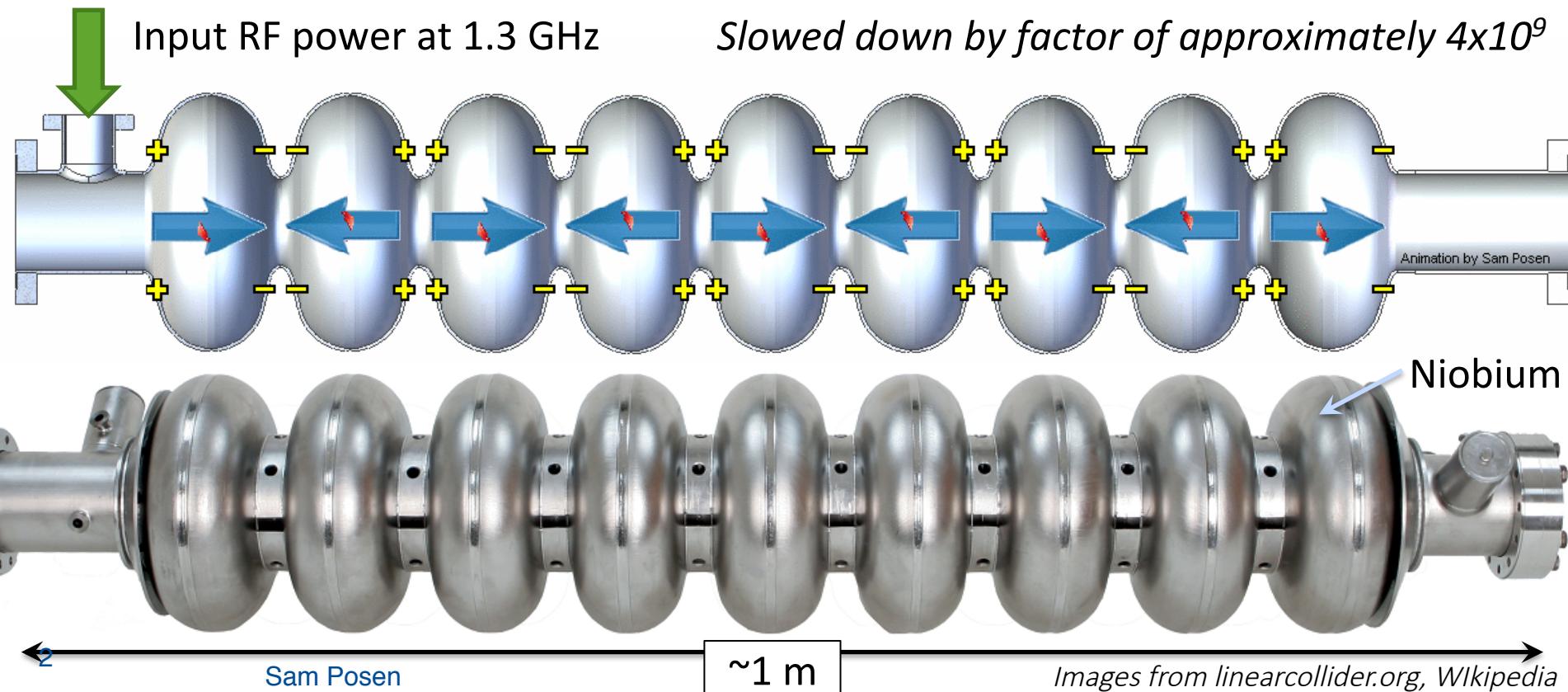
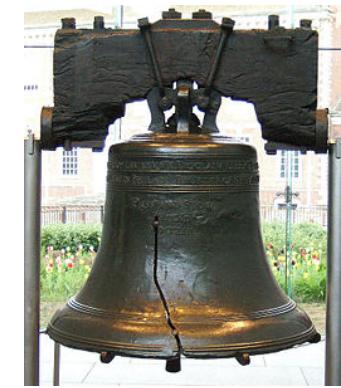
Sam Posen

Fermilab Colloquium

15 February 2017

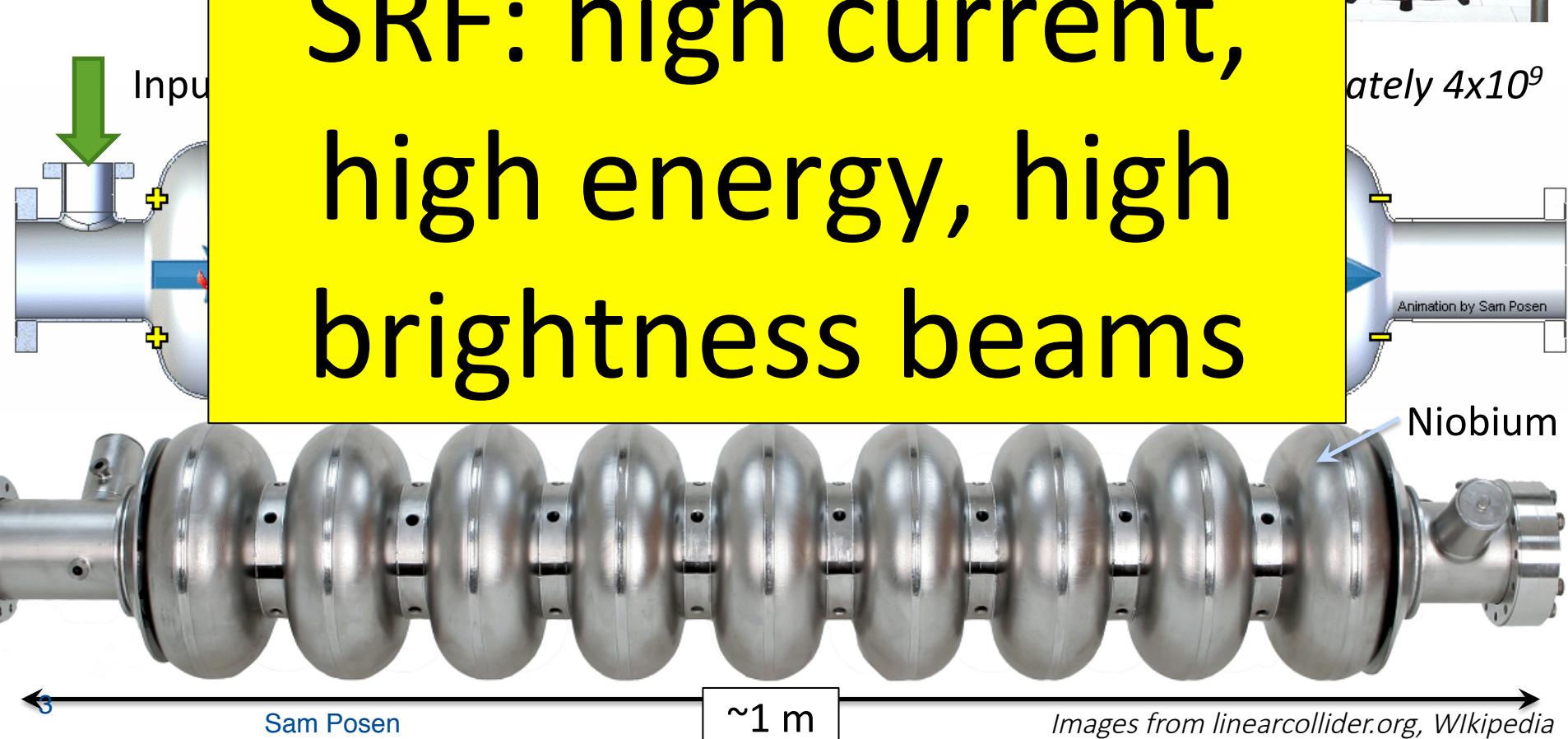
# Particle Acceleration via SRF Cavities

- Superconducting radiofrequency (SRF) cavities
- High quality EM resonators: Typical  $Q_0 > 10^{10}$
- Over billions of cycles, large electric field generated
- Particle beam gains energy as it passes through

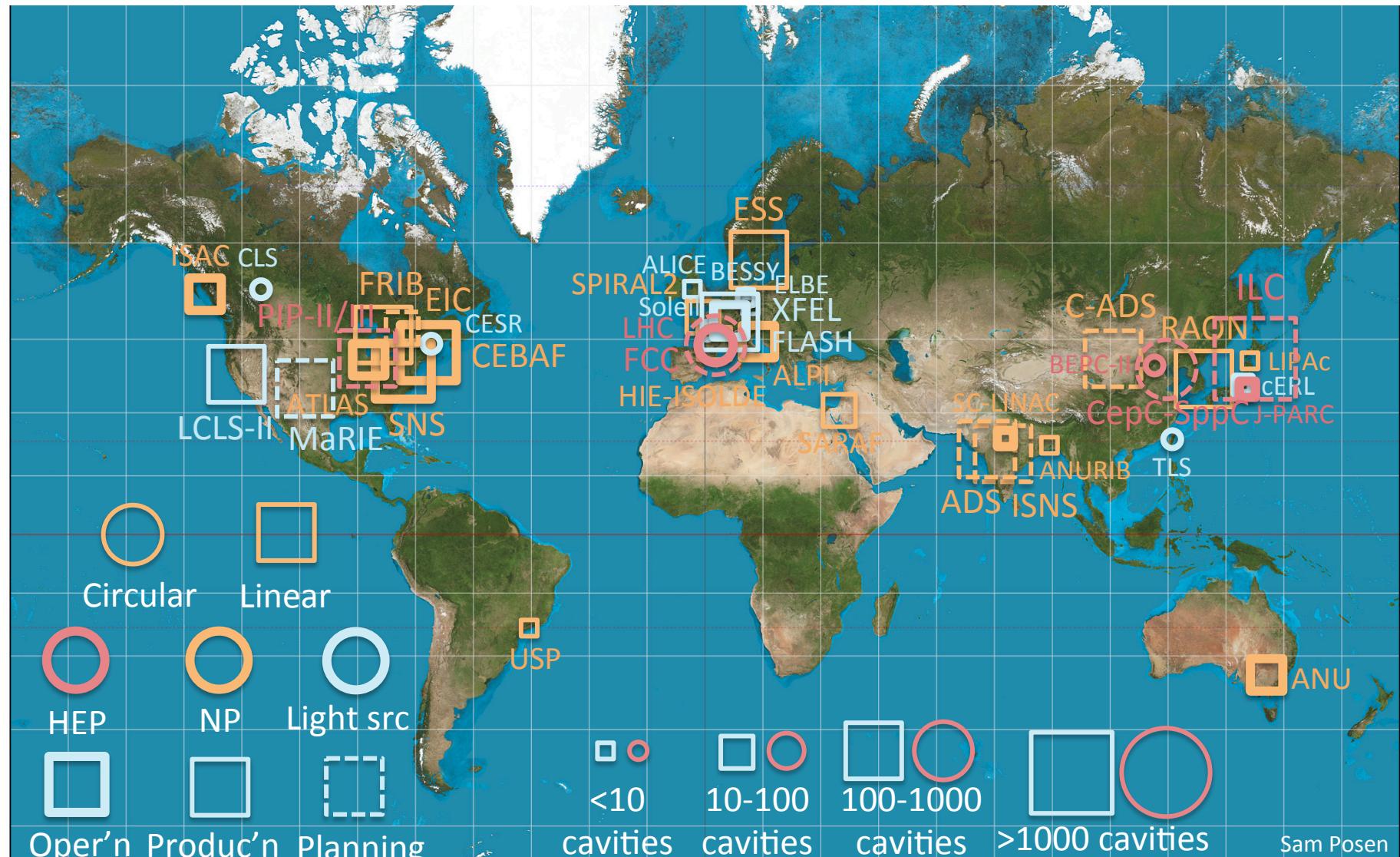


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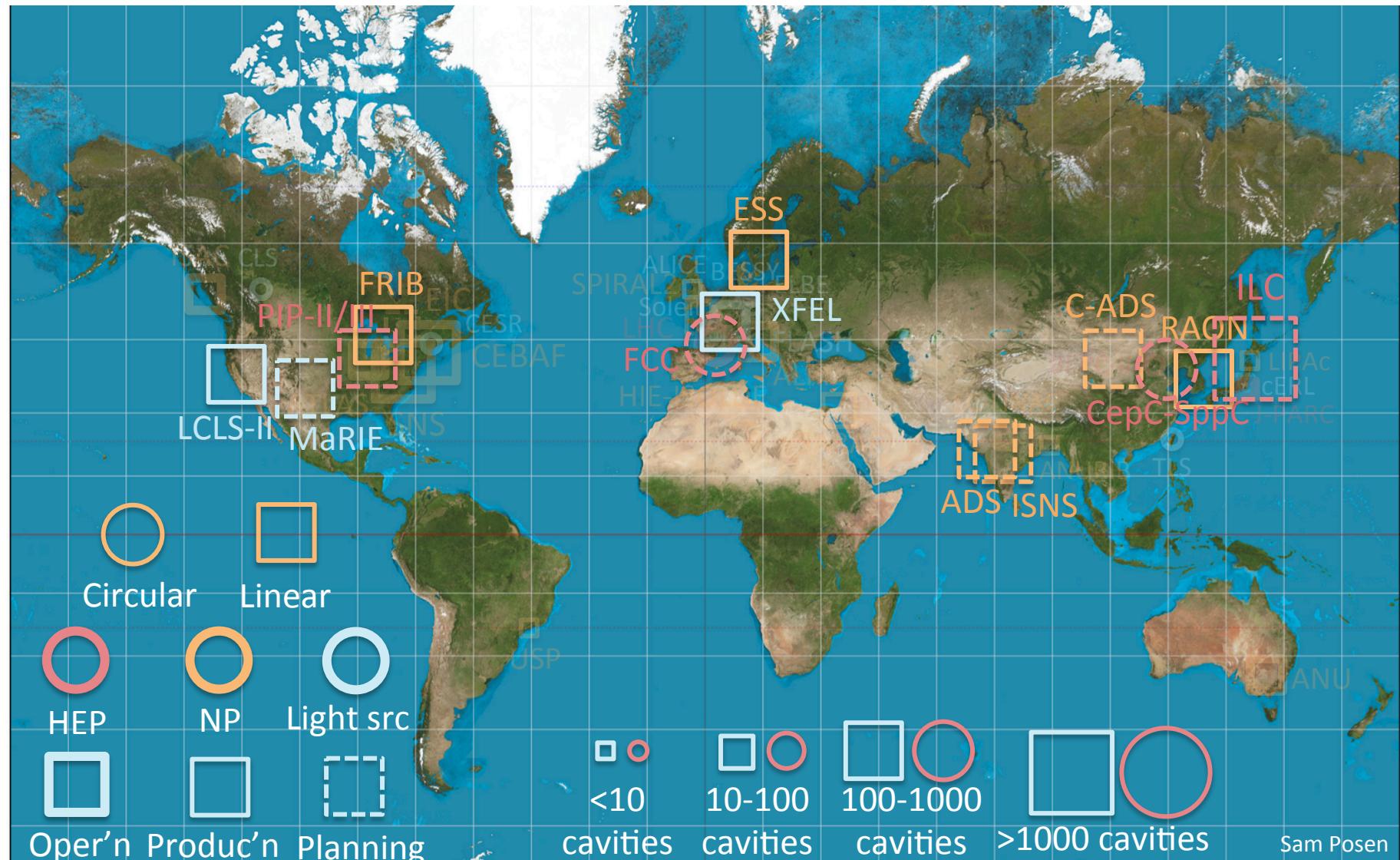
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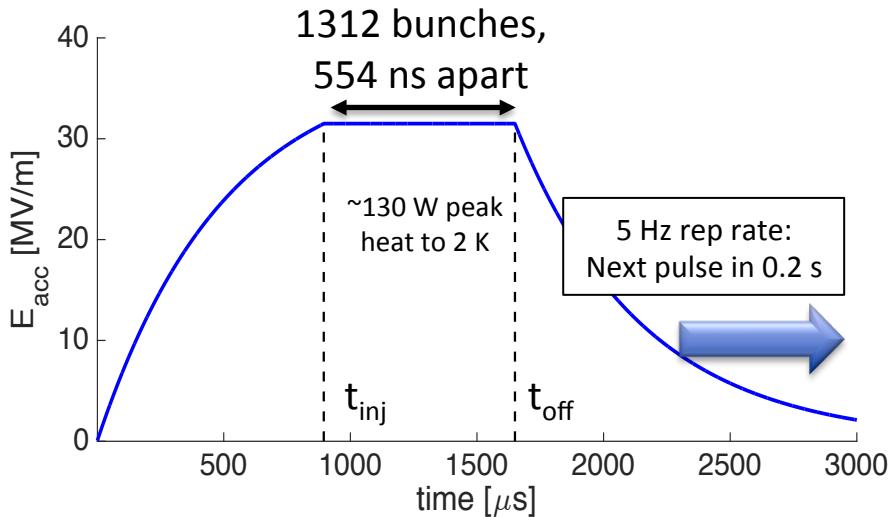
# SRF Accelerators Around the World



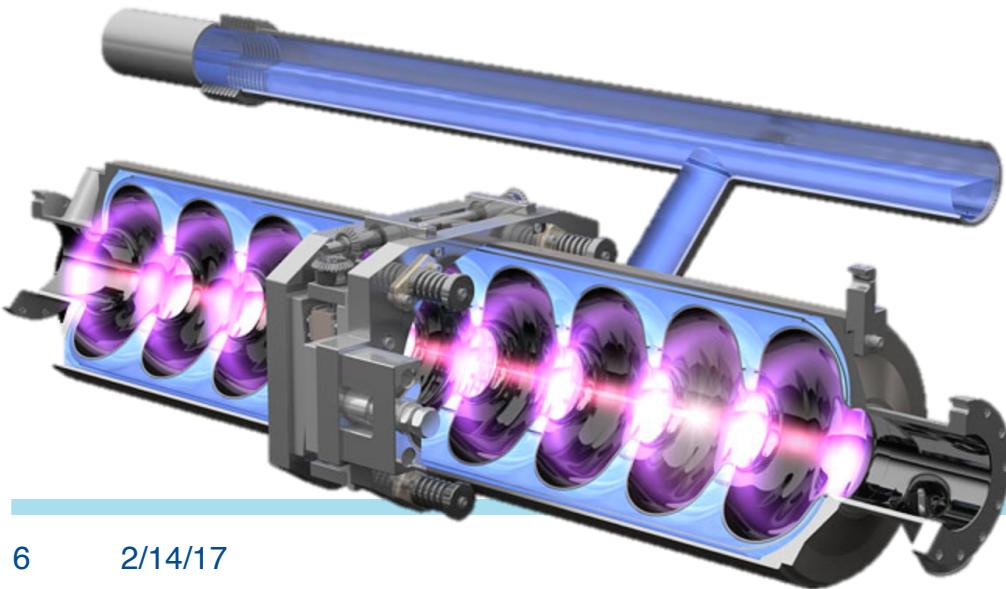
# SRF Accelerators Around the World



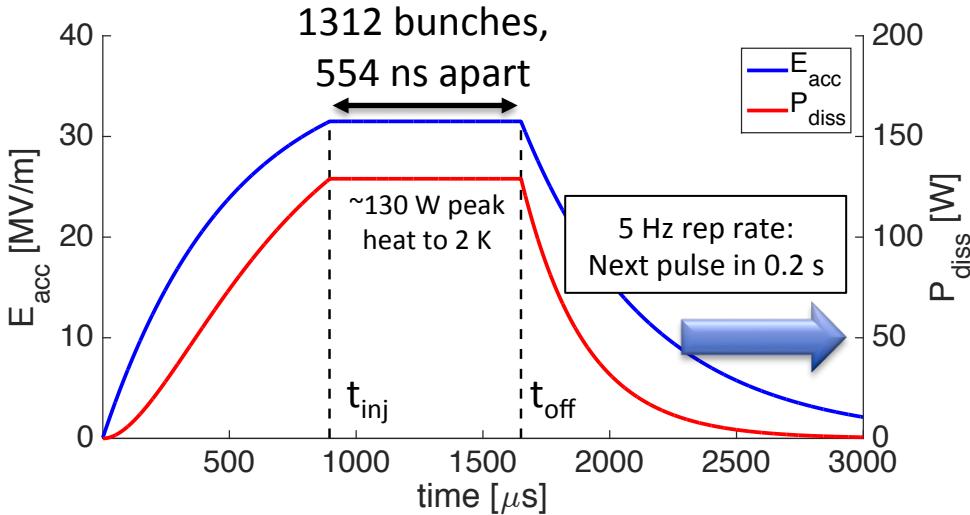
# Duty Factor



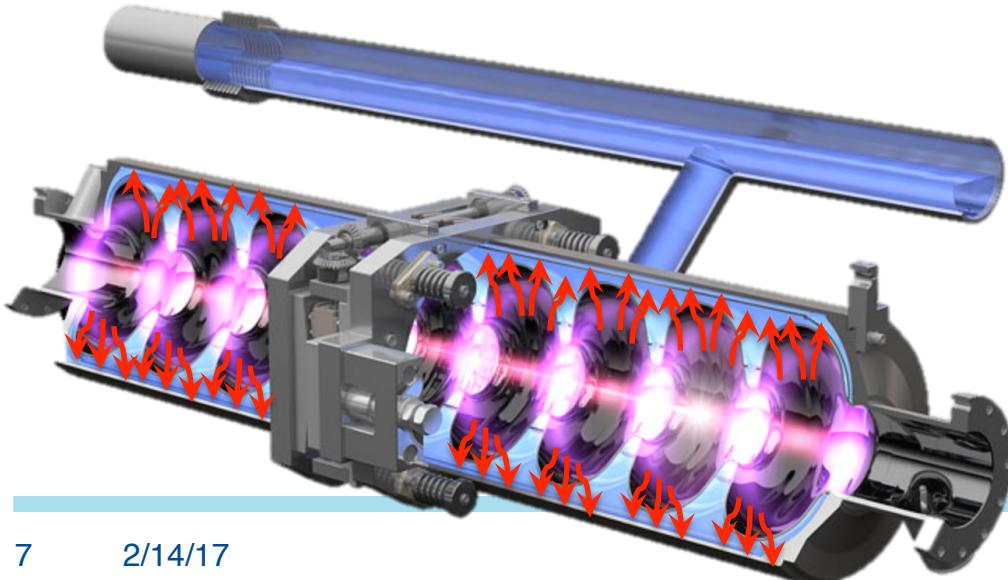
ILC (pulsed, <1% DF)  
LCLS-II (CW, 100%DF)



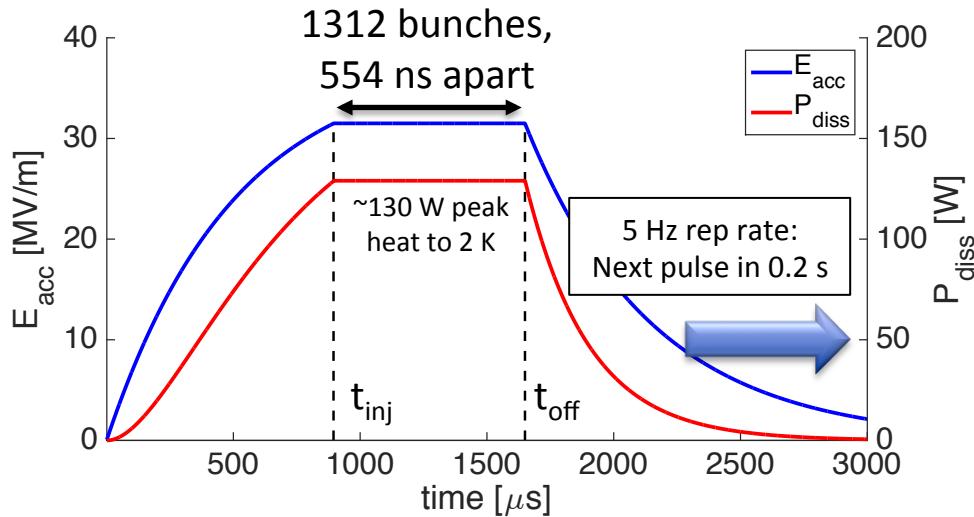
# Duty Factor and Cryogenic Costs



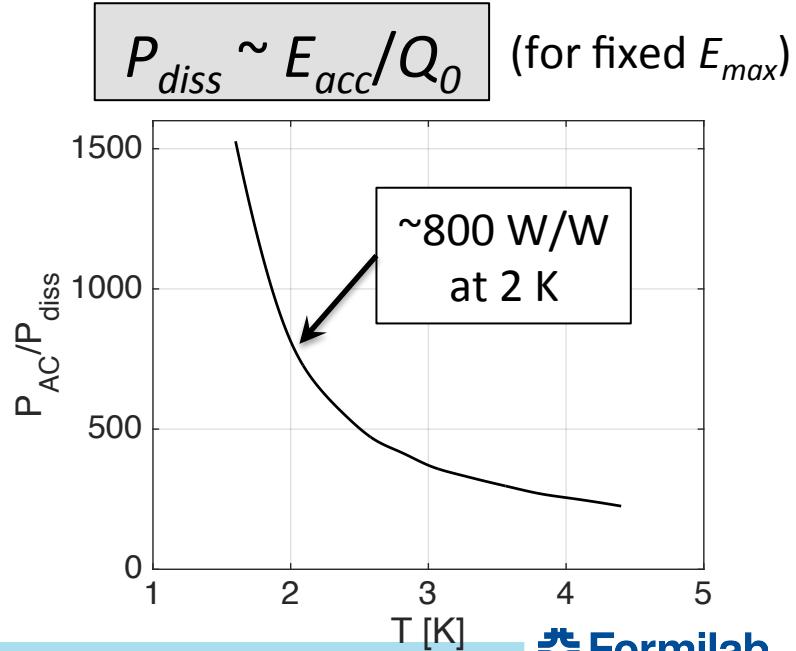
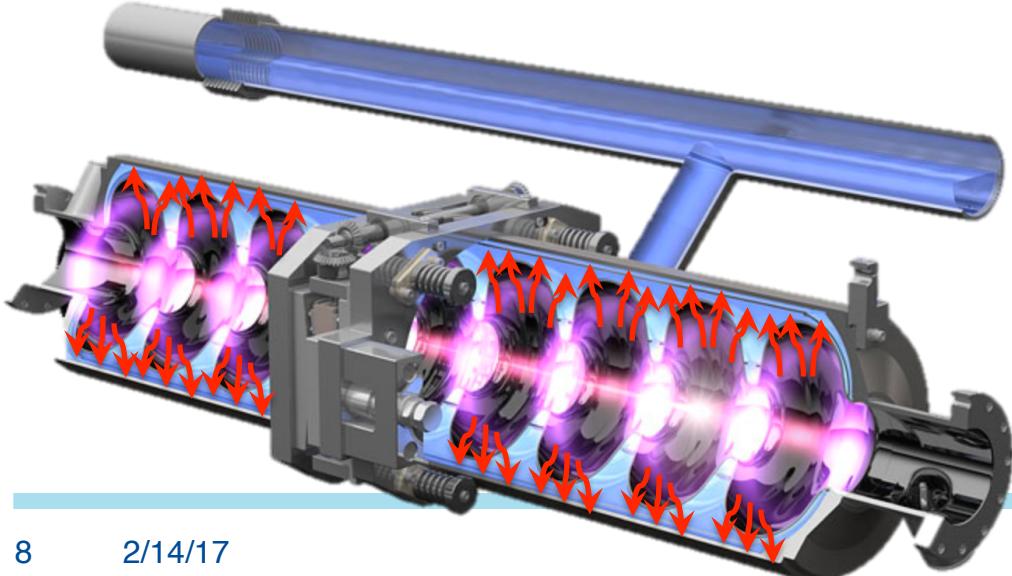
ILC (pulsed, <1% DF) ~0.5 W average per cavity  
LCLS-II (CW, 100%DF) ~10 W average per cavity



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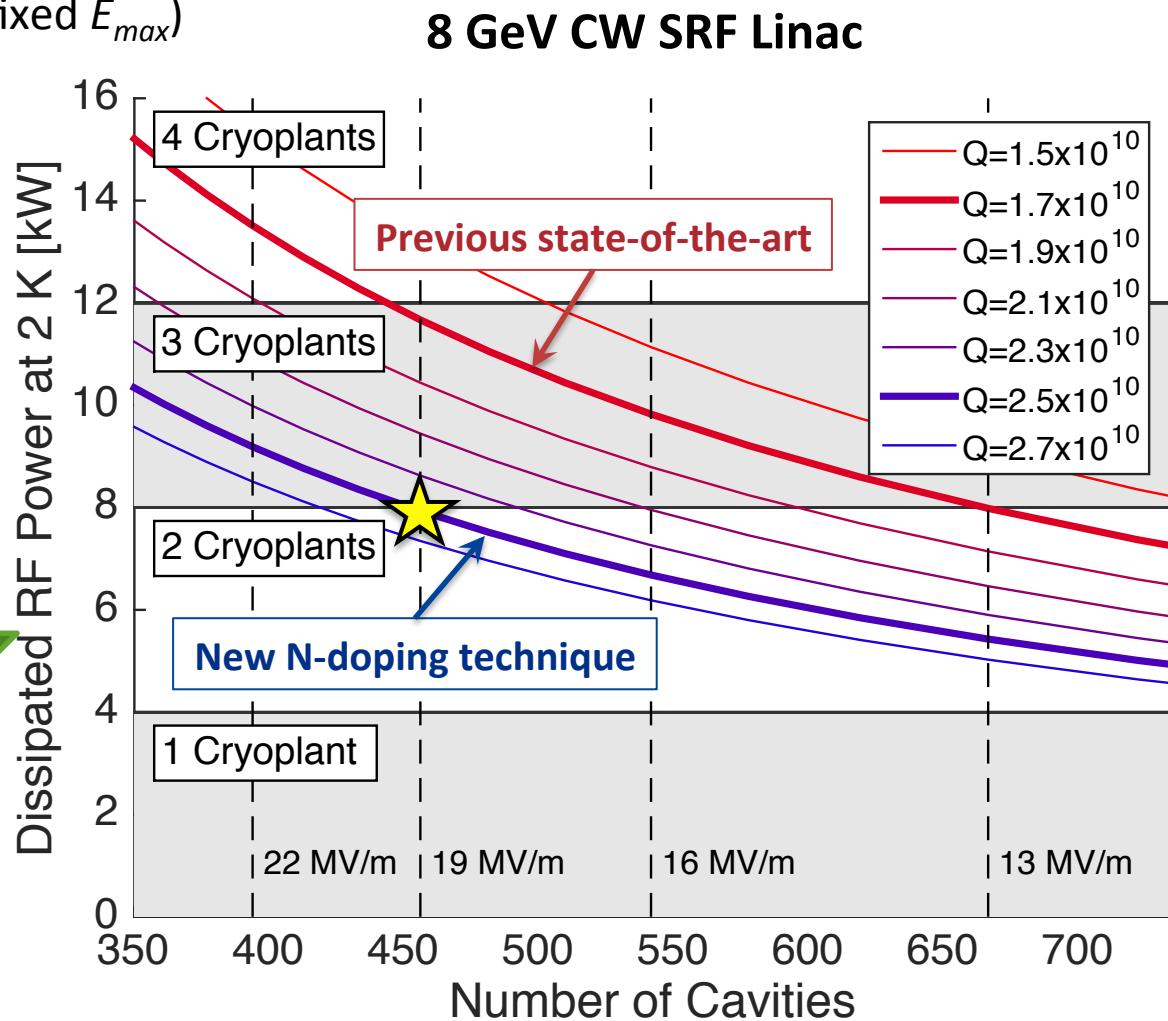
# $Q_0 \rightarrow$ Cryogenic Infrastructure, Operating Cost

$$P_{diss} \sim E_{acc}/Q_0$$

(for fixed  $E_{max}$ )



Lower cost



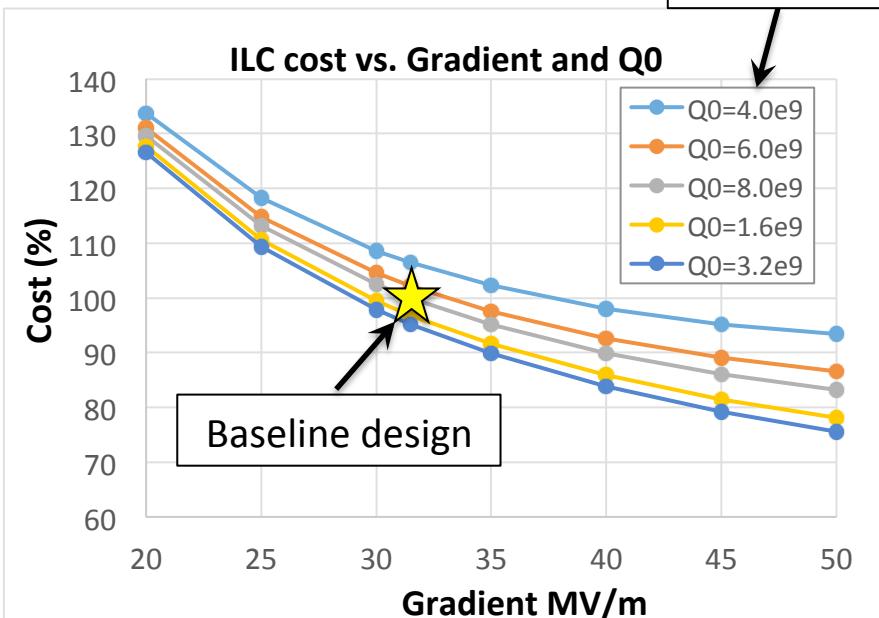
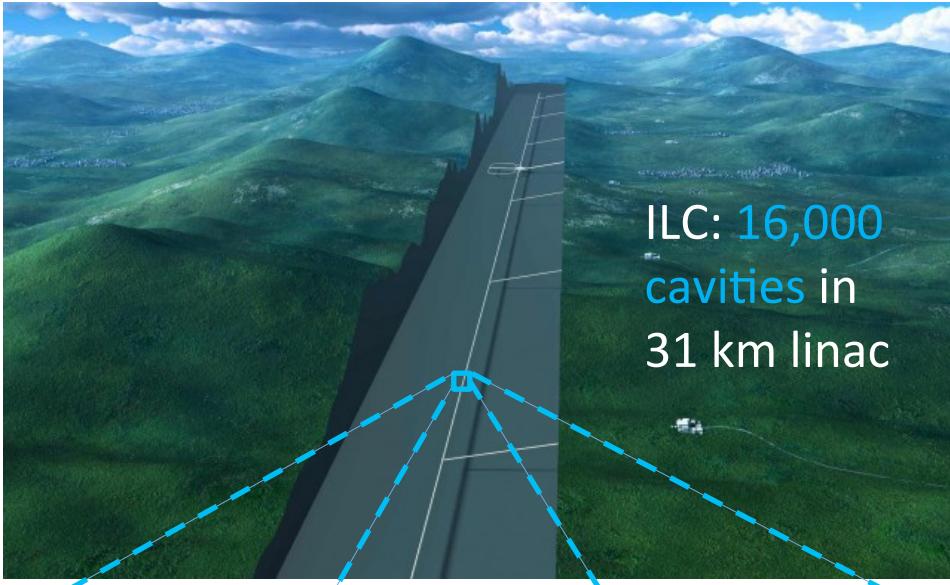
Lower cost

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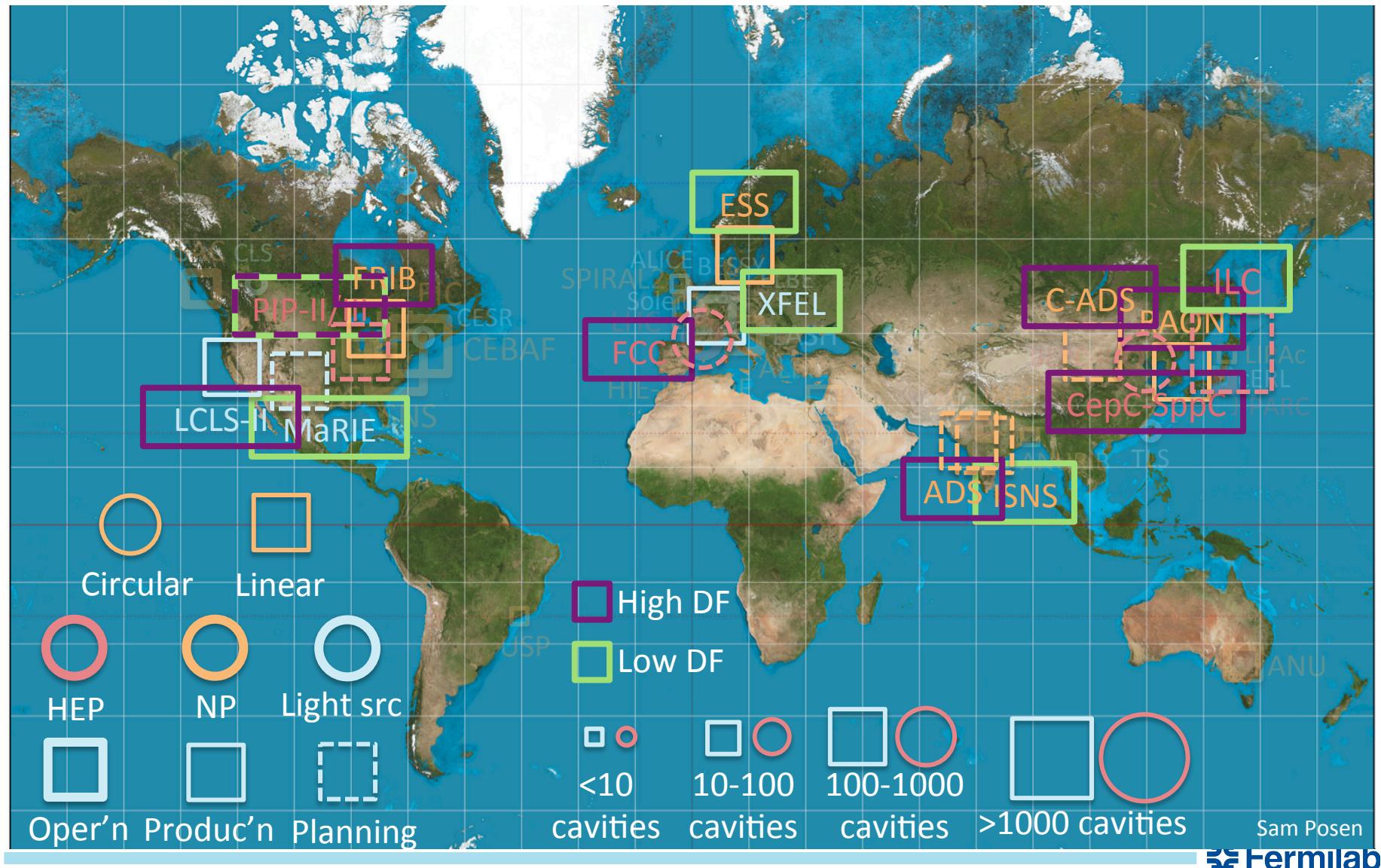
Above is a rough calculation for LCLS-II upgrade  
(from me, not to be considered official numbers from project)

# Gradient → Length for Linear Accelerator

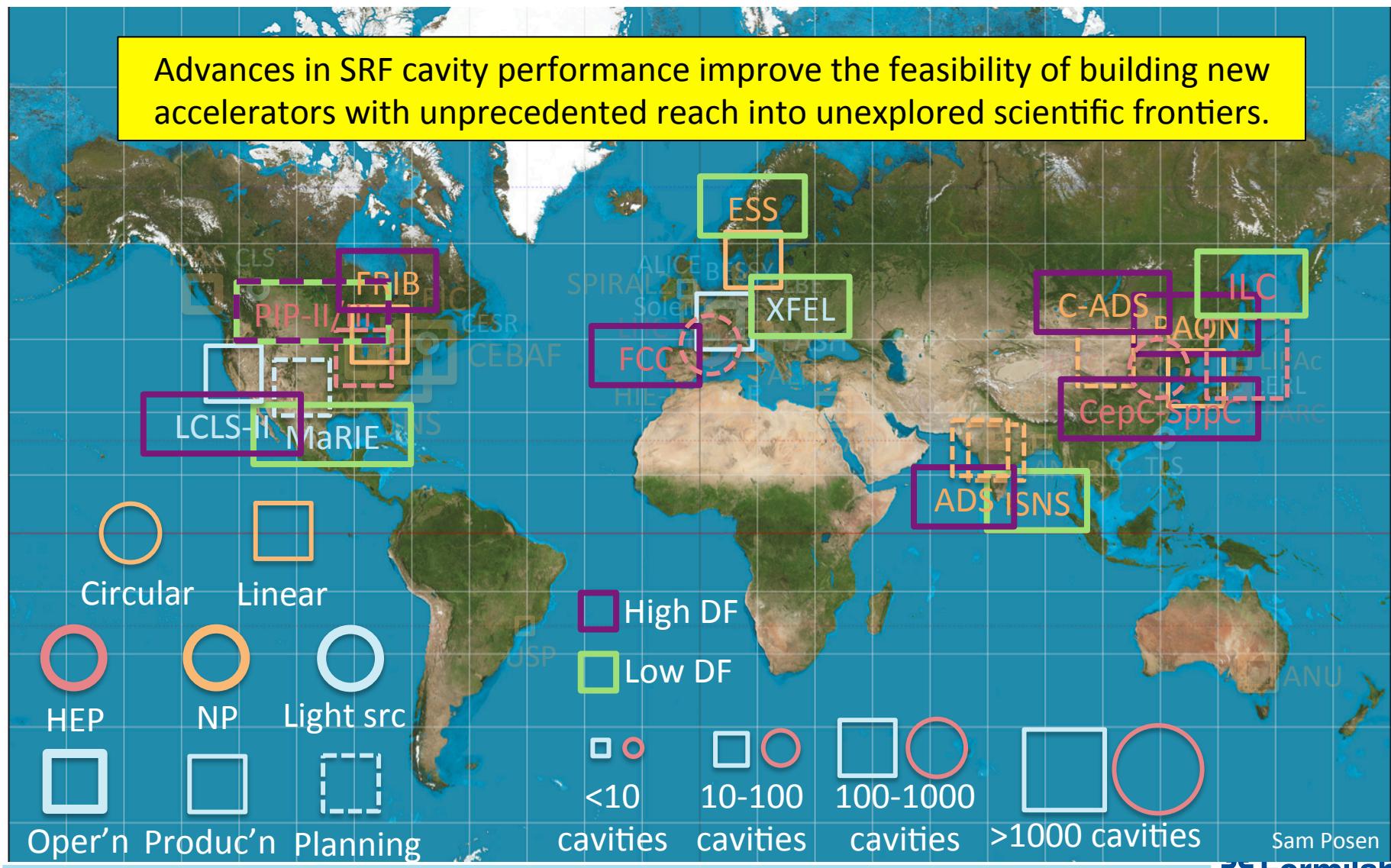
$Q_0$  also important!



# Motivation State-of-the-Art SRF Technology



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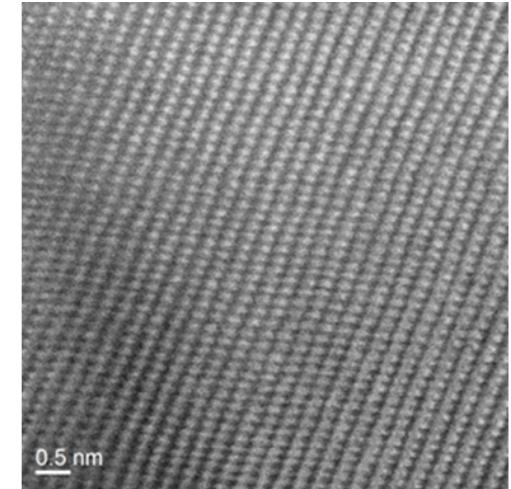


# Outline

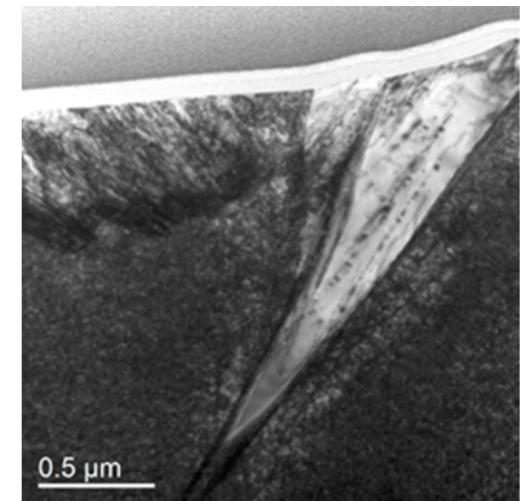
- High  $Q_0$  (medium  $E_{acc}$ )
  - Nitrogen doping
  - Flux expulsion
- High  $E_{acc}$  and high  $Q_0$ 
  - Nitrogen infusion
  - Nb<sub>3</sub>Sn
  - Plasma cleaning



ILC cryomodule with record average gradient for FAST facility



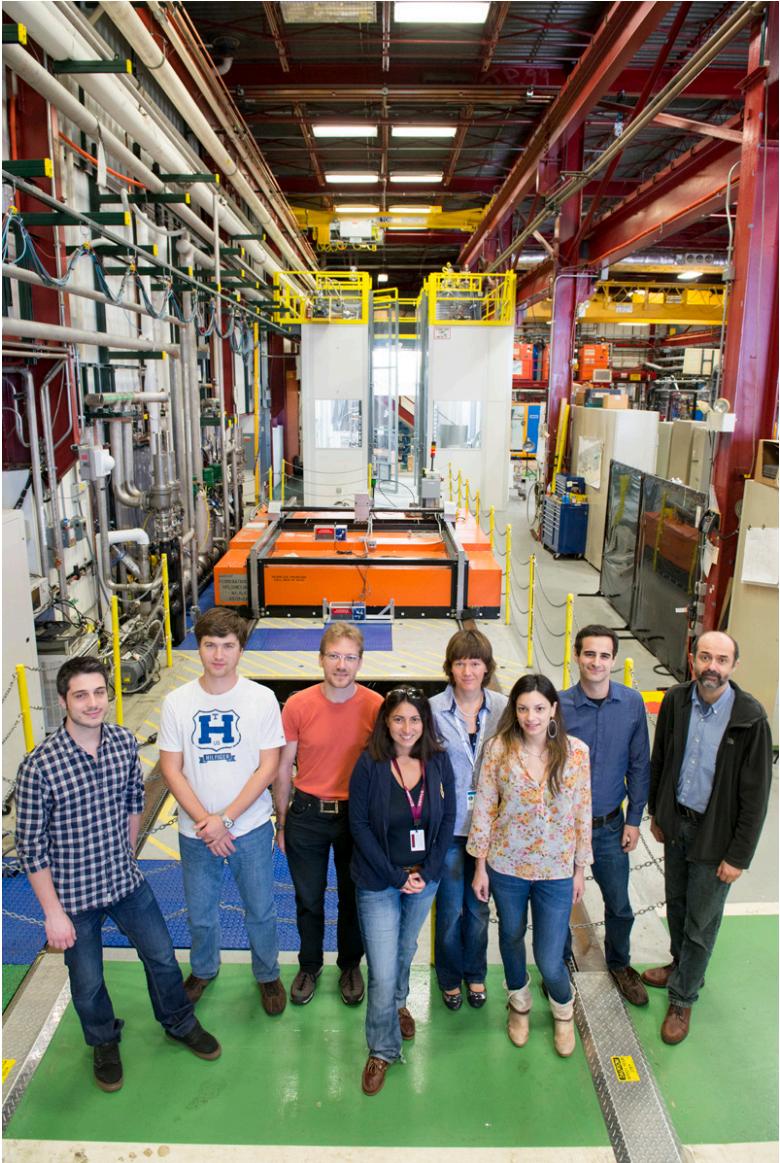
Aberration-corrected STEM image of the near-surface of Nb cavity - Y. Trenikhina



Niobium near-surface after the first step of nitrogen doping - Y. Trenikhina

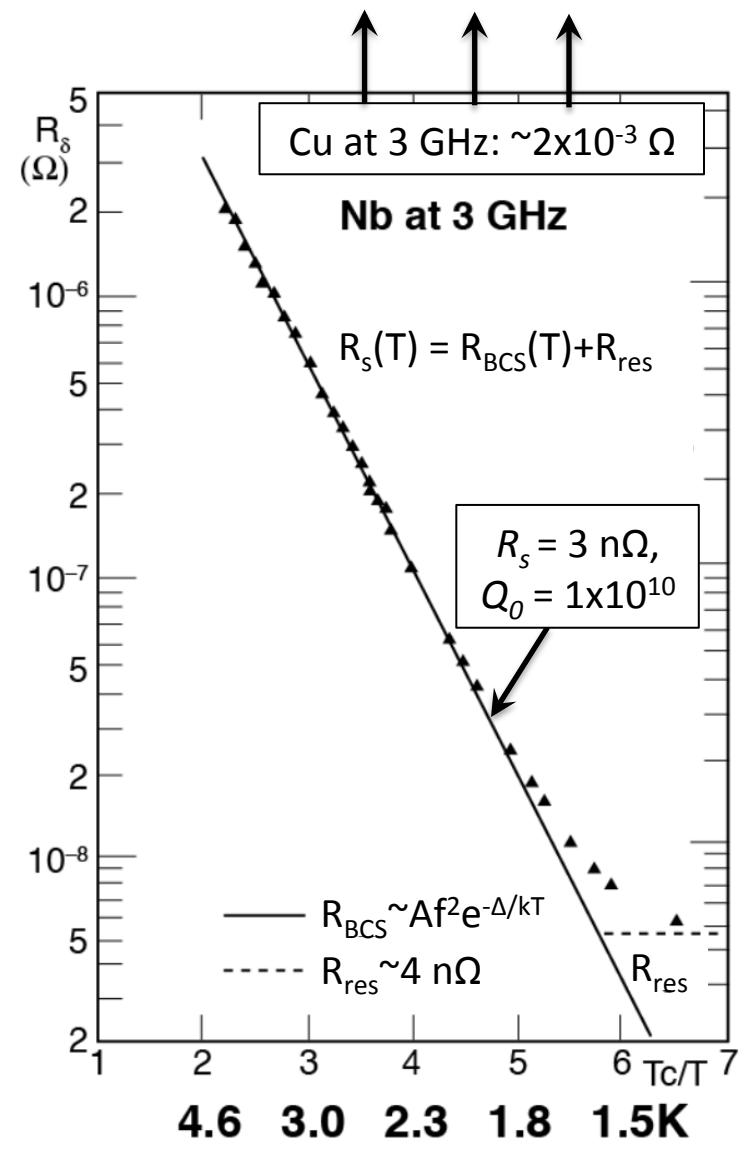
# Team Effort

- Results shown here are due to many hardworking people
- Thanks to SRF department and Fermilab LCLS-II team for contributions

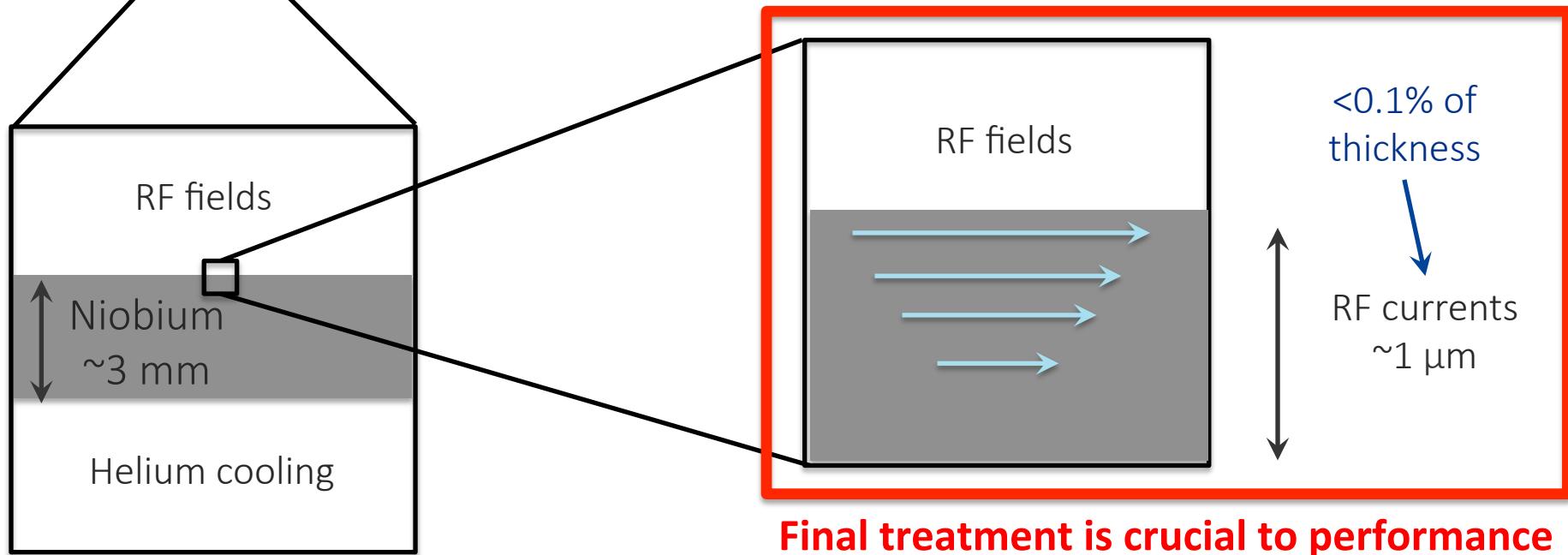


# Note on $Q_0$ and BCS/Residual Surface Resistance

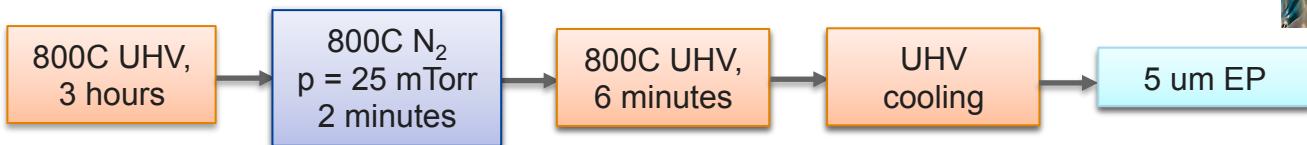
- $Q_0$  and  $R_s$  are related by a geometrical constant  $G$ :  $Q_0 = G/R_s$
- They measure efficiency
- Heat dissipated in the walls of the cavity:  $P_{diss} \sim R_s \sim Q_0^{-1}$
- $R_s$  decreases exponentially with decreasing  $T/T_c$  but it saturates at low  $T$ : residual resistance  $R_{res}$
- Generally we decompose  $R_s$  into temperature dependent  $R_{BCS}(T)$  and temperature independent  $R_{res}$
- Cavities often operate at  $\sim 2$  K where both are significant



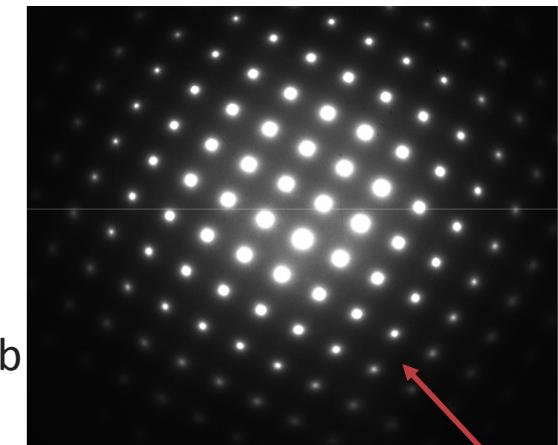
# Treatment for Enhancement of RF Penetration Layer



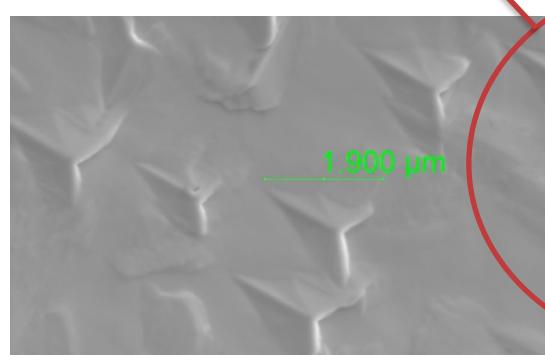
# N-doping treatment



Y. Trenikhina et Al, Proc. of SRF 2015



Final RF

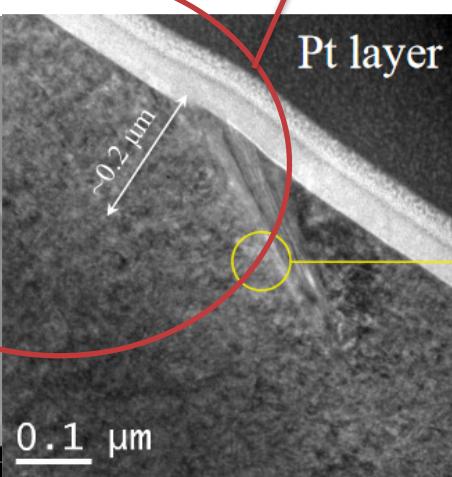
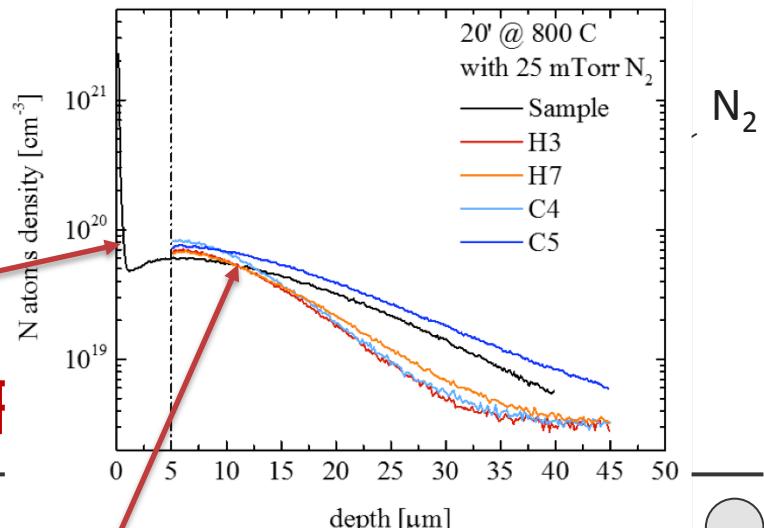


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Y. Trenikhina et al, Proc. of SRF 2015

0.1 μm

Scans adapted from M. Martínez



Nb [113]+Nb<sub>2</sub>N [210]+?

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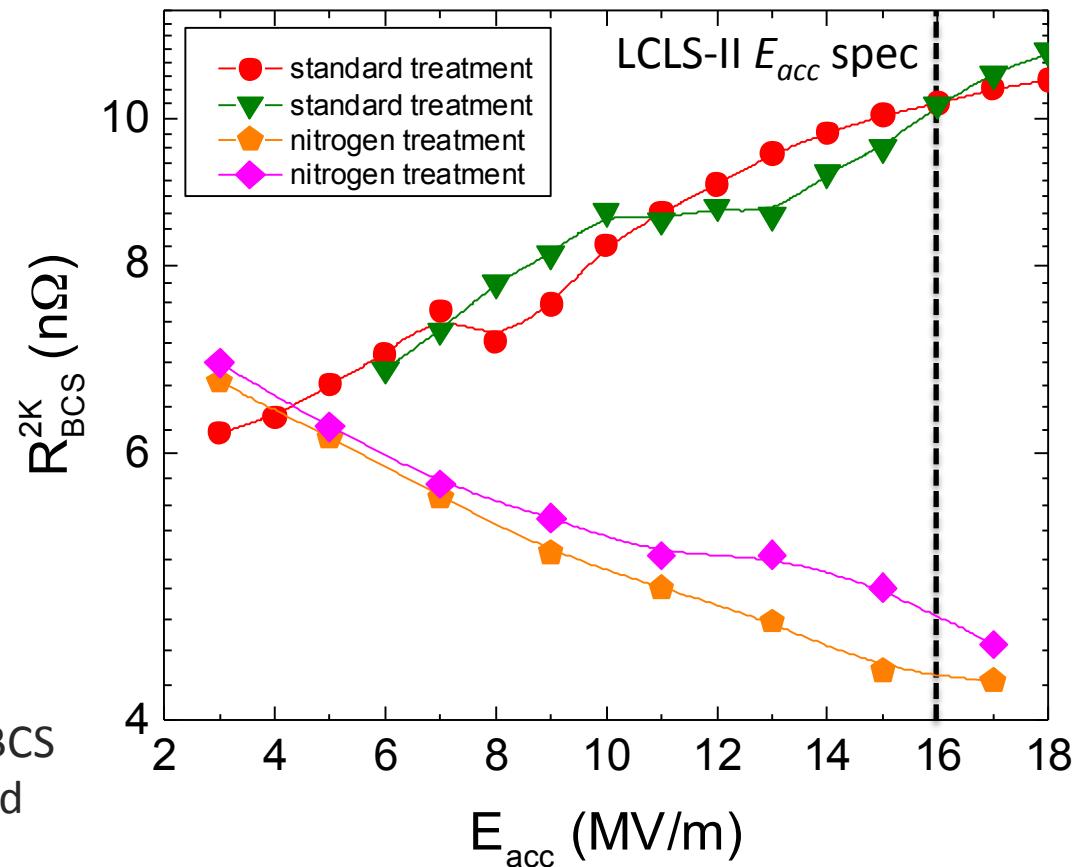
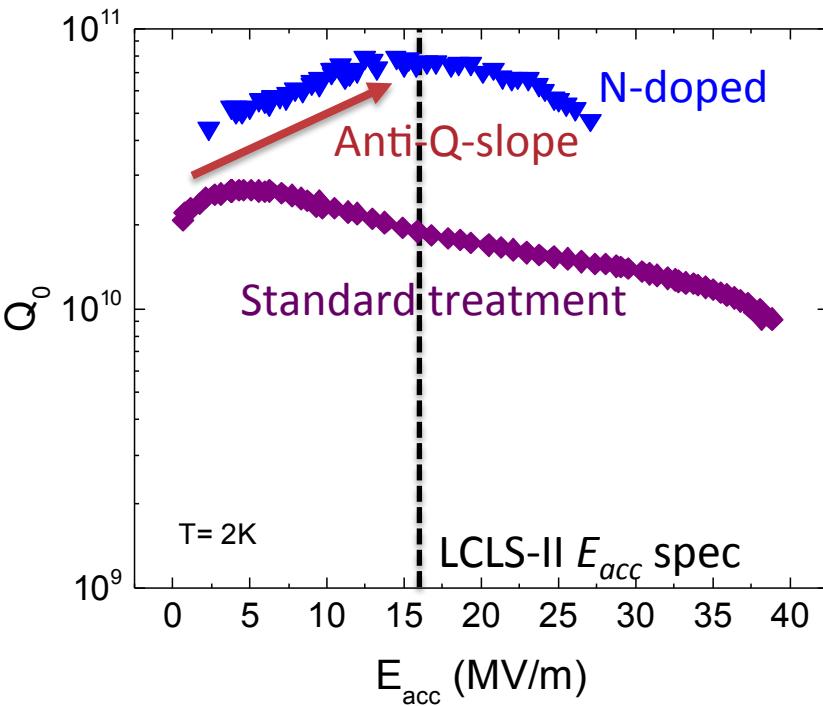
N

N<sub>2</sub>

Nb<sub>x</sub>N<sub>y</sub>

N Interstitial

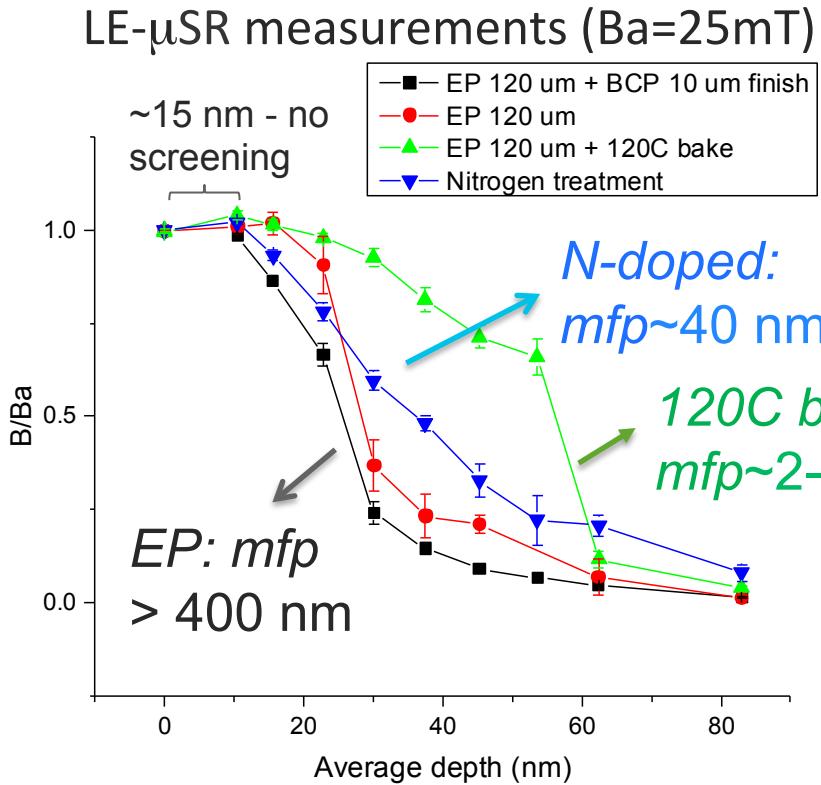
# Effect on Surface Resistance (and therefore $Q_0 = G/R_s$ )



Anti-Q-slope emerges from the BCS surface resistance decreasing with field  
→ Unexpected, unprecedented

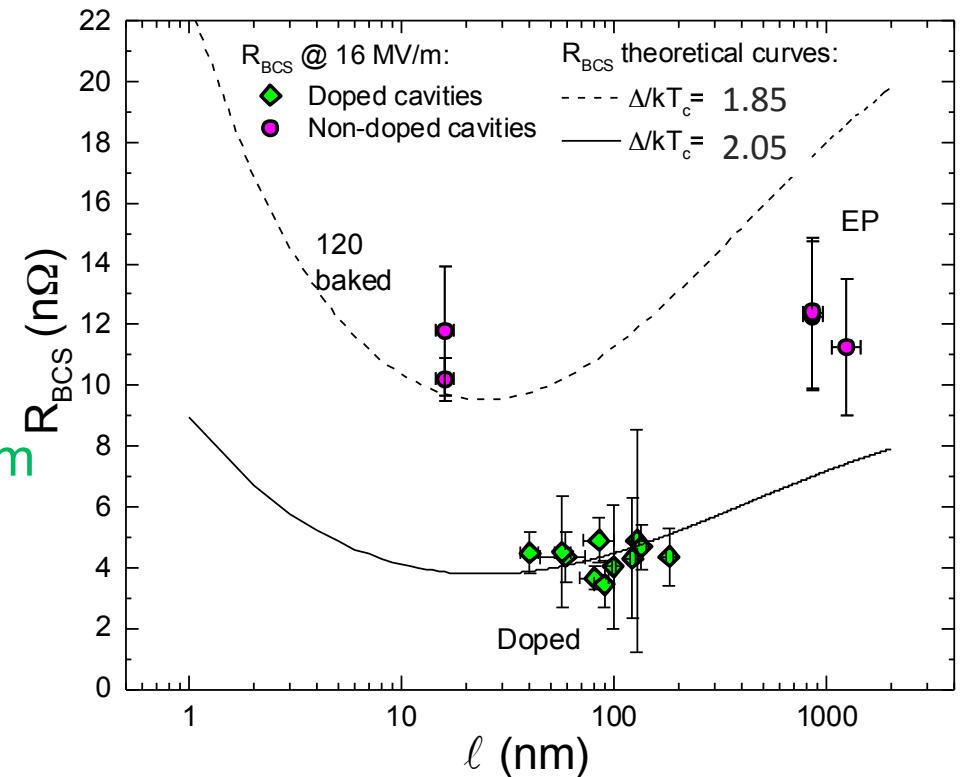
- $>2x R_{BCS}$  improvement at 2 K, 16 MV/m
- Reduced maximum field OK for high duty factor applications

# Origin of Improved Surface Resistance due to N-Doping



A. Romanenko et al, Appl. Phys. Lett. **104**, 072601 (2014)

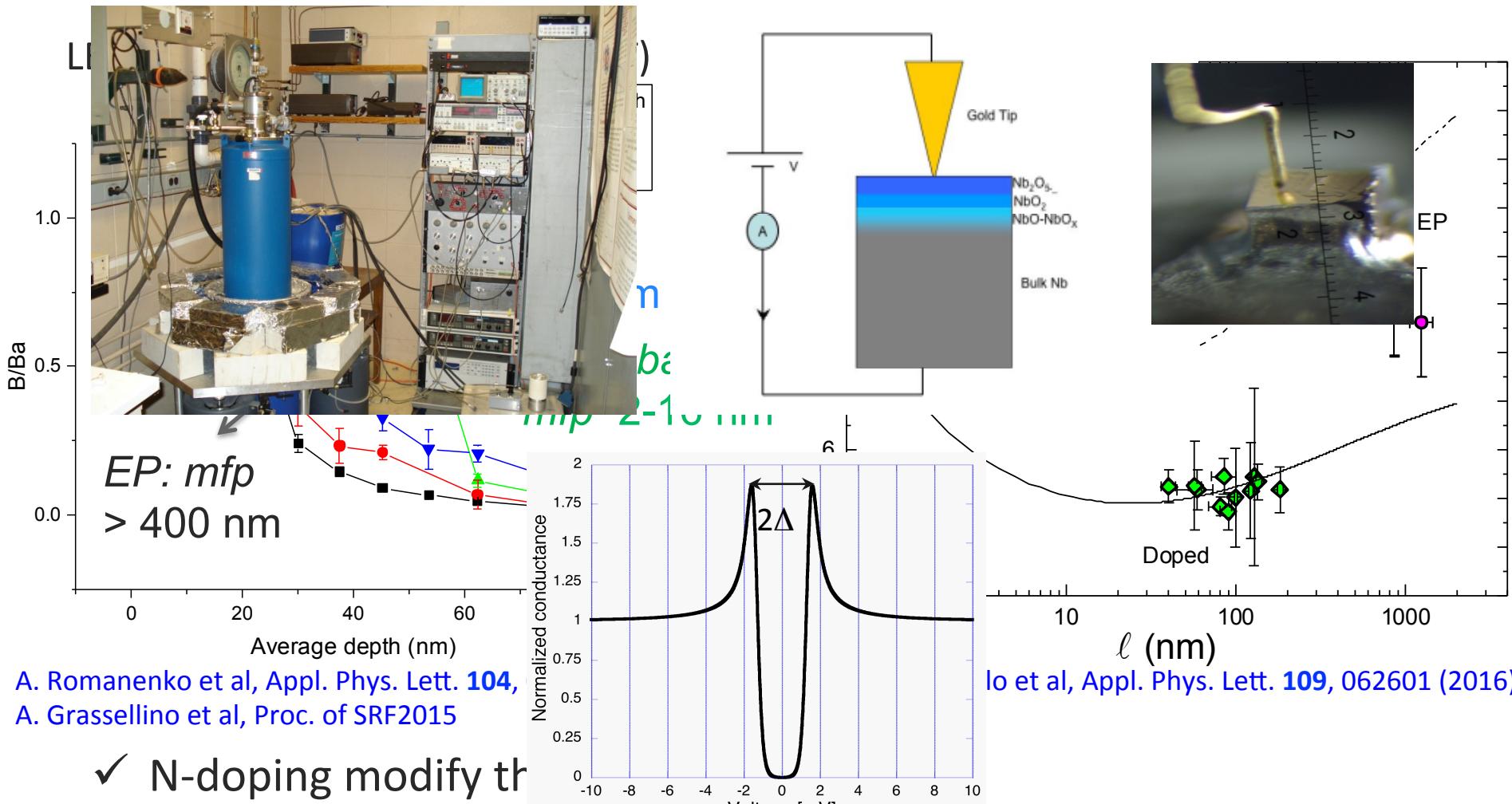
A. Grassellino et al, Proc. of SRF2015



M. Martinello et al, Appl. Phys. Lett. **109**, 062601 (2016)

- ✓ N-doping modify the mean free path  
→ Mean free path close to theoretical minimum of  $R_{BCS}$
- ✓ N-doping seems to increase the reduced energy gap  $\Delta/k_B T_c$

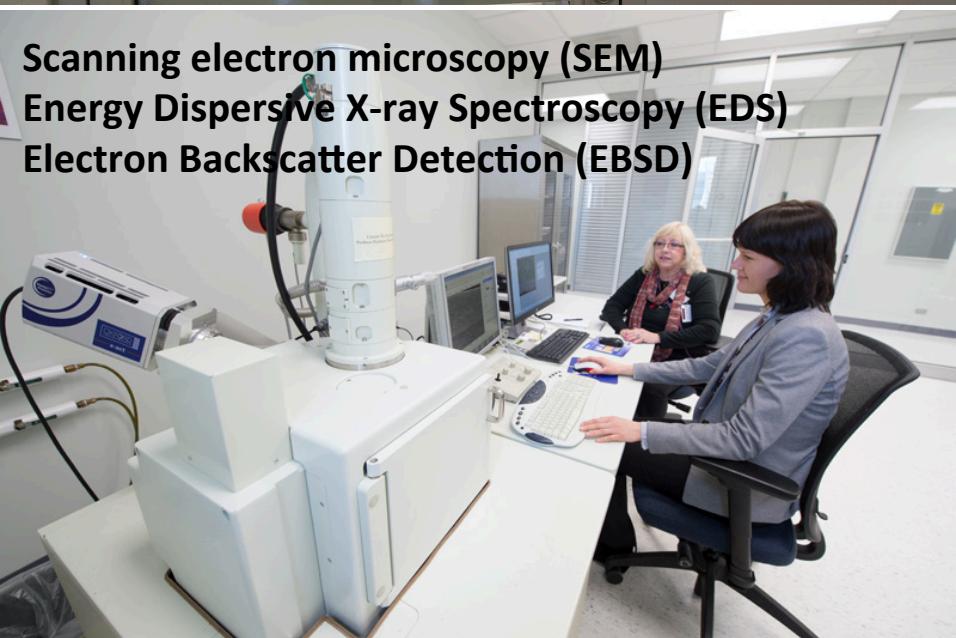
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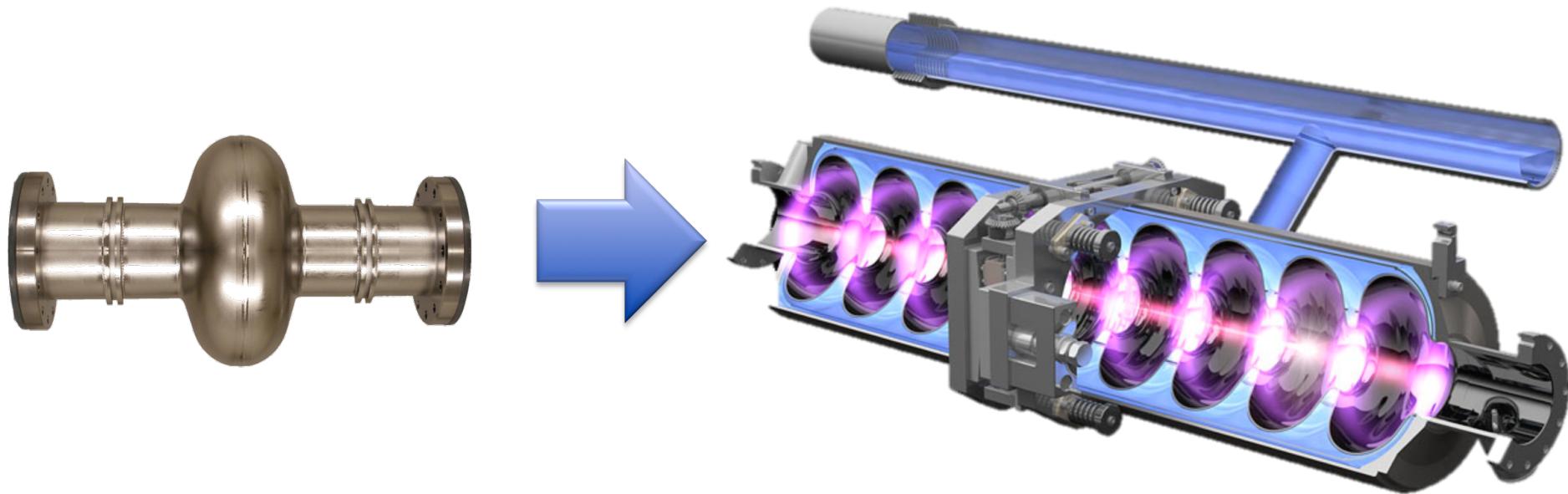
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# Materials Science Lab

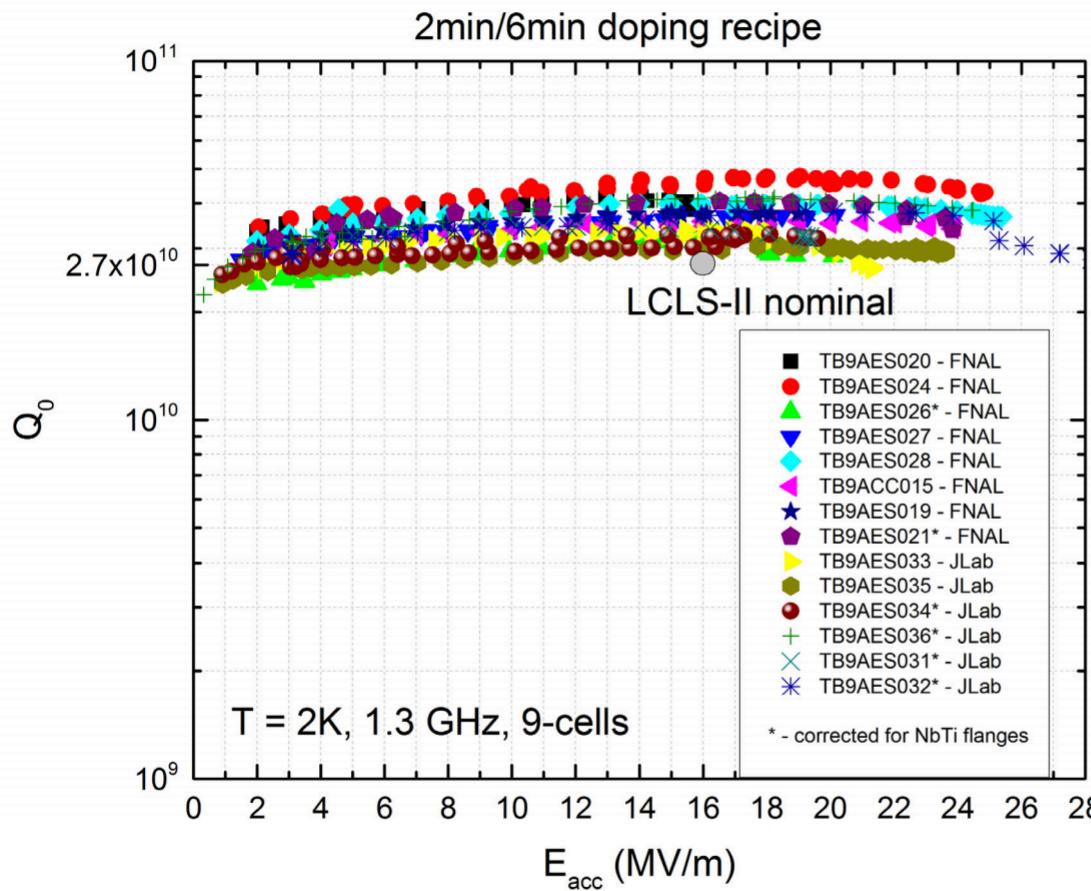


# Scale-Up

- Initial studies on single cell R&D-style cavities
- Several milestones required to demonstrate technology maturity for accelerator applications



# From single cell R&D to cryomodule ready technology: the two LCLS-II prototype cryomodules (FNAL and Jlab)

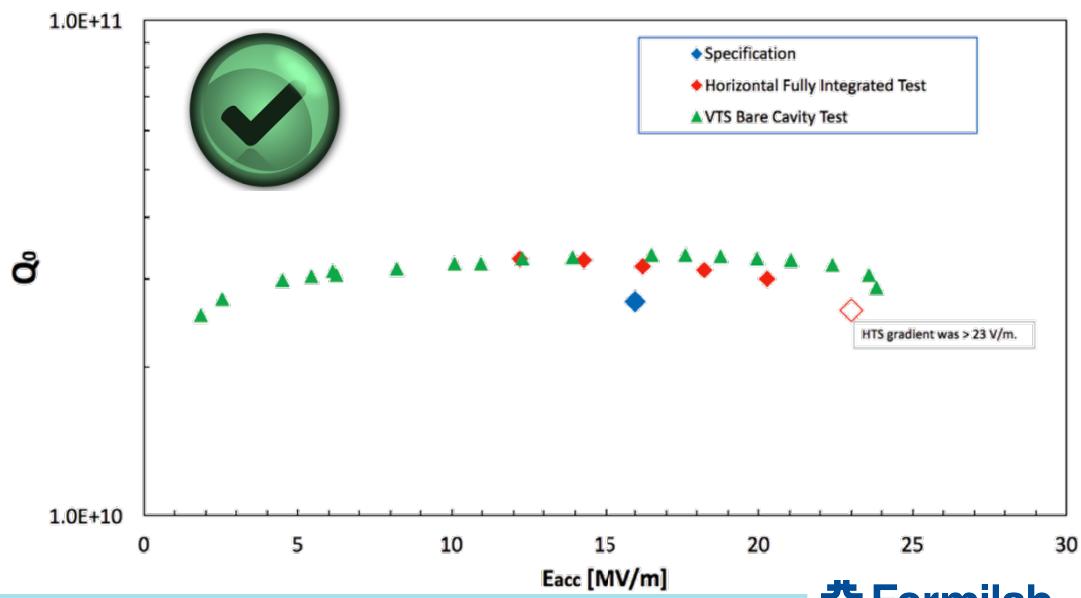


$$\langle Q \rangle = 3.6 \text{e}10$$
$$\langle E_{max} \rangle = 22.2 \text{ MV/m}$$
$$E_{max} \text{ median} = 22.8 \text{ MV/m}$$

It is the highest average Q ever demonstrated in vertical test for 1.3 GHz nine cells at 2K, 16 MV/m in the history of SRF (larger than a factor of two the state of the art)

# Integrated Testing

- Record  $Q_0 > 3 \times 10^{10}$  at 16 MV/m, 2 K for a LCLS-II dressed cavity in fully integrated horizontal test (with high power coupler, HOMs, tuner etc.)
- Important milestone to show new readiness for implementation in application

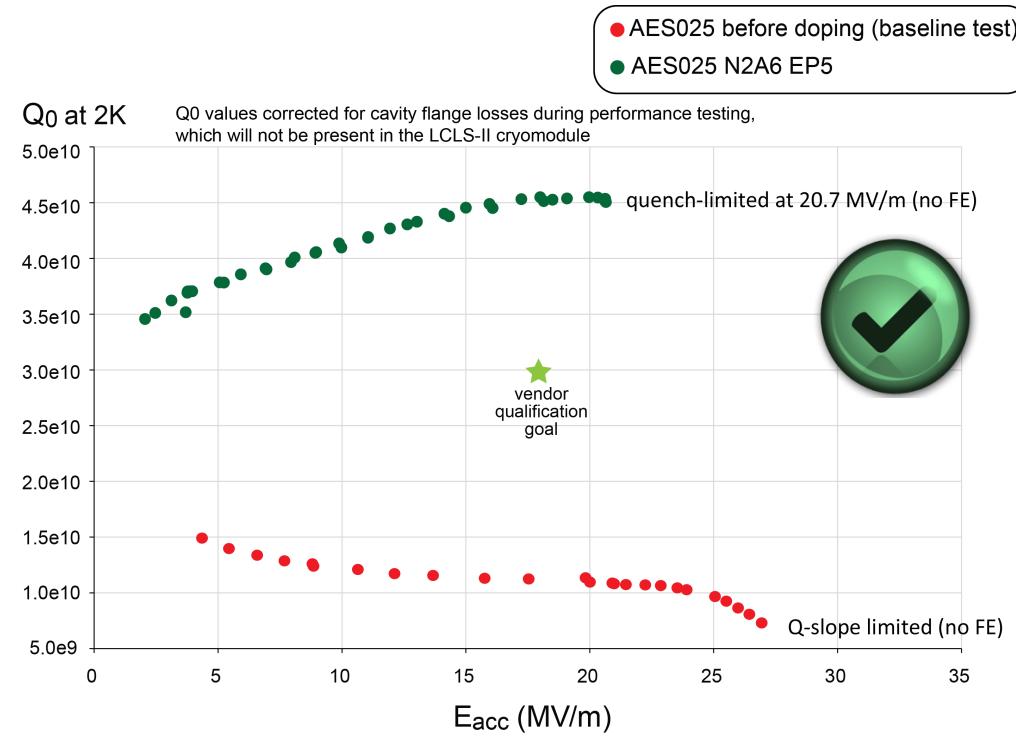


# Technology Transfer

- SRF cavity vendors: from niobium material to N-doped cavities ready for qualification testing



research  
instruments



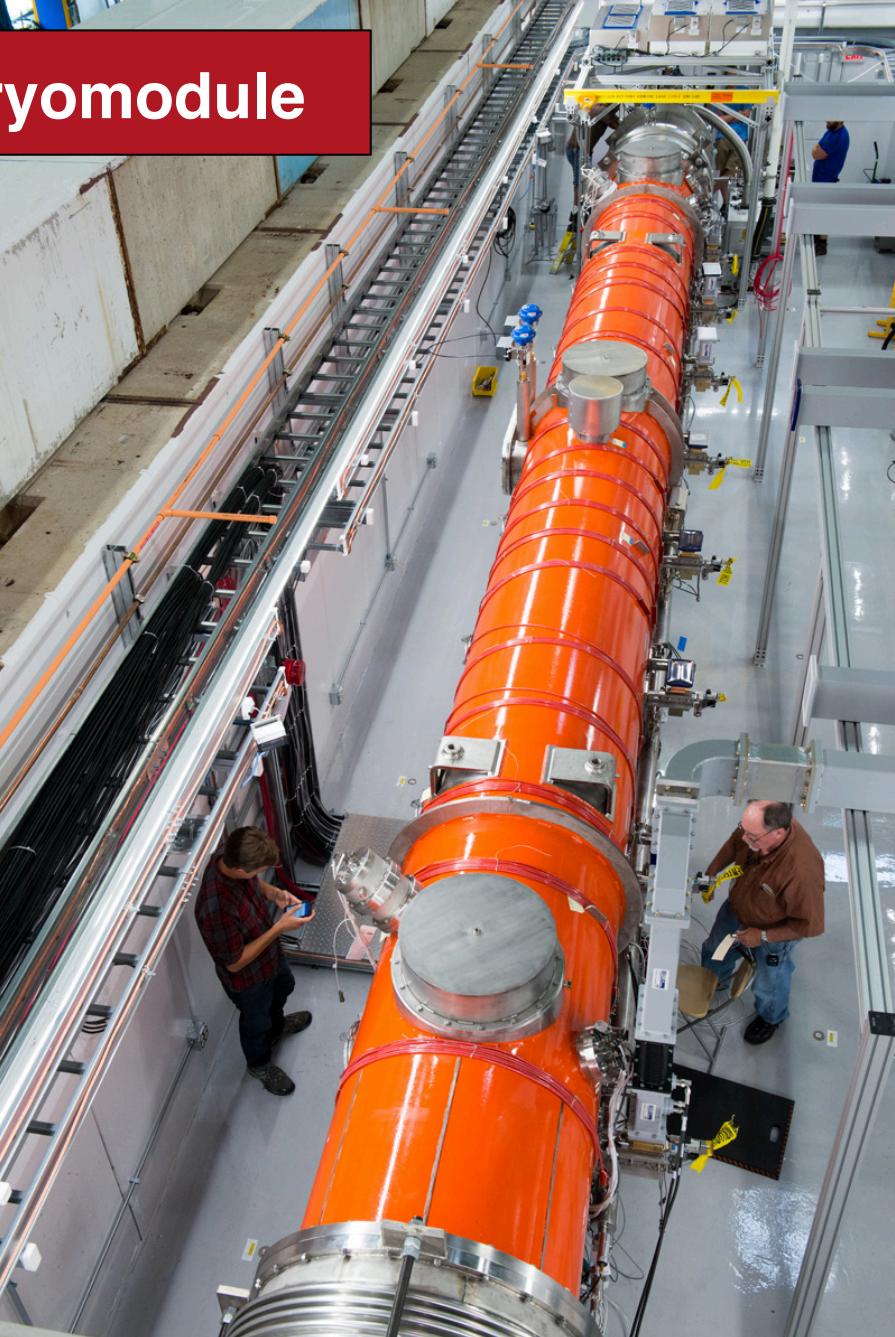
# Fermilab Prototype LCLS-II Cryomodule

Cavity	Usable Gradient* [MV/m]	Q0 @16MV/m* 2K Fast Cool Down
TB9AES021	18.2	2.6E+10
TB9AES019	18.8	3.1E+10
TB9AES026	19.8	3.6E+10
TB9AES024	20.5	3.1E+10
TB9AES028	14.2	2.6E+10
TB9AES016	16.9	3.3E+10
TB9AES022	19.4	3.3E+10
TB9AES027	17.5	2.3E+10
<b>Average</b>	<b>18.2</b>	<b>3.0E+10</b>
Total Voltage	<b>148.1 MV</b>	

Spec:  
133 MV



Spec:  
 $2.7 \times 10^{10}$

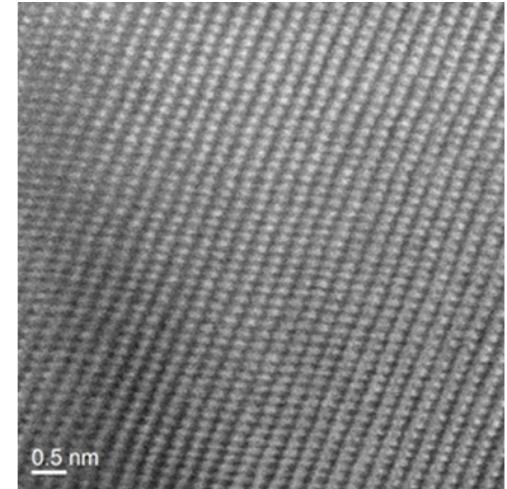


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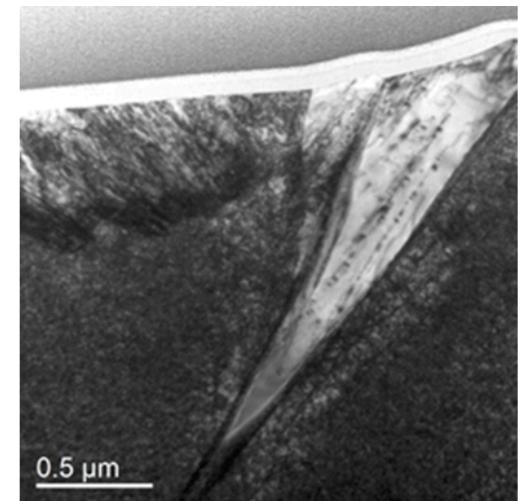
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  - Nitrogen doping
  - Flux expulsion
- High  $E_{acc}$  and high  $Q_0$ 
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  - Nb<sub>3</sub>Sn
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ILC cryomodule with record average gradient for FAST facility

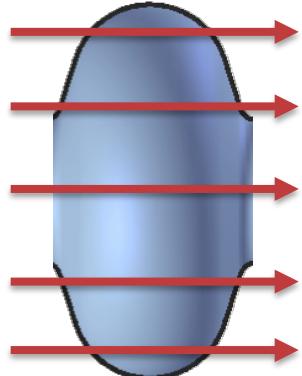
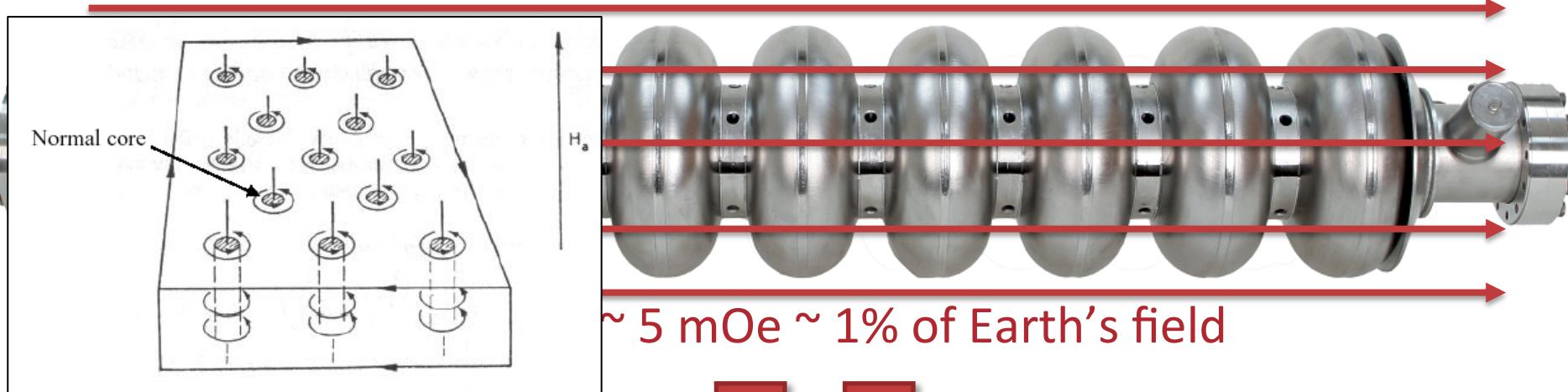


Aberration-corrected STEM image of the near-surface of Nb cavity - Y. Trenikhina

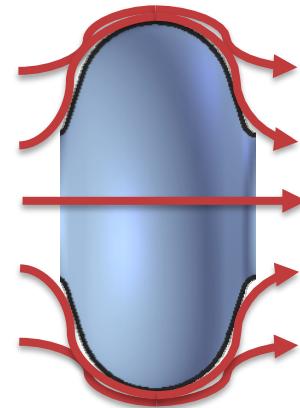
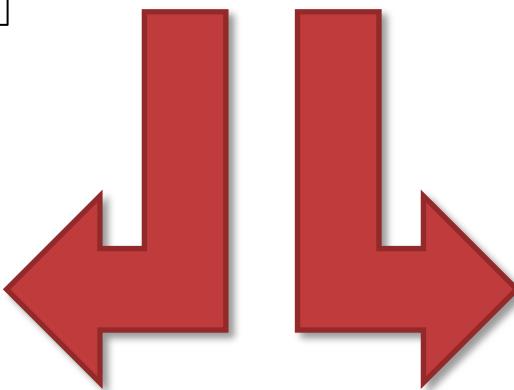


Niobium near-surface after the first step of nitrogen doping - Y. Trenikhina

# Cooldown through Critical Temperature



Magnetic Flux  
Trapping

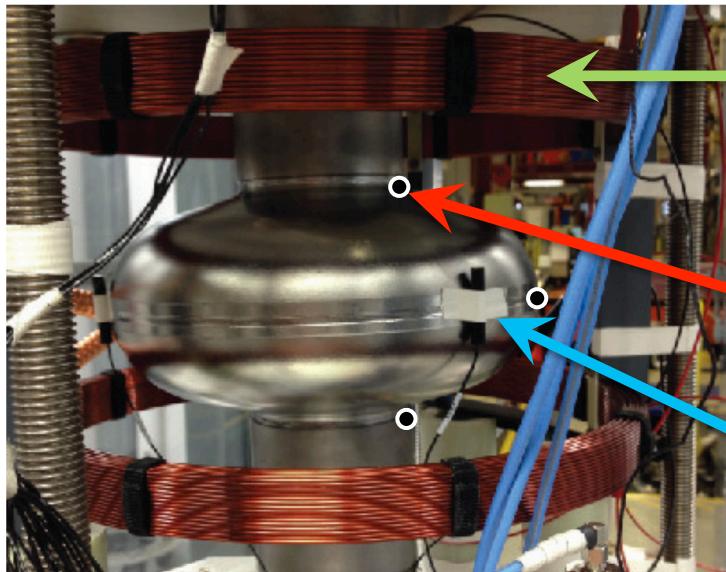


Magnetic Flux  
Expulsion

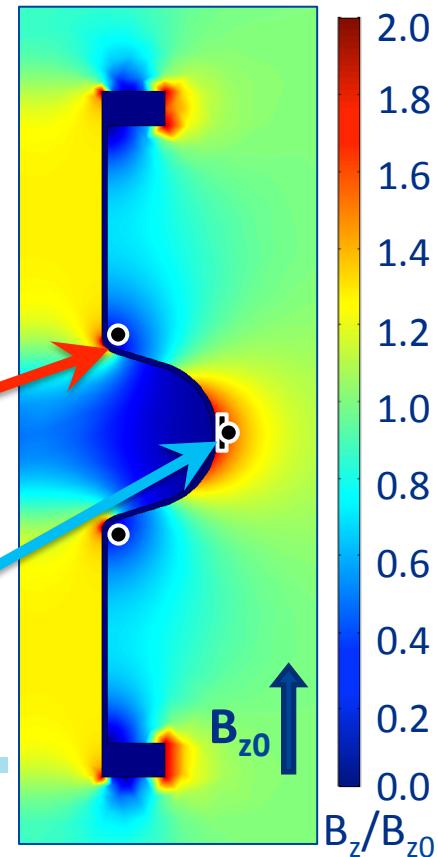
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# Measuring Flux Expulsion

- An axial magnetic field is applied during cooldown. Fluxgate magnetometers at the equator measured the magnetic field before  $B_{NC}$  and after  $B_{SC}$  superconducting transition.
  - Complete trapping:  $B_{SC}/B_{NC} = 1$
  - Complete expulsion:  $B_{SC}/B_{NC} \sim 1.7$

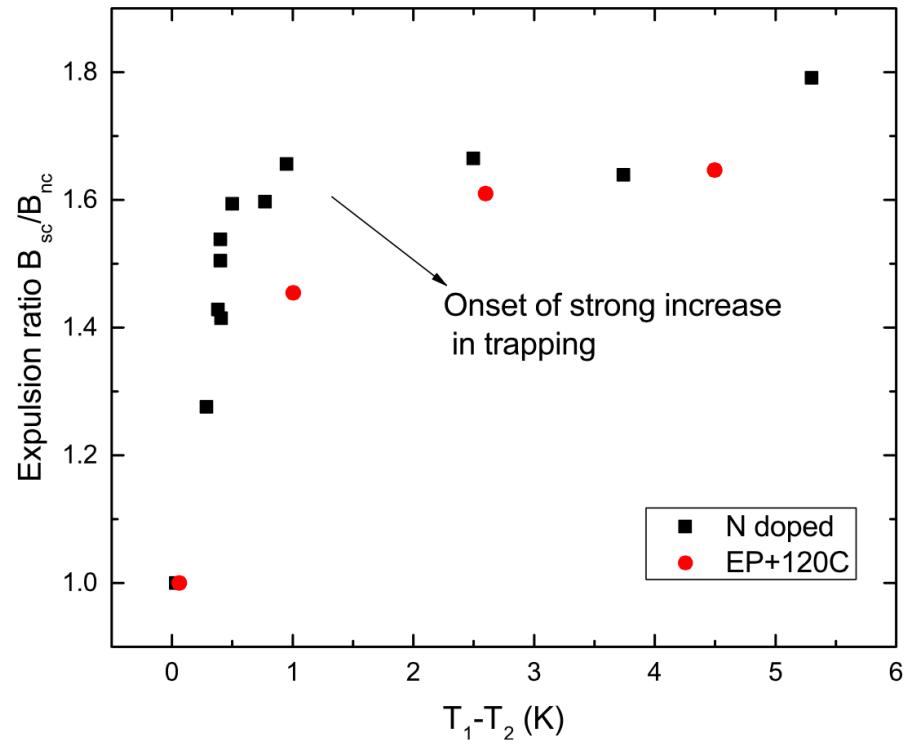
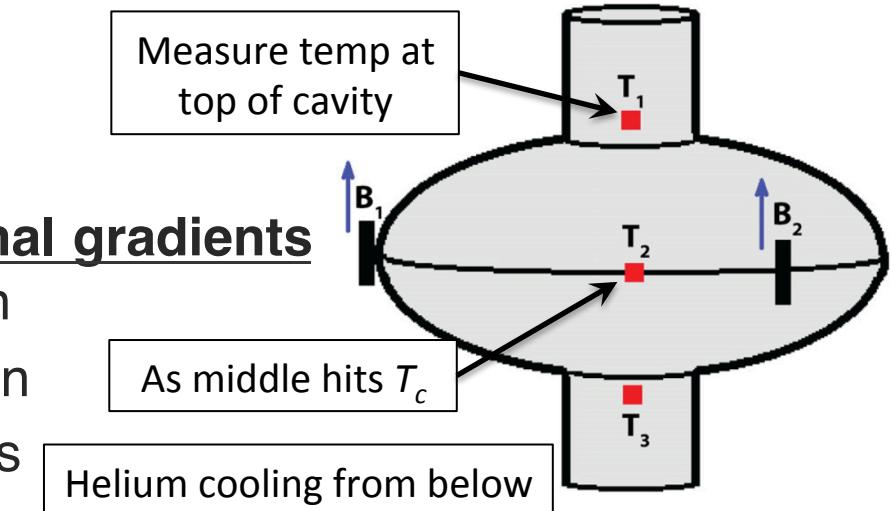
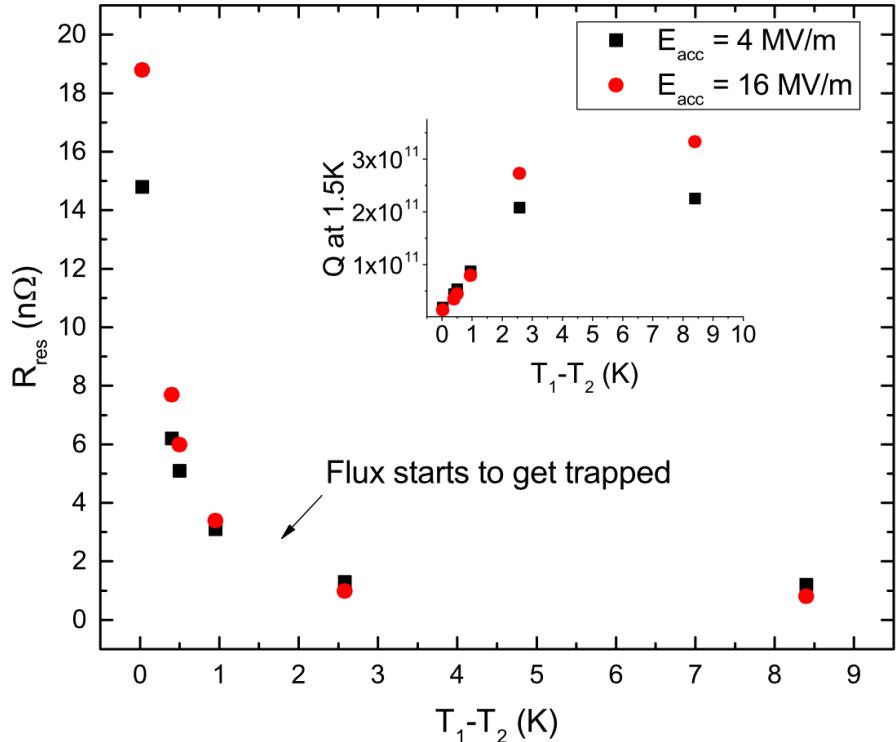


External  
field coils  
Temperature  
sensor  
Fluxgate  
magnetometer



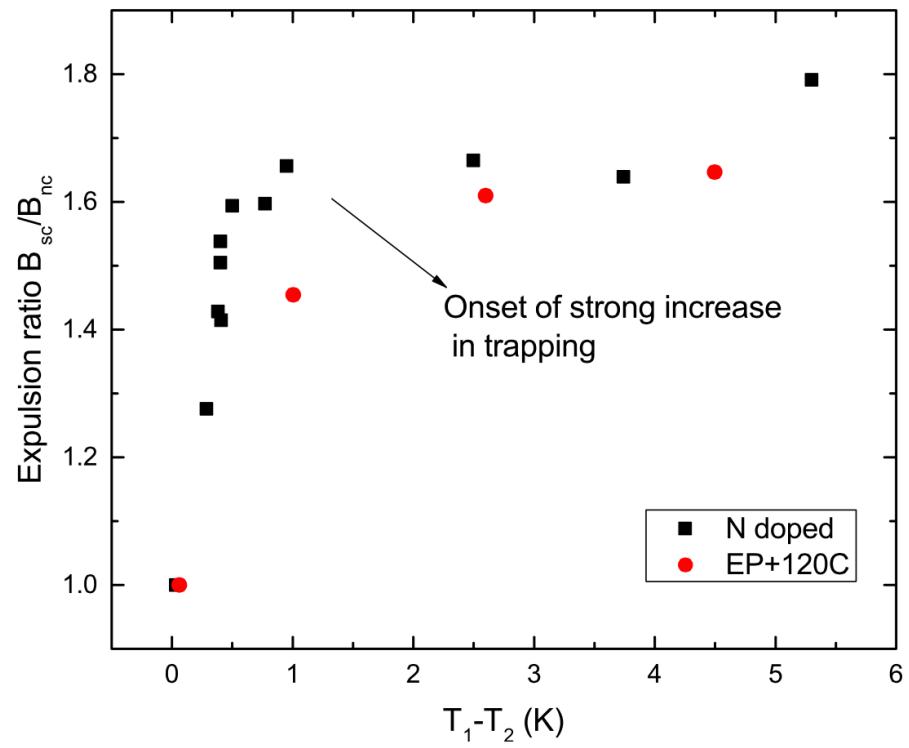
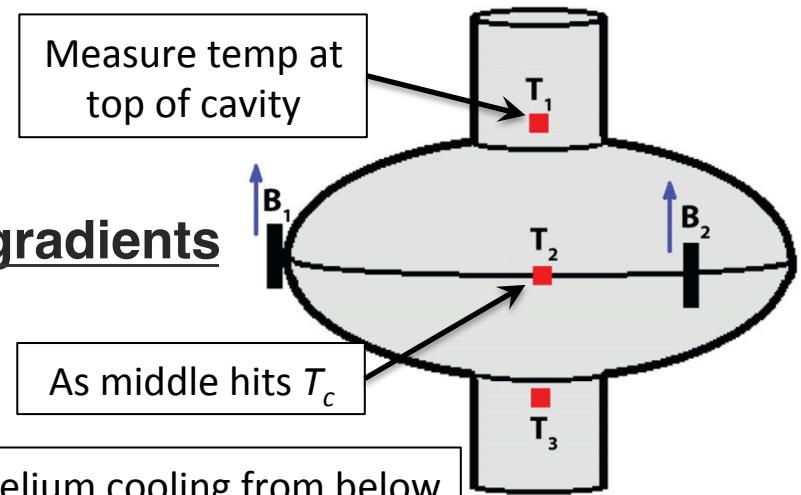
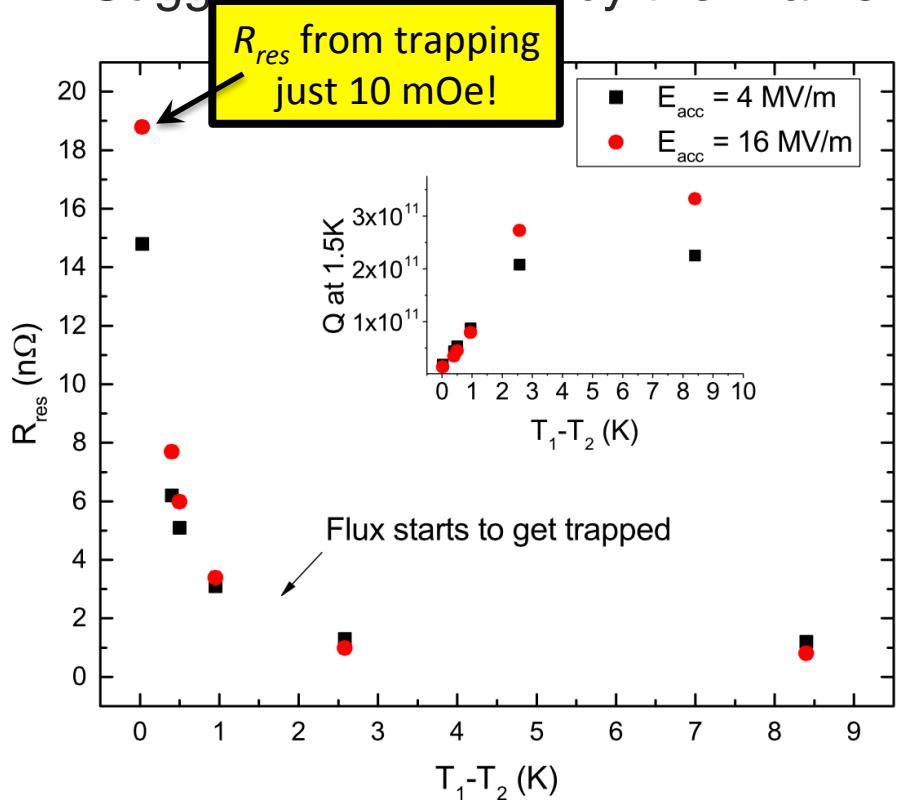
# Thermal Gradients

- **Fast cool-down** lead to large thermal gradients which promote efficient flux expulsion
- **Slow cool-down** → poor flux expulsion
- Suggests depinning by thermal forces



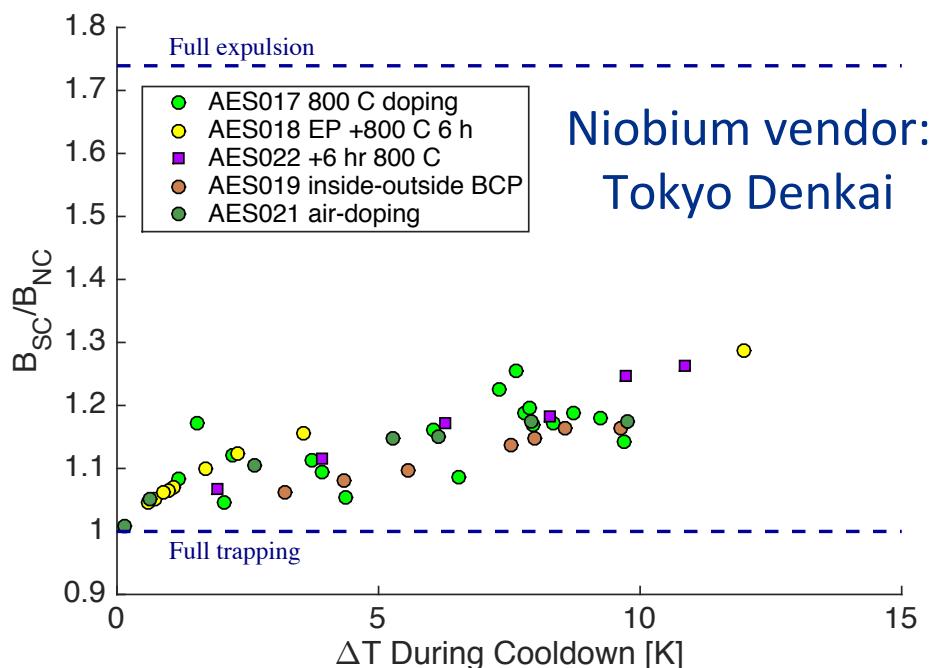
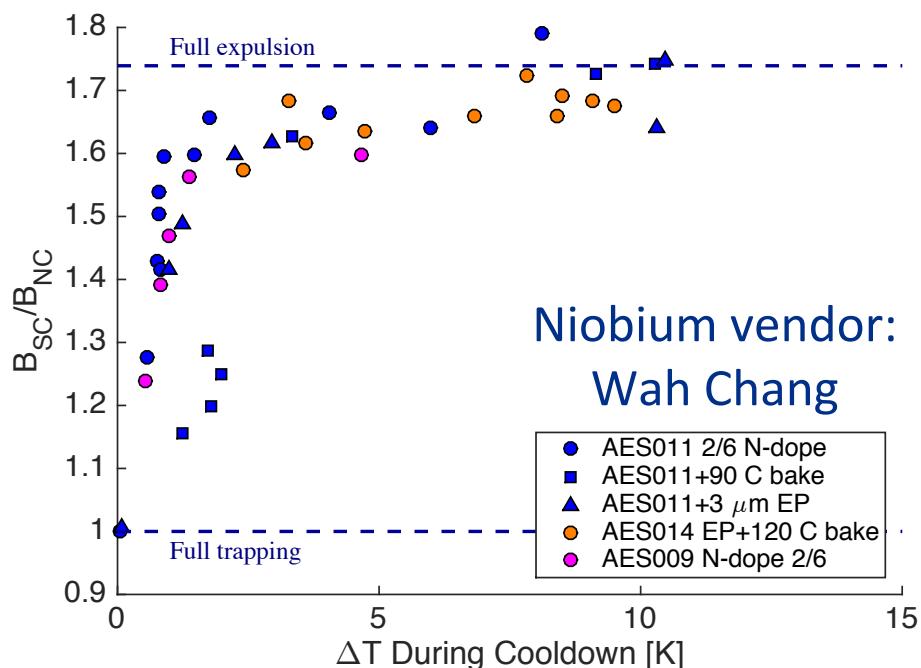
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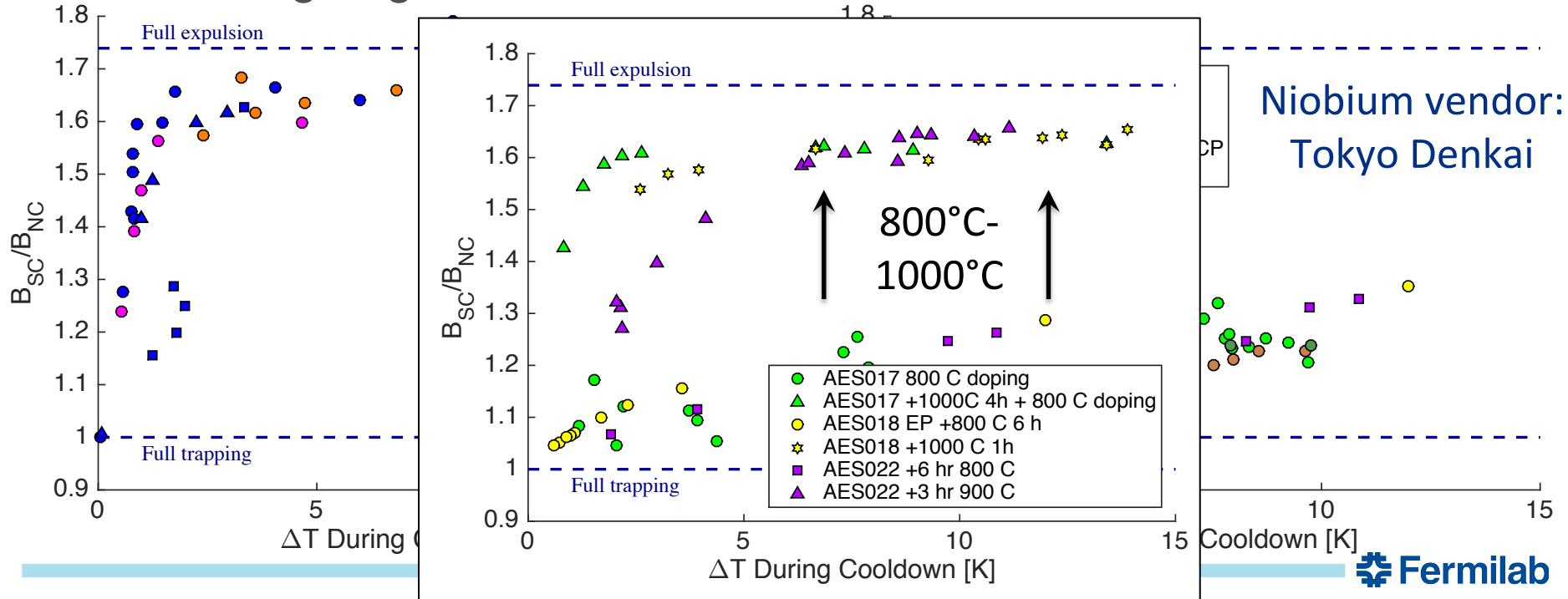
# Variability in Material and Modifying Expulsion Behavior

- Seems to be a great deal of variability in as-received material
- Variability from batches even within a single vendor

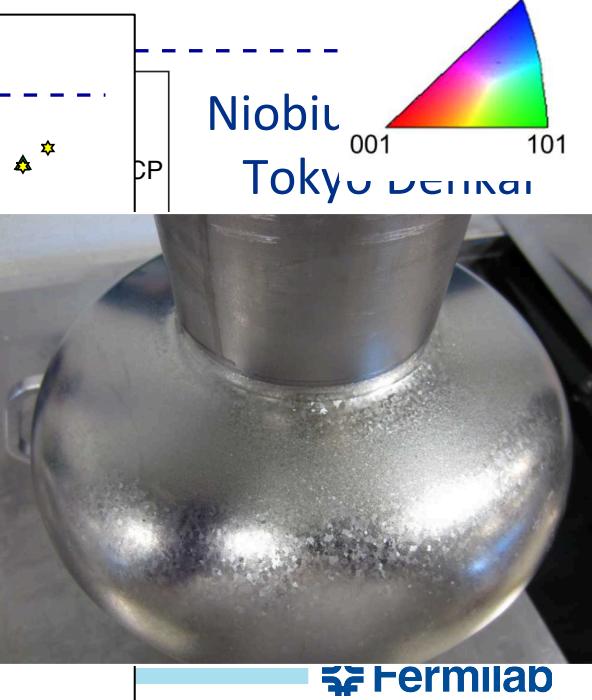
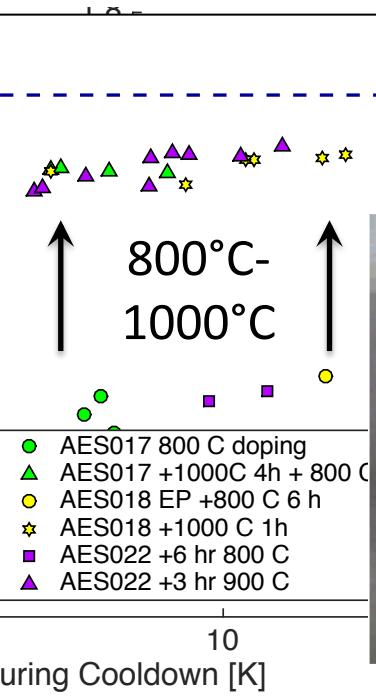
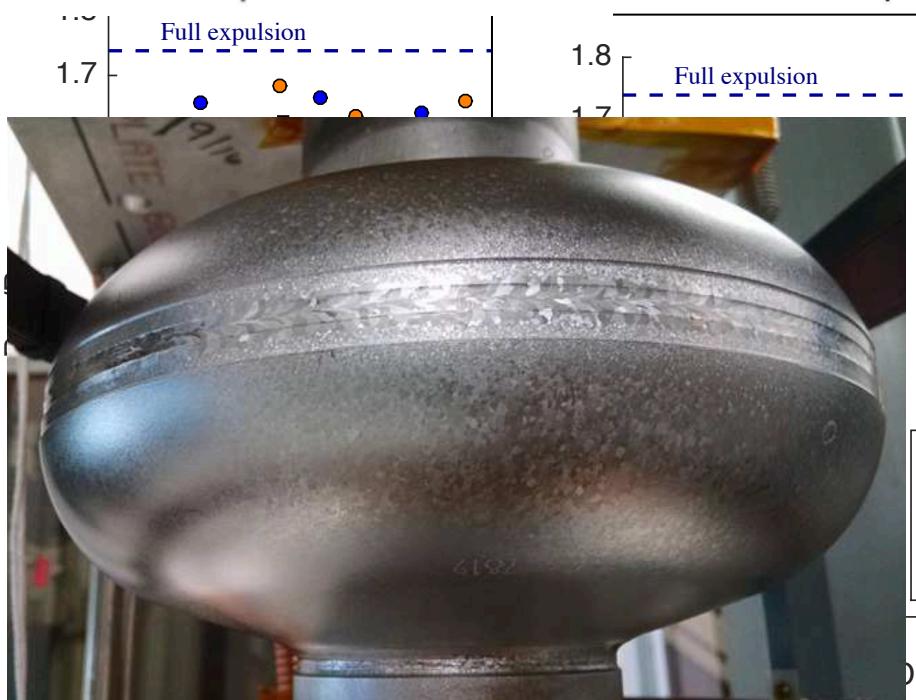
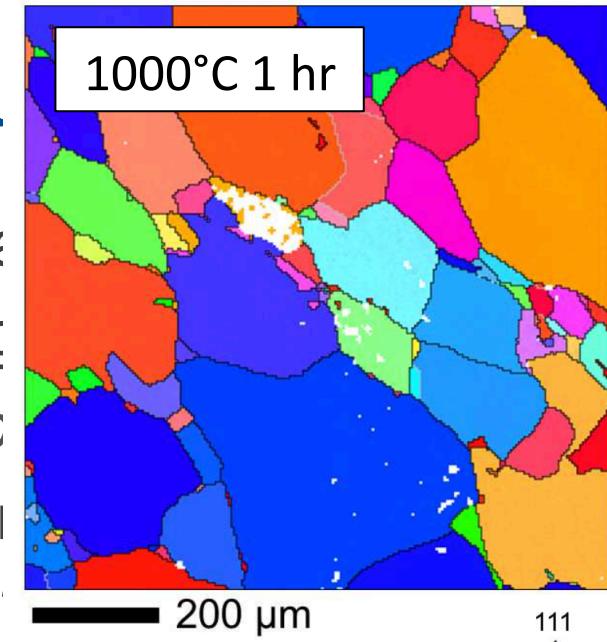
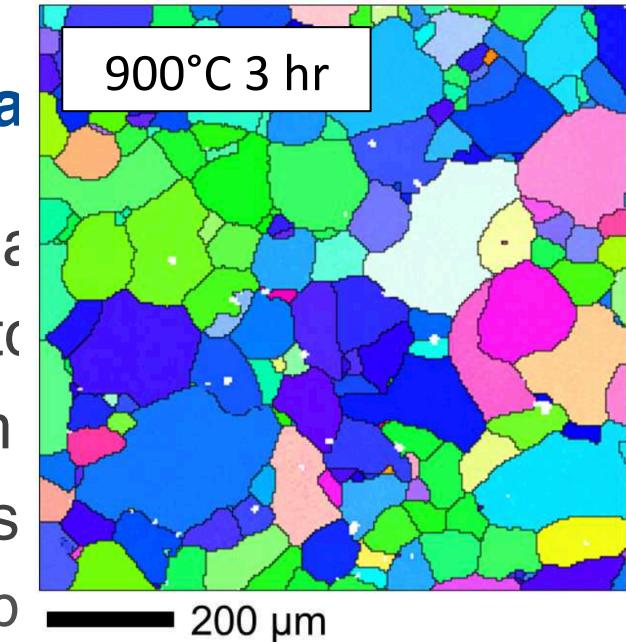
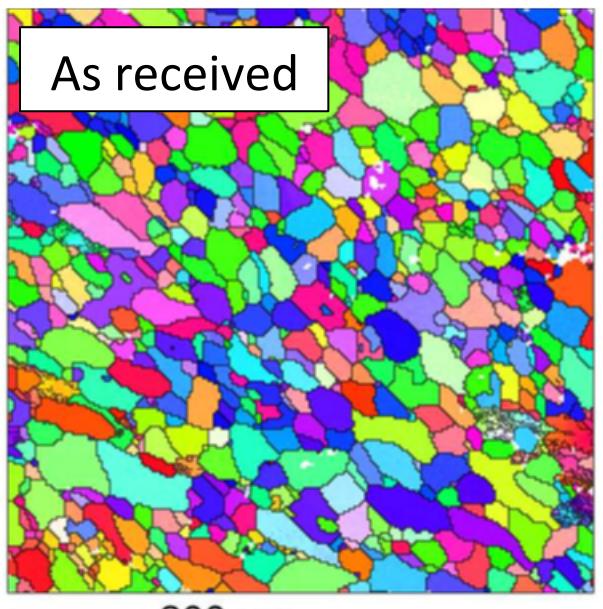


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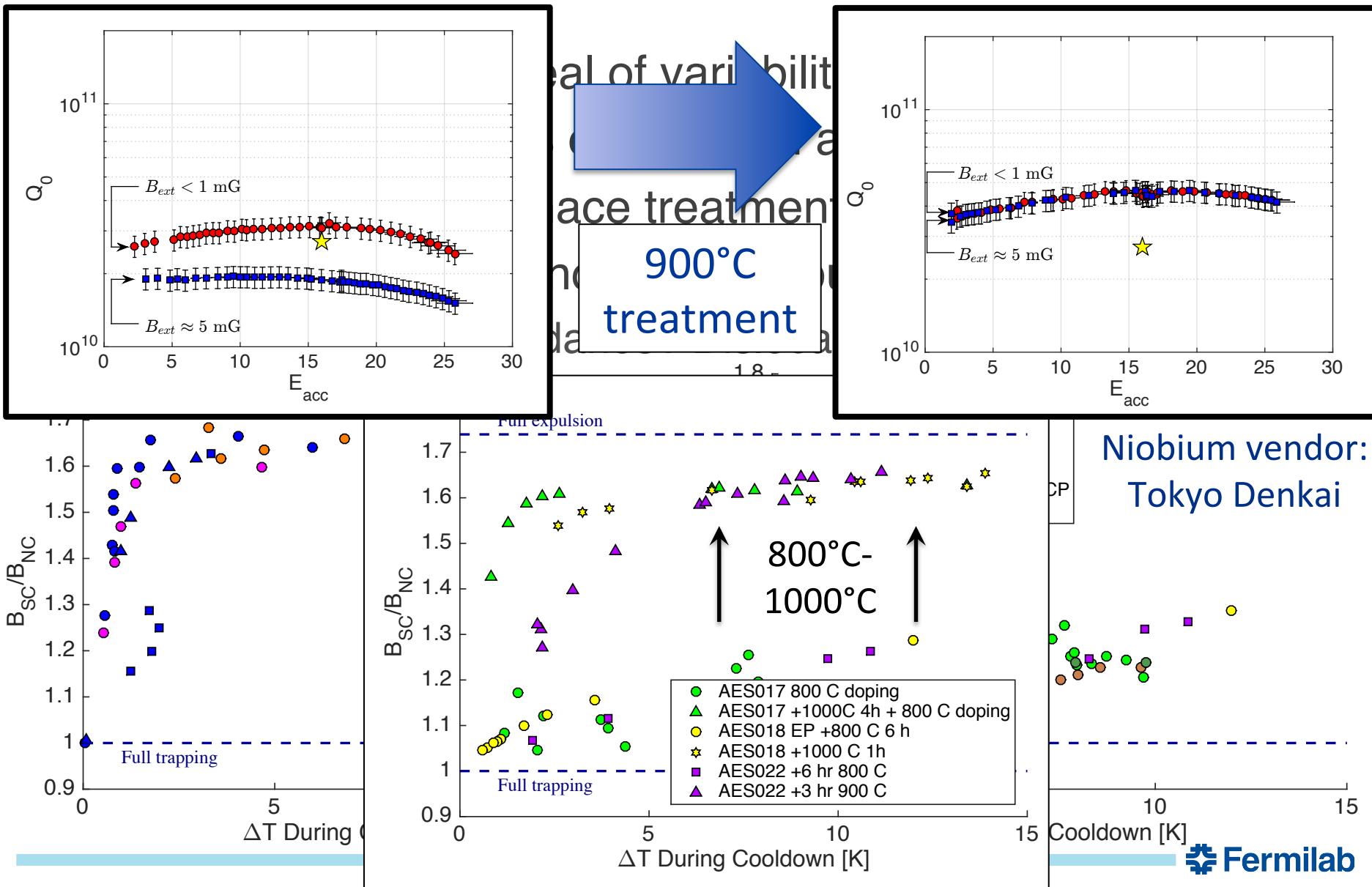
- Seems to be a great deal of variability in as-received material
- Variability from batches even within a single vendor
- High temp vacuum furnace treatment *improves* expulsion
- Surface treatments do not affect expulsion → bulk property
  - Pinning at grain boundaries? Dislocations?



As received

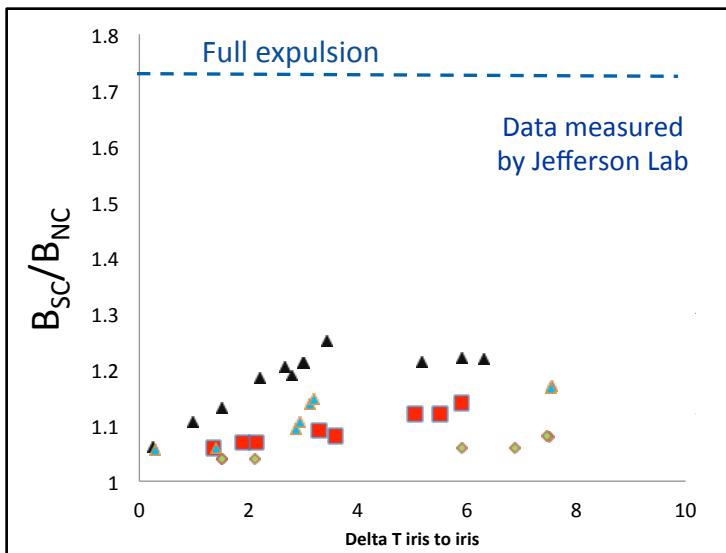


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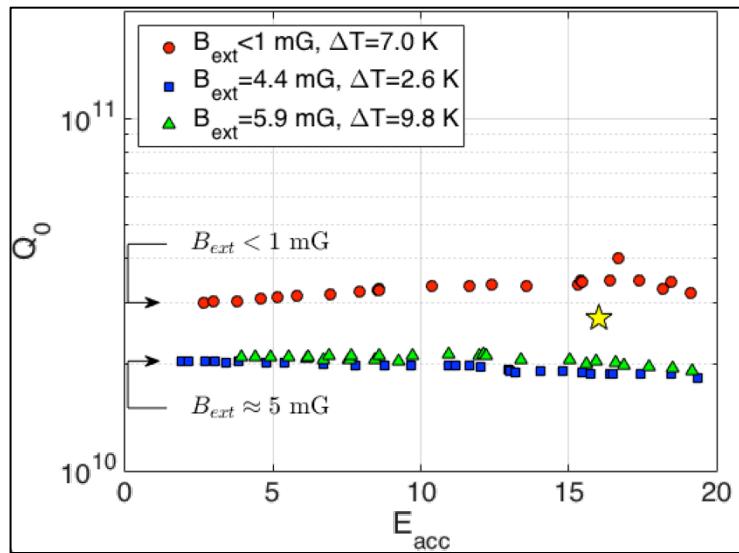


# LCLS-II - Preproduction

As-received niobium material for LCLS-II production: very poor expulsion



Cooling in 5 mG applied field  
(spec for background field in module)



# LCLS-II - Preproduction

Cooling in 5 mG applied field  
(spec for background field in module)

As-received niobium material for LCLS-II production very poorly expuls



2.7 Cryomodules  
D. Stout, MSU / Subcommittee 7

OFFICE OF  
**SCIENCE**

1.8  
1.7  
Full expulsion

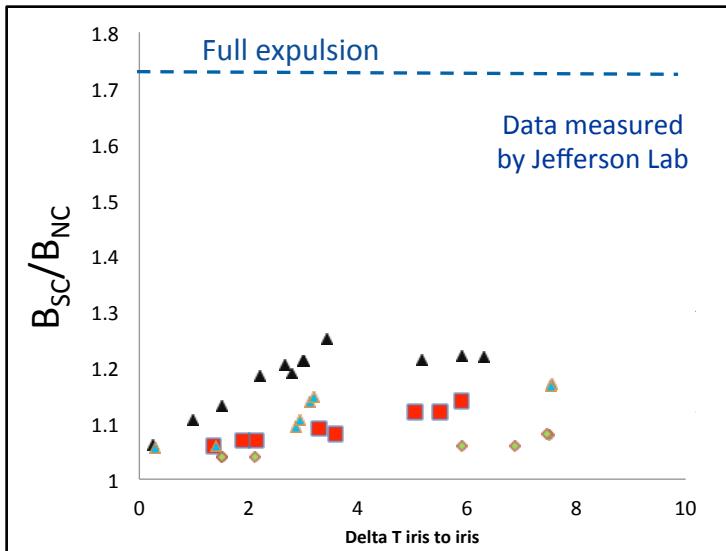
•  $B_{ext} < 1 \text{ mG}, \Delta T = 7.0 \text{ K}$   
■  $B_{ext} = 4.4 \text{ mG}, \Delta T = 2.6 \text{ K}$

## Recommendations

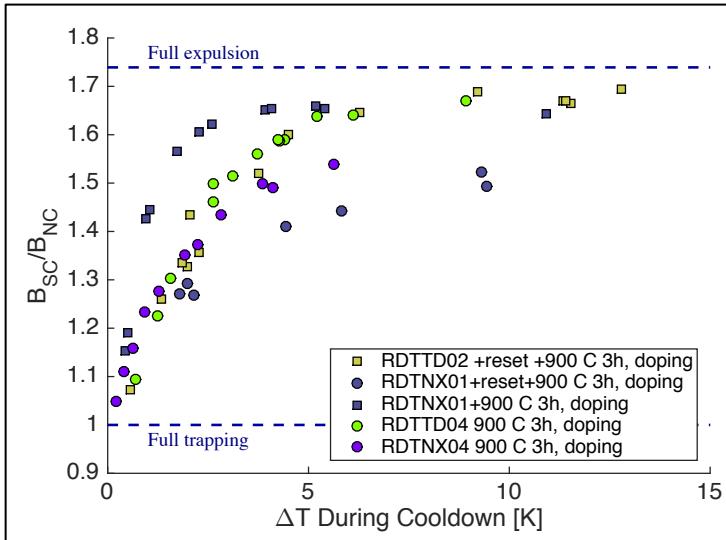
1. The Project is ready to proceed to CD-2/3
2. Finalize cavity and cryomodule minimum acceptance criteria based on the current project baseline – by 3/2016
3. Conduct a supply chain risk assessment of critical cryomodule assembly components to identify items needing second sources or other mitigations – by 3/2016
4. Develop a cure to improve the flux expulsion of the procured niobium material and implement before cavity production.
5. Conduct an independent peer review of the detailed assembly methods for connecting cryomodules – prior to first connection in 2017

# LCLS-II - Preproduction

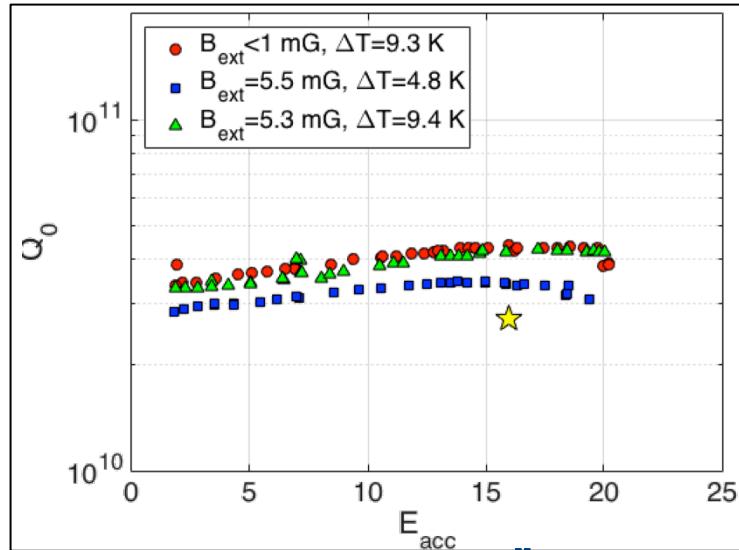
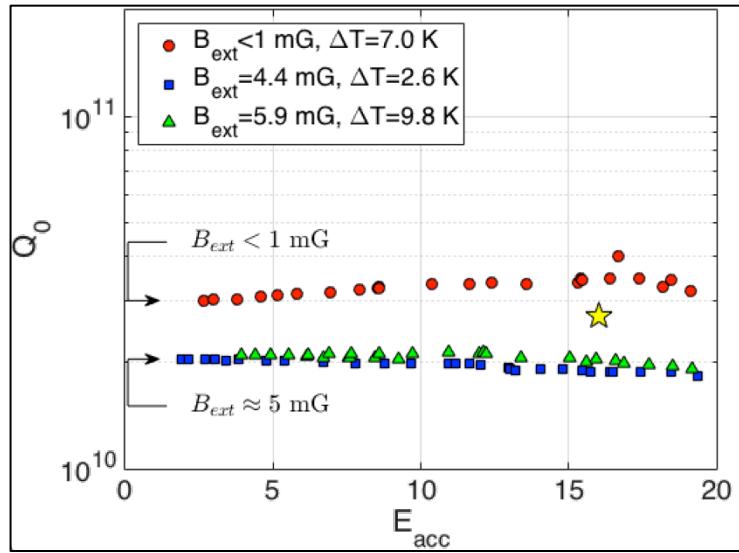
As-received niobium material for LCLS-II production: very poor expulsion



After 900°C treatment: much improved

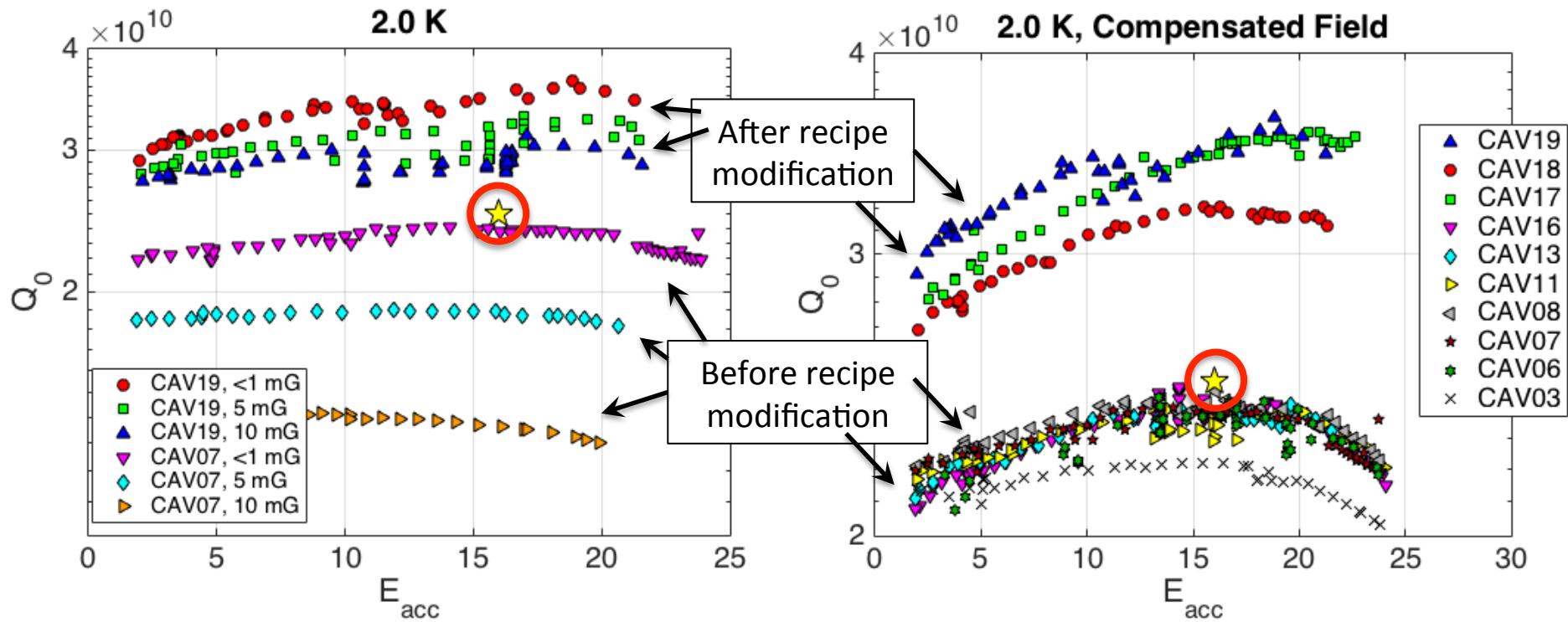


Cooling in 5 mG applied field  
(spec for background field in module)



# LCLS-II - Production

- After seeing results of first batch of 16 cavities, planned for modifications for next batch
- Modified recipe – 900 C now standard
- Still some stubborn material, but now qualifying great cavities!

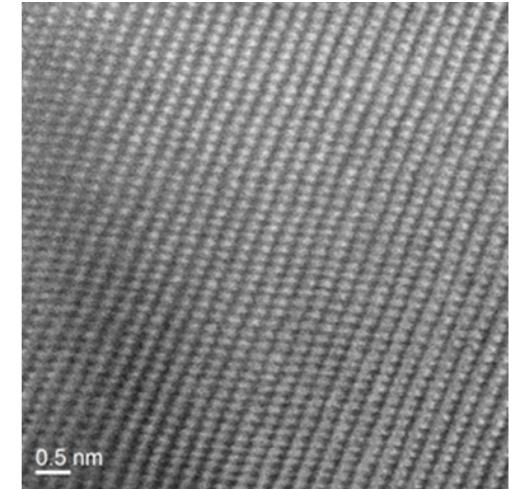


# Outline

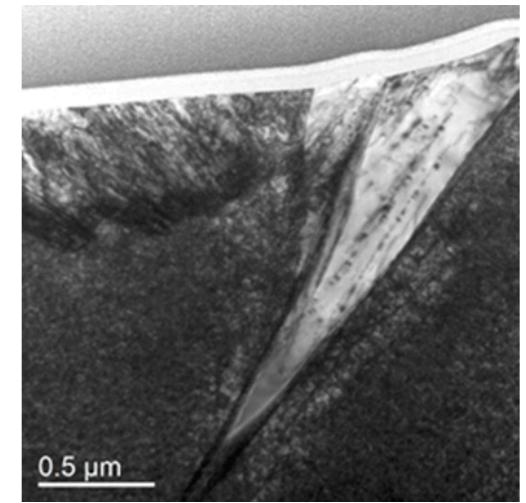
- High  $Q_0$  (medium  $E_{acc}$ )
  - Nitrogen doping
  - Flux expulsion
- High  $E_{acc}$  and high  $Q_0$ 
  - Nitrogen infusion
  - $\text{Nb}_3\text{Sn}$
  - Plasma cleaning



ILC cryomodule with world record gradient for FAST facility



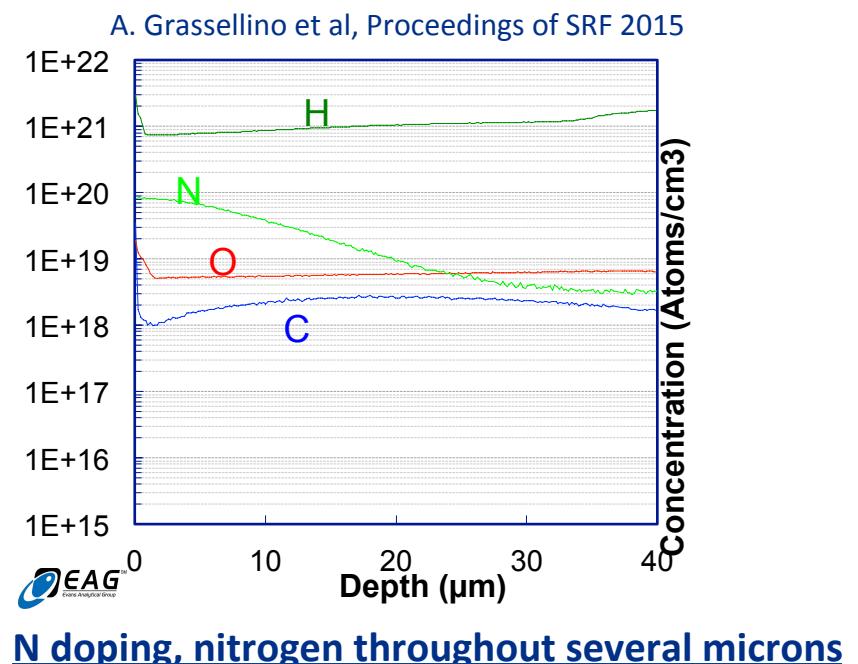
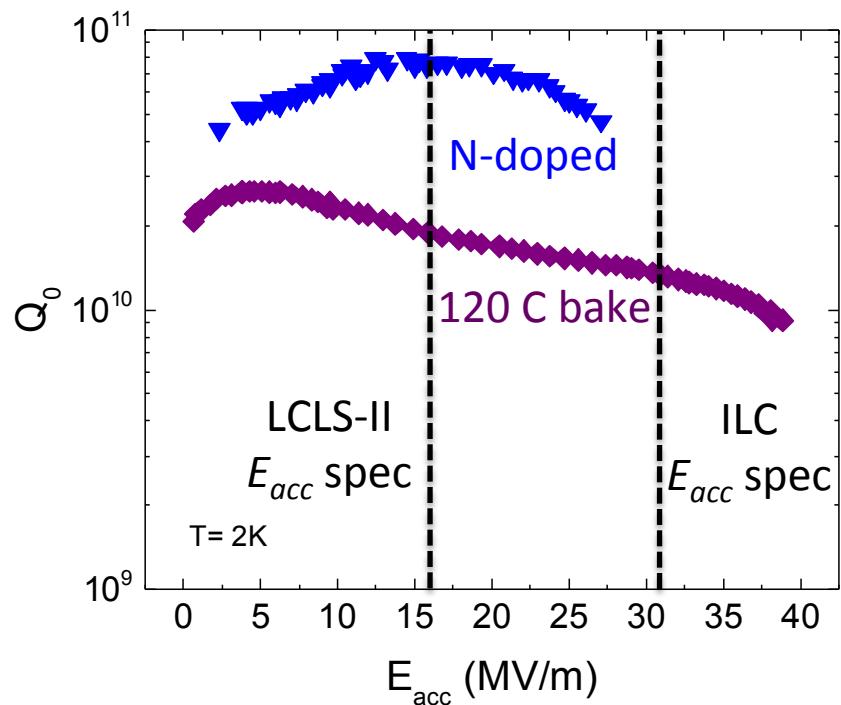
Aberration-corrected STEM image of the near-surface of Nb cavity - Y. Trenikhina



Niobium near-surface after the first step of nitrogen doping - Y. Trenikhina

# Motivation behind experiments

- **N Doping** at  $T > 800\text{C}$  proven to manipulate mean free path, but constantly throughout several microns, **giving high Q**
- **120C bake** known to manipulate mean free path at very near surface on clean bulk, and **produce the highest gradients**



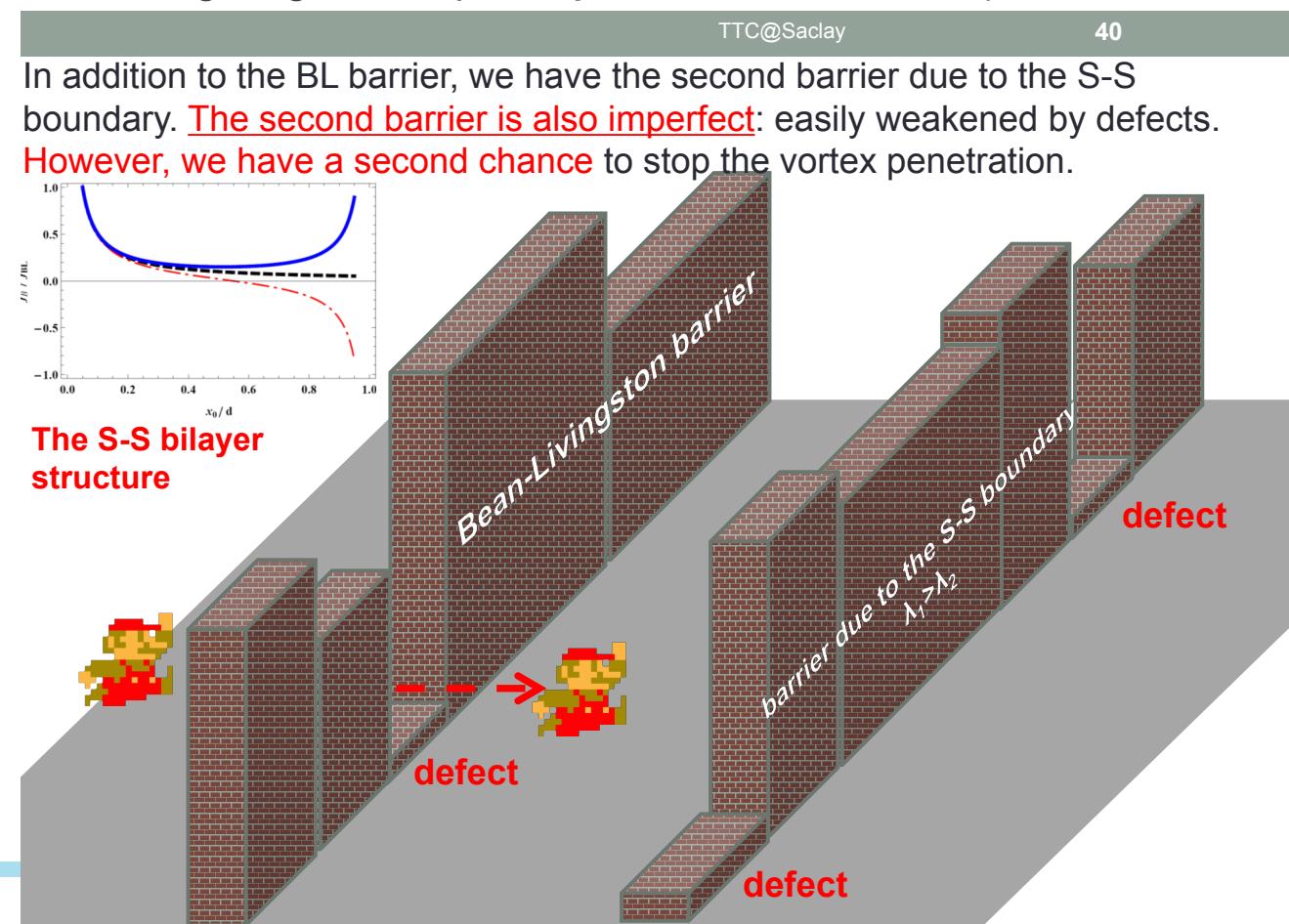
N doping, nitrogen throughout several microns

# Motivation behind experiments

- Therefore, we decided to study how to better “engineer” a dirty layer on top a clean bulk, using low T nitrogen treatments → aim to **create few to several nanometers of nitrogen enriched layer** on top of clean EP bulk, to attempt to bring together the benefit of the Q and gradient
- Nitrogen enriched nanometric layer to be created in the furnace post 800C treatment – when no oxide is present at the moment of injection of nitrogen at low T
- Studies aim also at fundamental understanding of HFQS and 120C cure of high field Q slope

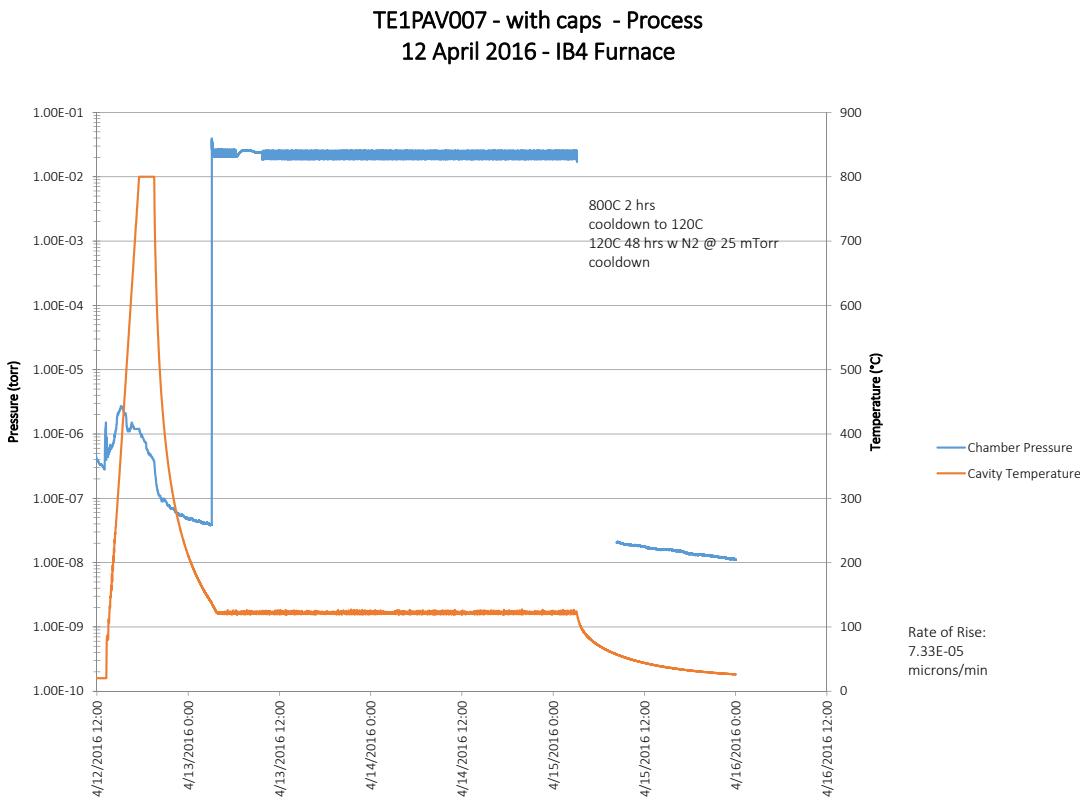
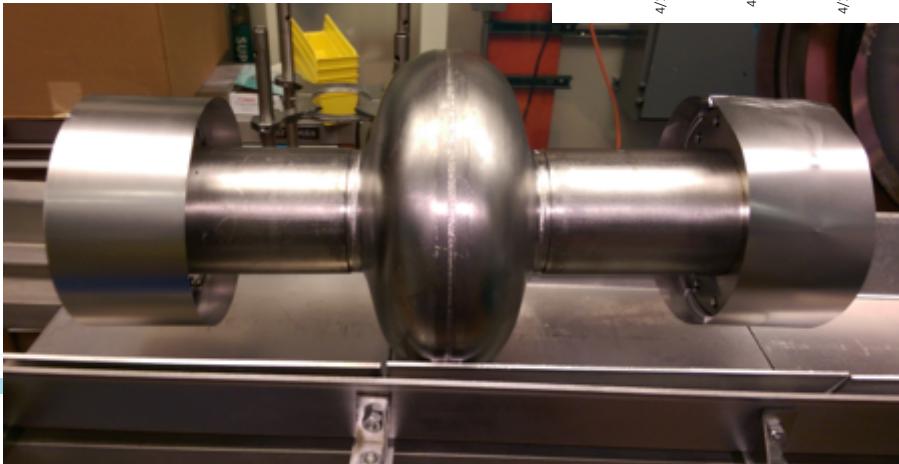
# Kubo and Checchin models on bi-layer potentially increasing achievable accelerating gradients

- This idea is further strengthened by Checchin (FNAL) and Kubo (KEK) models on bi-layer structure (eg dirty N doped layer on clean Nb) –claim that can enhance the achievable accelerating gradient
- Ideal Depth of this layer ? Can this trick help push beyond the 200 mT or achieve 200 mT with higher yield? We are investigating this empirically via low T N infusion (different T and durations)



# Example of new surface processing sequence

- Bulk electro-polishing
- High T furnace with caps to avoid furnace contamination:
  - 800C 3 hours HV
  - 120C 48 hours with N2 (25 mTorr)
- NO chemistry post furnace
- HPR, VT assembly

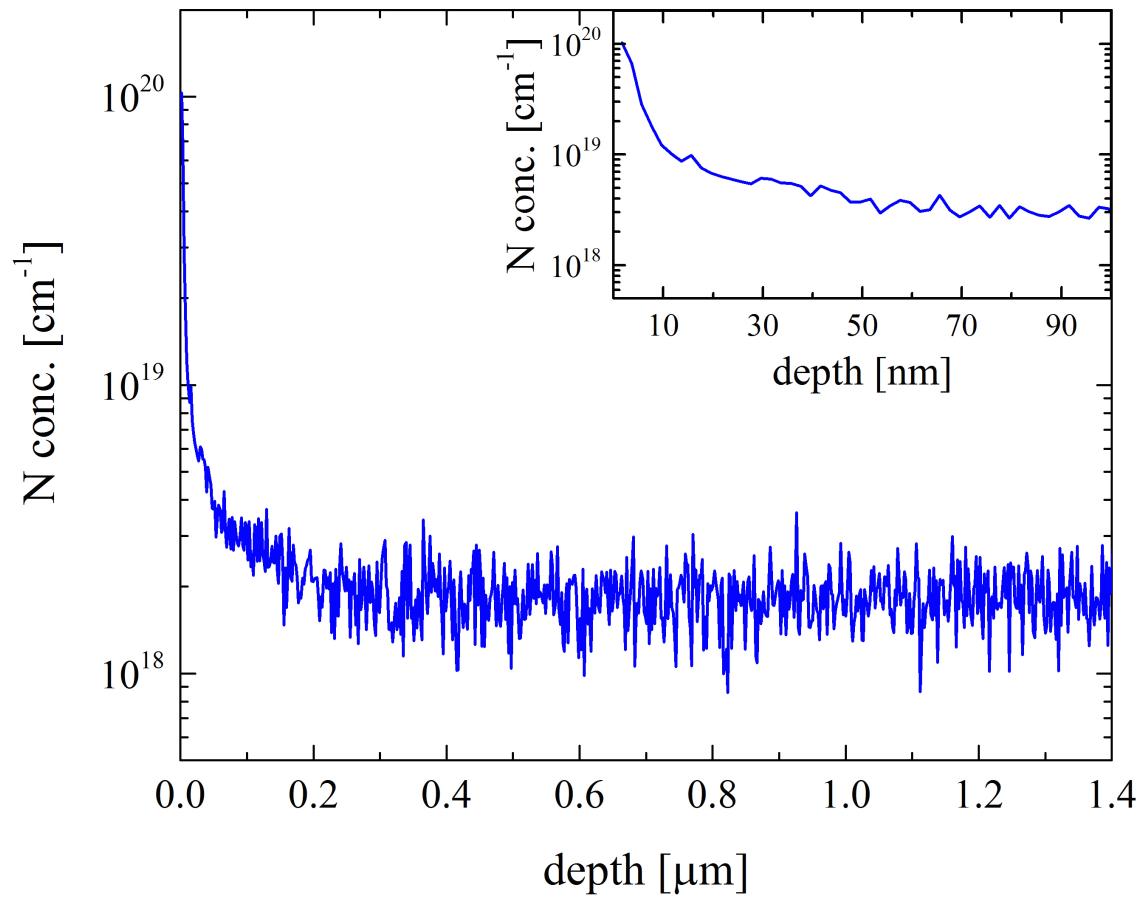


Protective caps and foils are BCP'd prior to every furnace cycle and assembled in clean room, prior to transporting cavity to furnace area

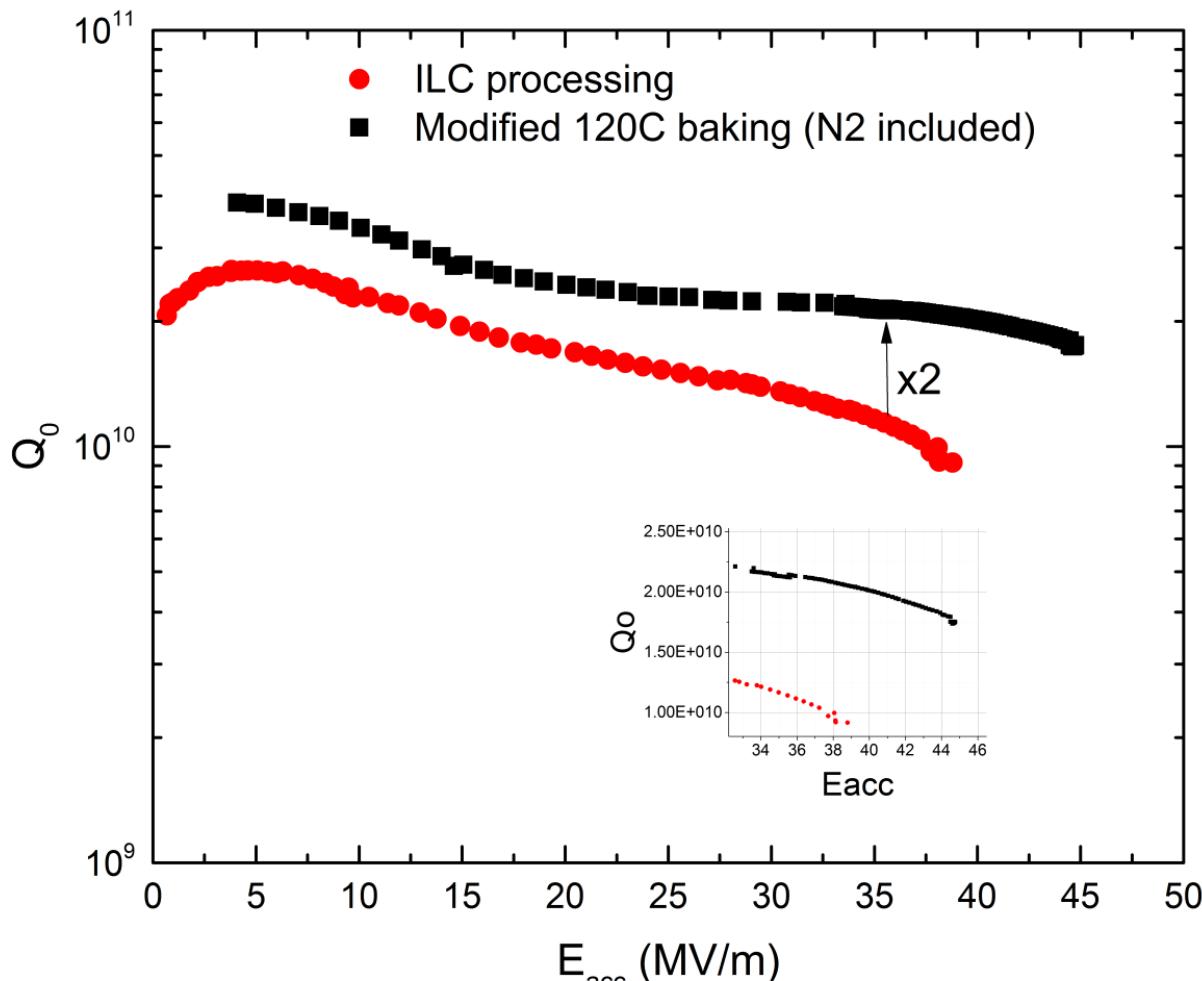
[A. Grassellino et al, arXiv:1305.2182](https://arxiv.org/abs/1305.2182)

# To what depth does nitrogen diffuse?

- First SIMS measurements on samples baked with cavities in furnace with N at low T show ~ few-tens nm potential nitrogen enriched layer, depending on T used



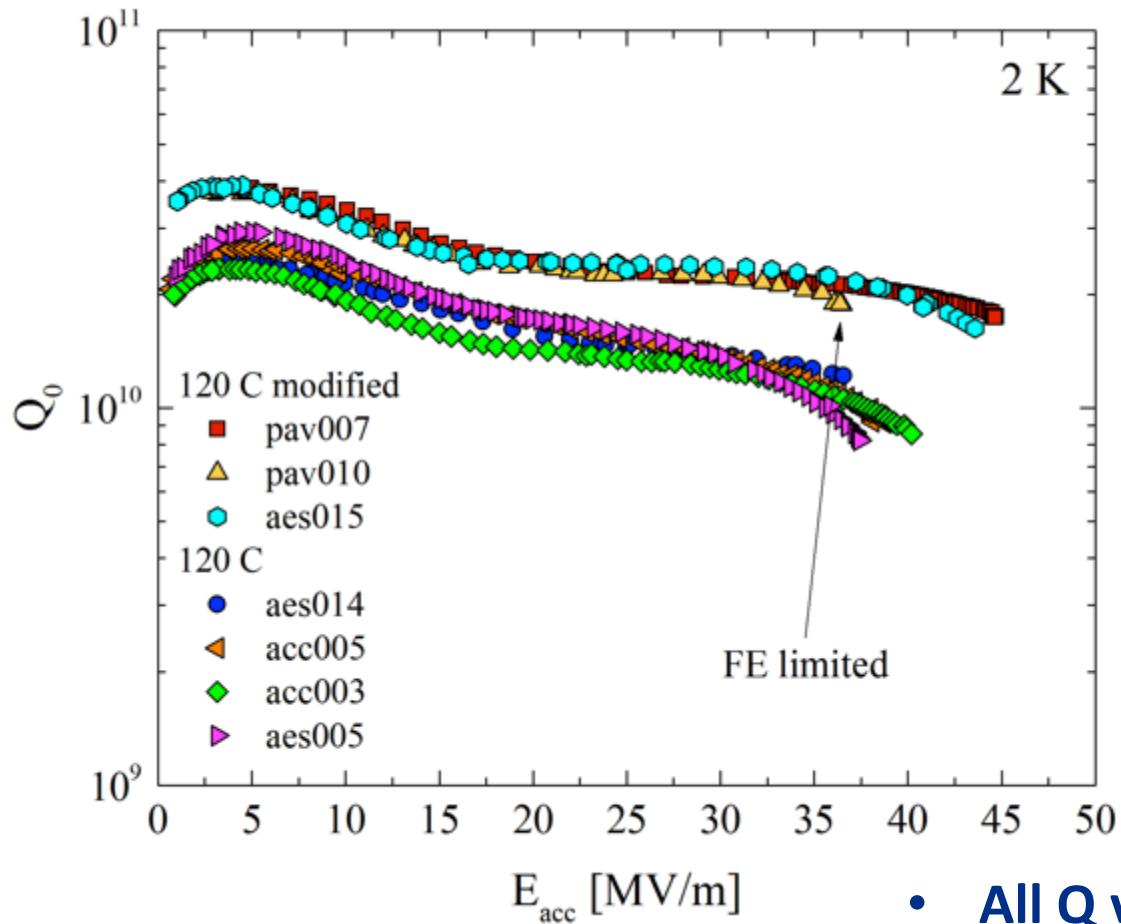
# Results comparison : “standard” 120C bake vs “N infused” 120C bake



Increase in Q factor of two, increase in gradient  $\sim 15\%$

- Same cavity, sequentially processed, no EP in between
- Achieved:  
 $45.6 \text{ MV/m}$   
 $\rightarrow 194 \text{ mT}$   
With  $Q \sim 2e10!$
- $Q$  at  $\sim 35 \text{ MV/m}$   
 $\sim 2.3e10$
- All  $Q$  vs  $E$  curves shown are for 1.3 GHz single cells,  
 $T=2\text{K}$

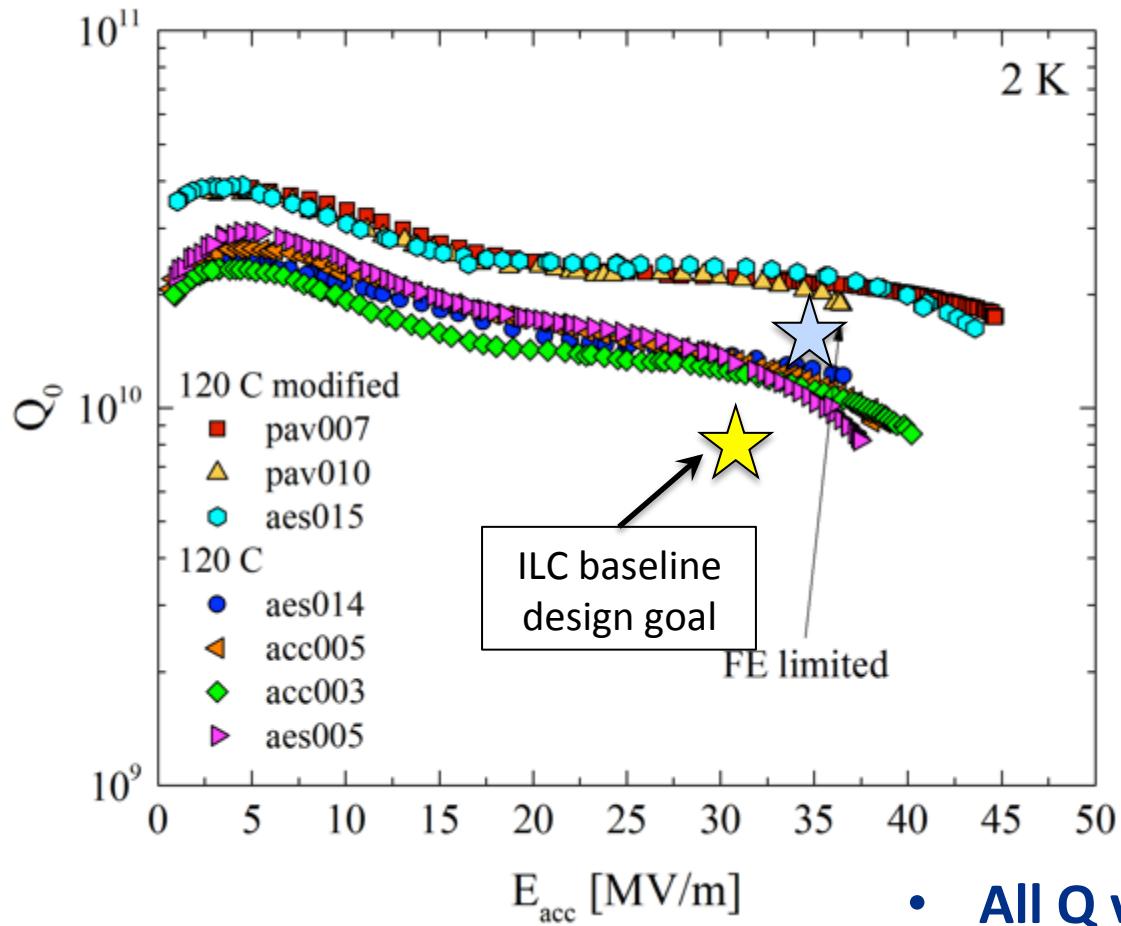
# Reproducibility: repeatedly highest Q ever measured >2e10 at very high gradients > 40 MV/m!



- So far three out of 4 cavities processed with this regime have reached 45 MV/m with high Q
- Performed slow cooldown in 10mG and extracted very low sensitivity to B on order of 0.3 nOhm/mG  
-> very robust for Q preservation

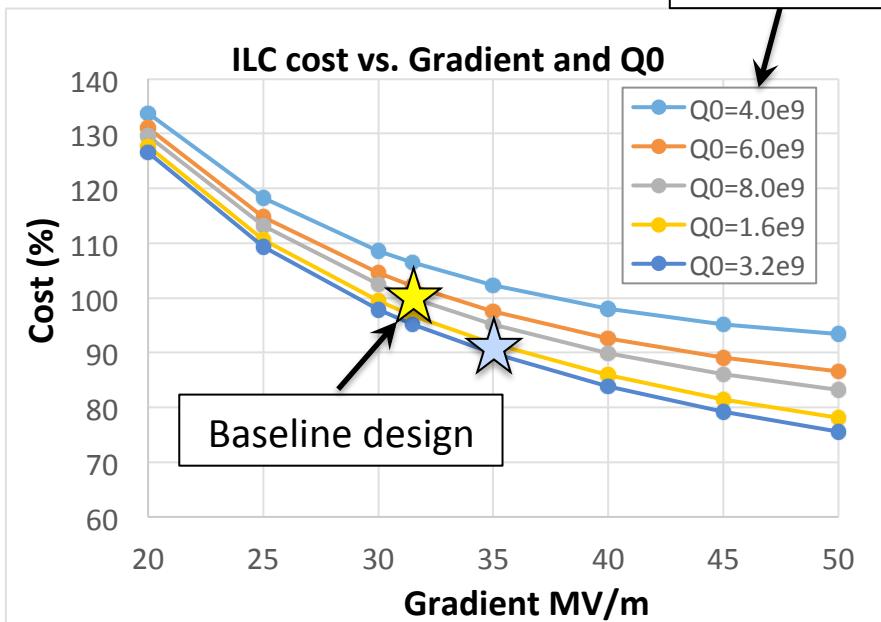
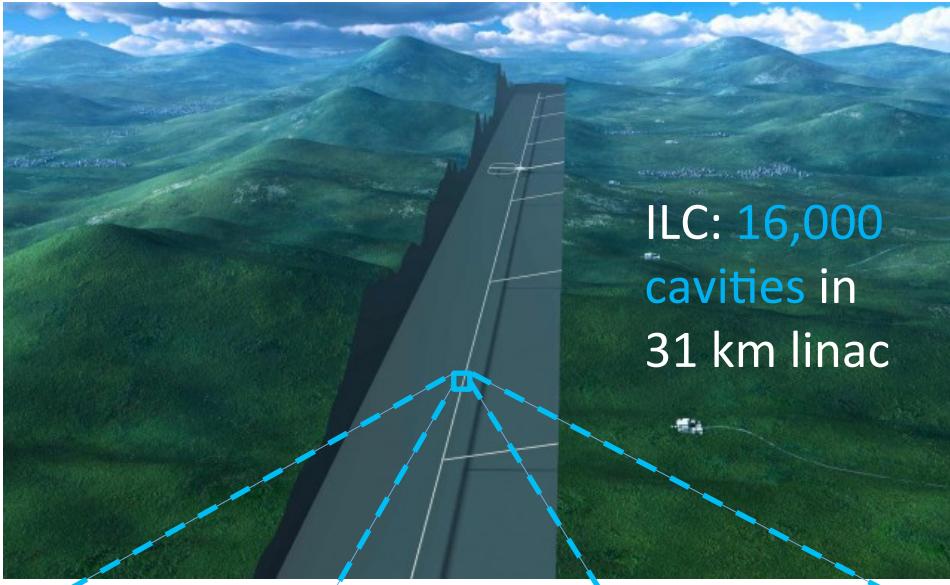
- All Q vs E curves shown are for 1.3 GHz single cells, T=2K

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- All Q vs E curves shown are for 1.3 GHz single cells, T=2K

# Gradient $\rightarrow$ Length for Linear Accelerator

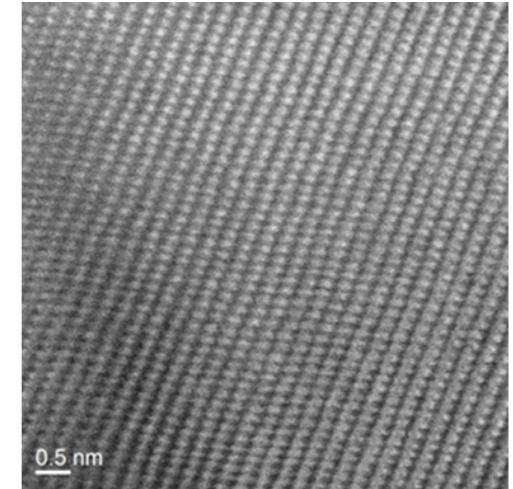


# Outline

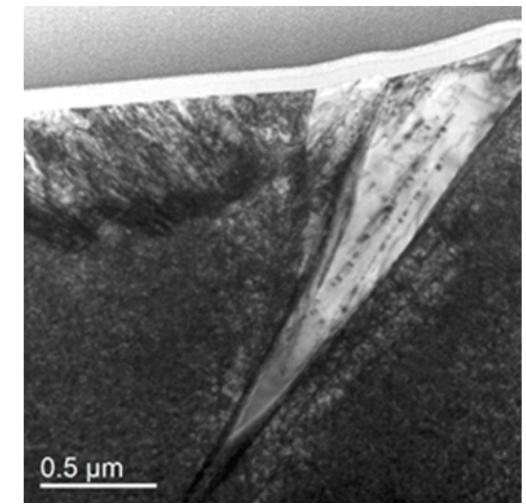
- High  $Q_0$  (medium  $E_{acc}$ )
  - Nitrogen doping
  - Flux expulsion
- High  $E_{acc}$  and high  $Q_0$ 
  - Nitrogen infusion
  - Nb<sub>3</sub>Sn
  - Plasma cleaning



ILC cryomodule with record average gradient for FAST facility

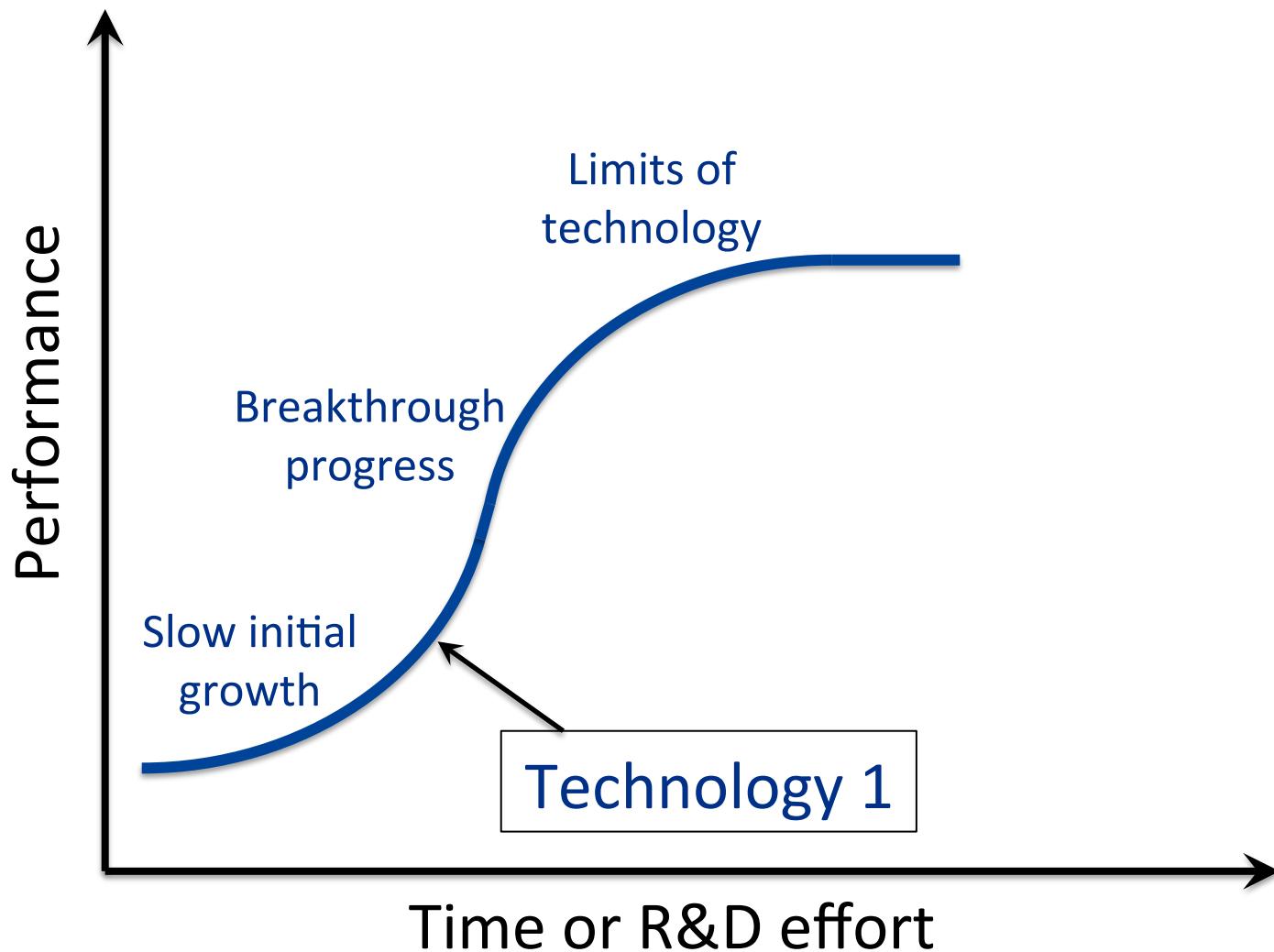


Aberration-corrected STEM image of the near-surface of Nb cavity - Y. Trenikhina

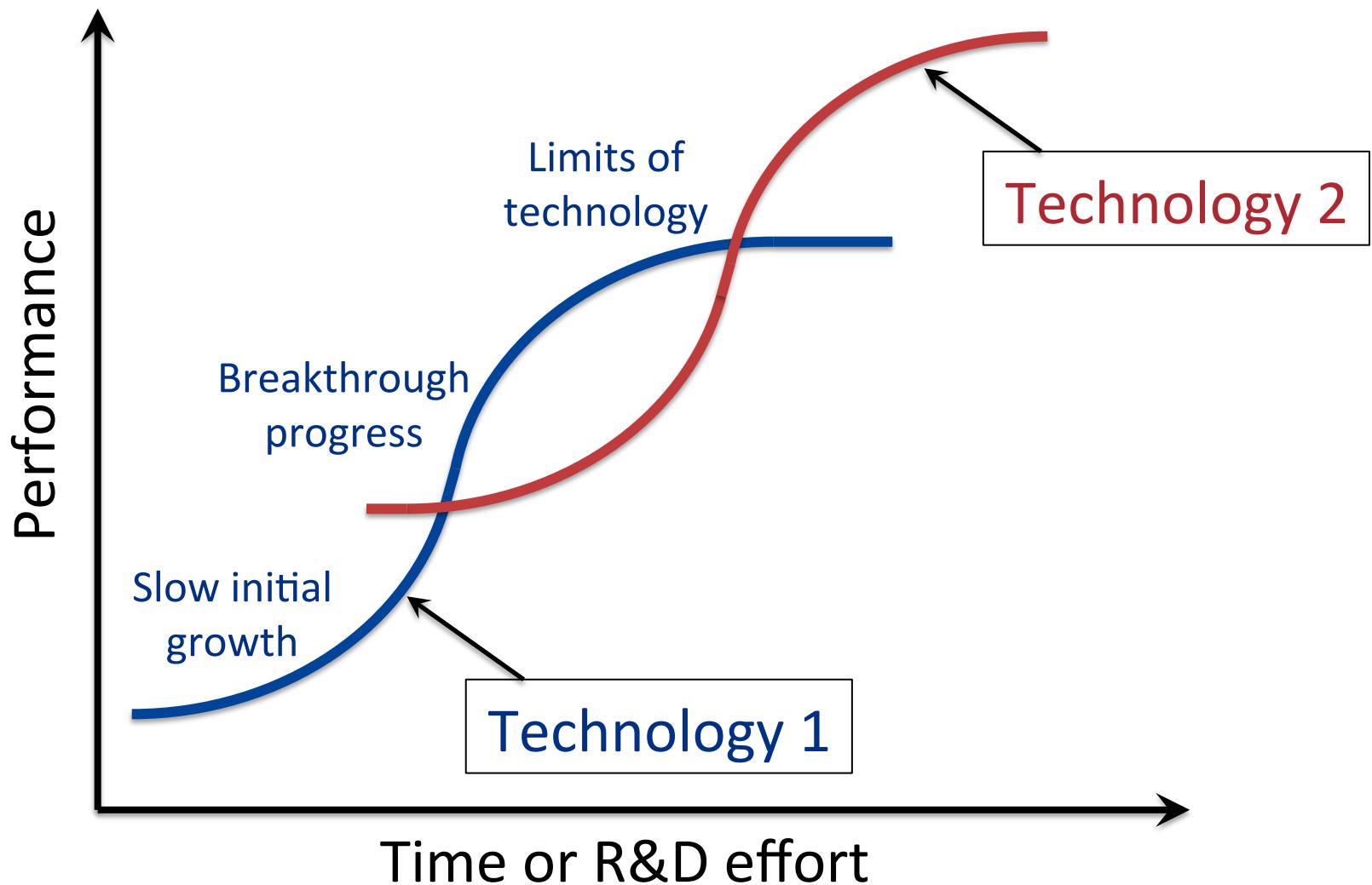


Niobium near-surface after the first step of nitrogen doping - Y. Trenikhina

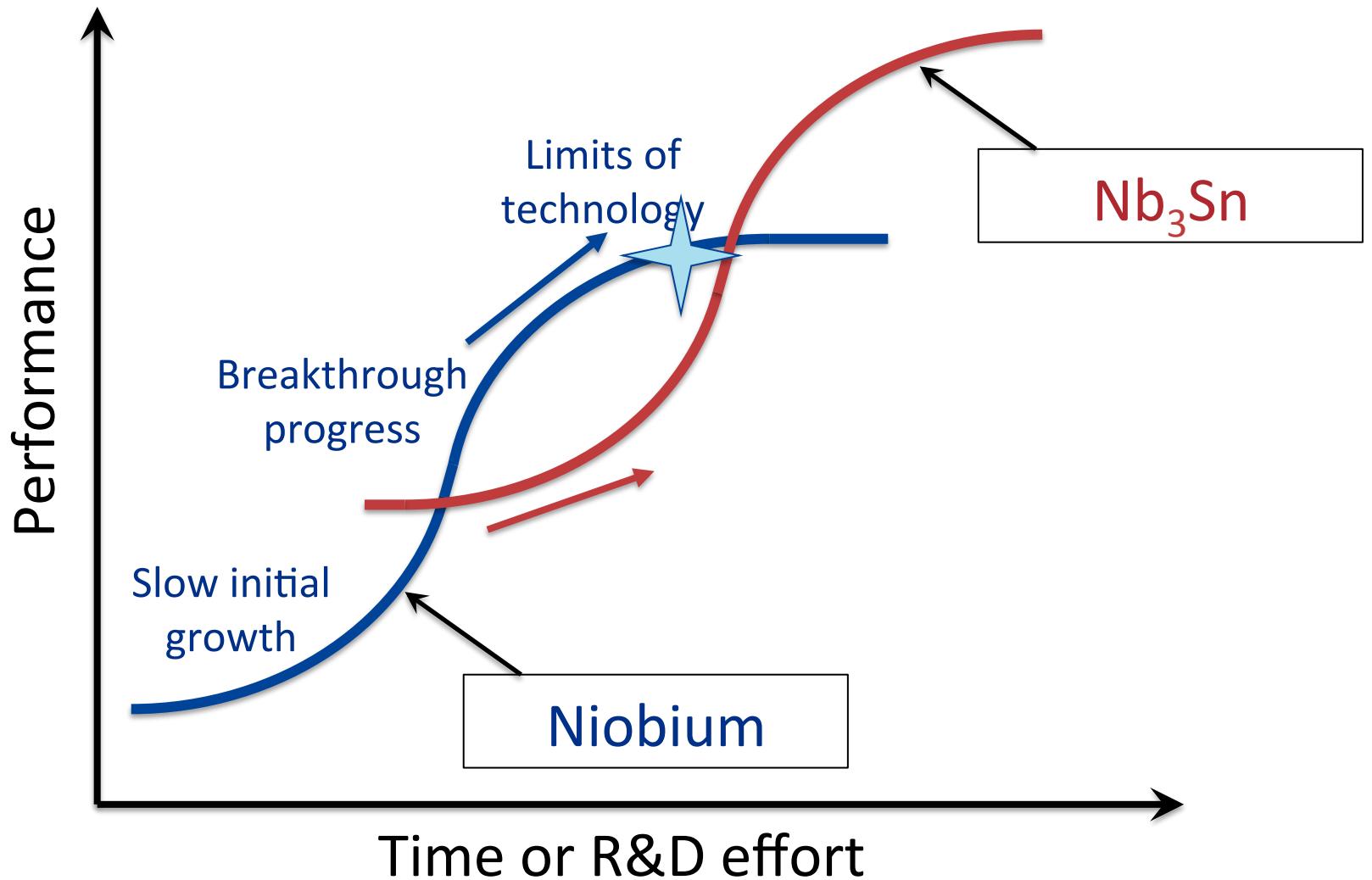
# 'S-shaped technology curve'



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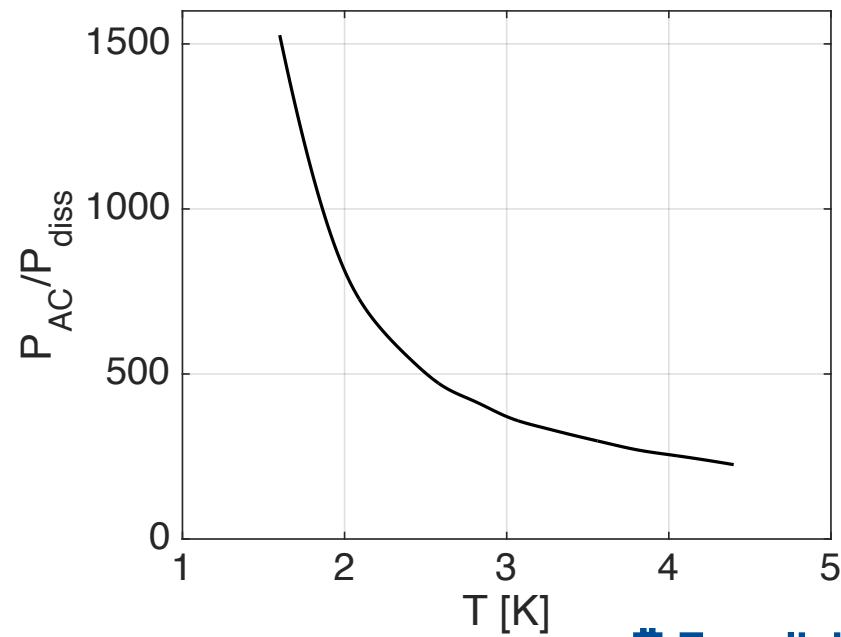
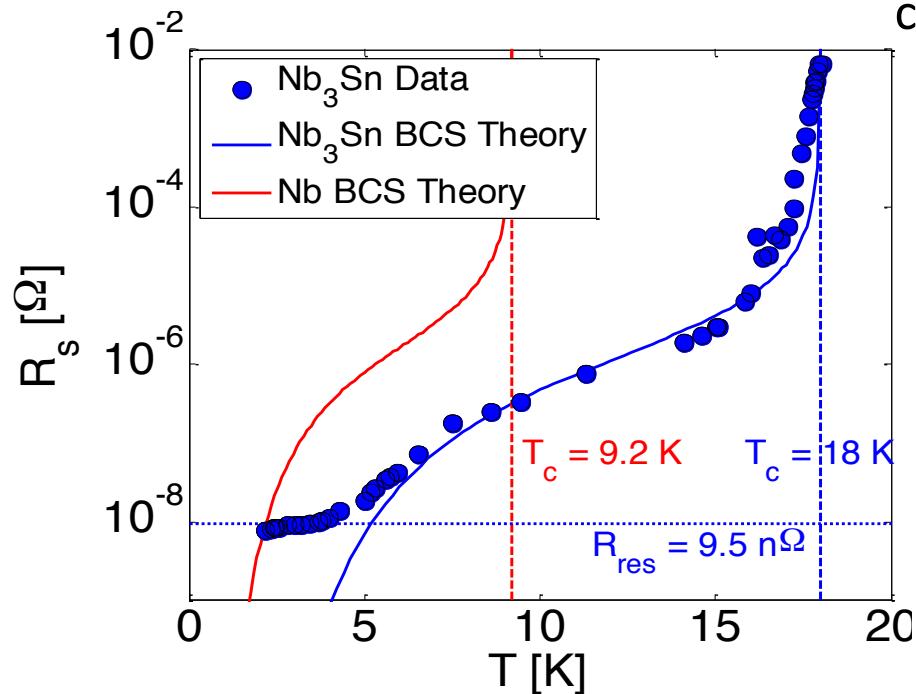


# $\text{Nb}_3\text{Sn } Q_0(T)$

- Large  $T_c \sim 18 \text{ K}$ 
  - Very small  $R_{\text{BCS}}(T) - R_{\text{BCS}}(T) \sim e^{-1.76T_c/T}$
  - High  $Q_0$  even at relatively high  $T$
- Higher temperature operation
  - Simpler cryogenic plant
  - Higher efficiency



Big effect! Cryoplants for large installations cost  $\sim \$100 \text{ million}$  and require **MW of power**



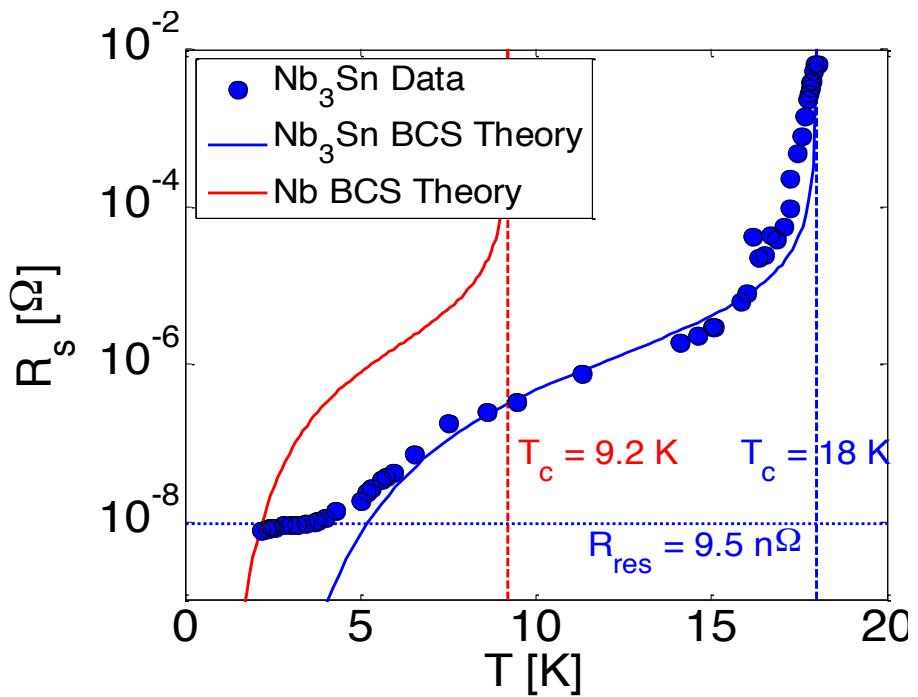


# Higher $Q_0(T)$ with $\text{Nb}_3\text{Sn}$

- Large  $T_c \sim 18 \text{ K}$ 
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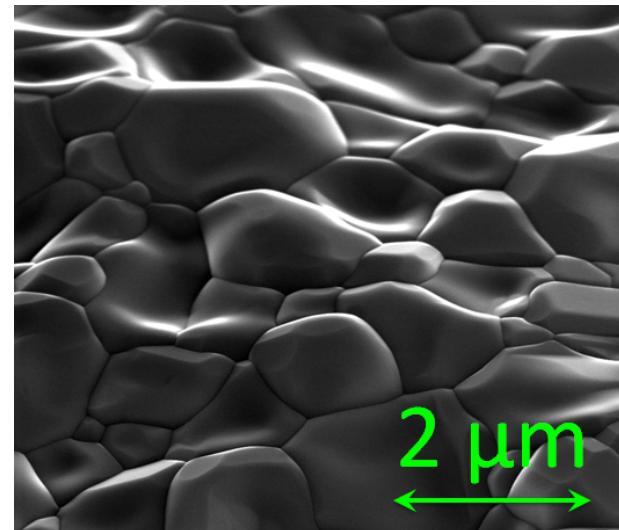
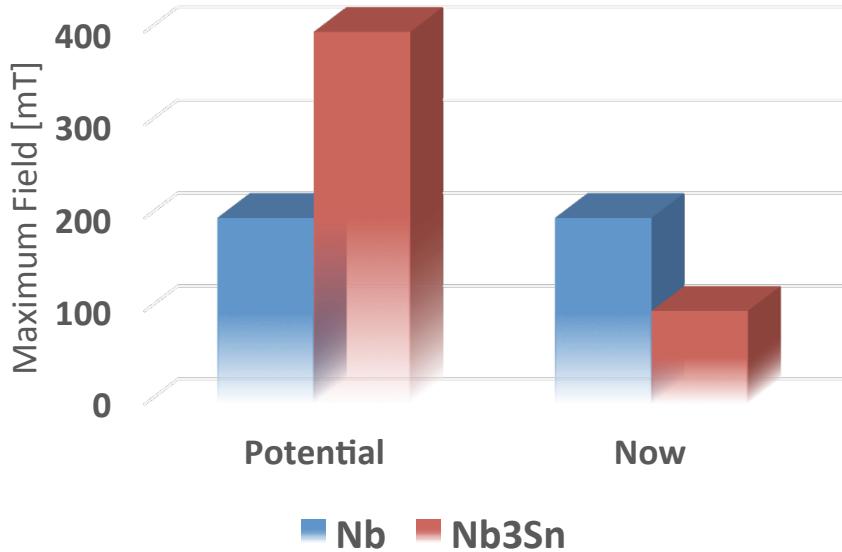


Possibility of cryocooler operation! Industrial accelerators for treatment of wastewater & flue gas, border security...



# High $H_{sh}$ with $Nb_3Sn$

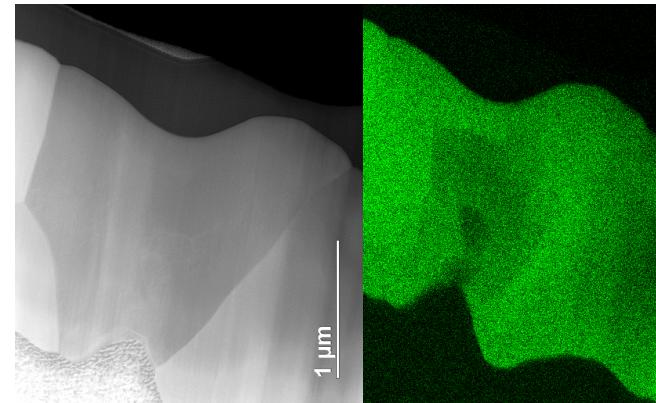
- $Nb_3Sn$  is predicted to have **2x** the fundamental metastable limit of niobium



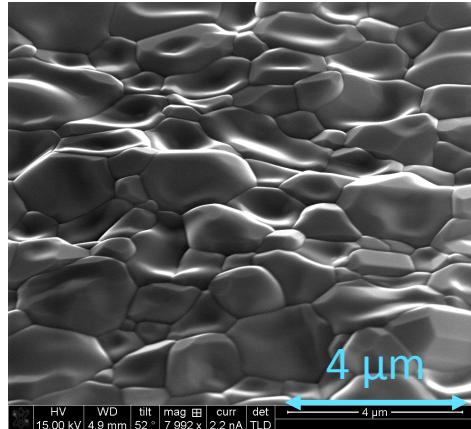
- Twice the energy gain per cavity?
- Not there yet—additional R&D required

# Increasing $E_{acc}$ in Nb<sub>3</sub>Sn Cavities

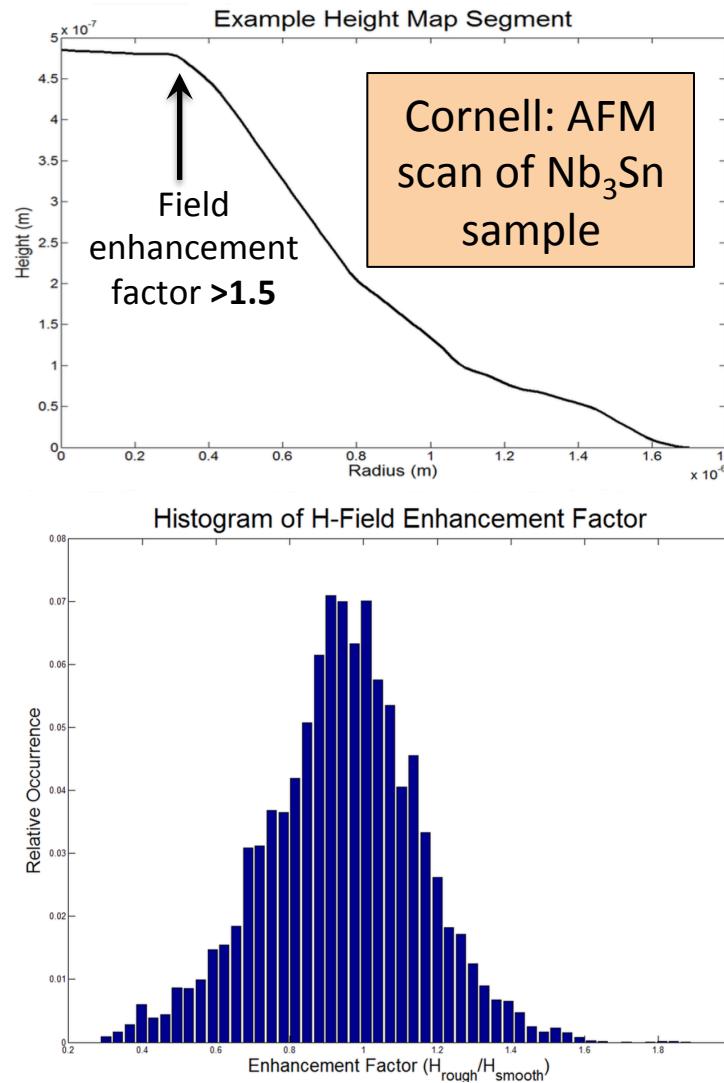
- Substantial recent improvement in maximum  $E_{acc}$  with high  $Q_0$
- Several promising paths forward for continued progress including:
  - Smooth sharp-edged surfaces
  - Reduce low tin content regions
- 20-40% increase: 22-25 MV/m



Y. Trenikhina, S. Posen, D. Hall, and M. Liepe,  
Proc. SRF Conference 2015, TUPB056, 2015



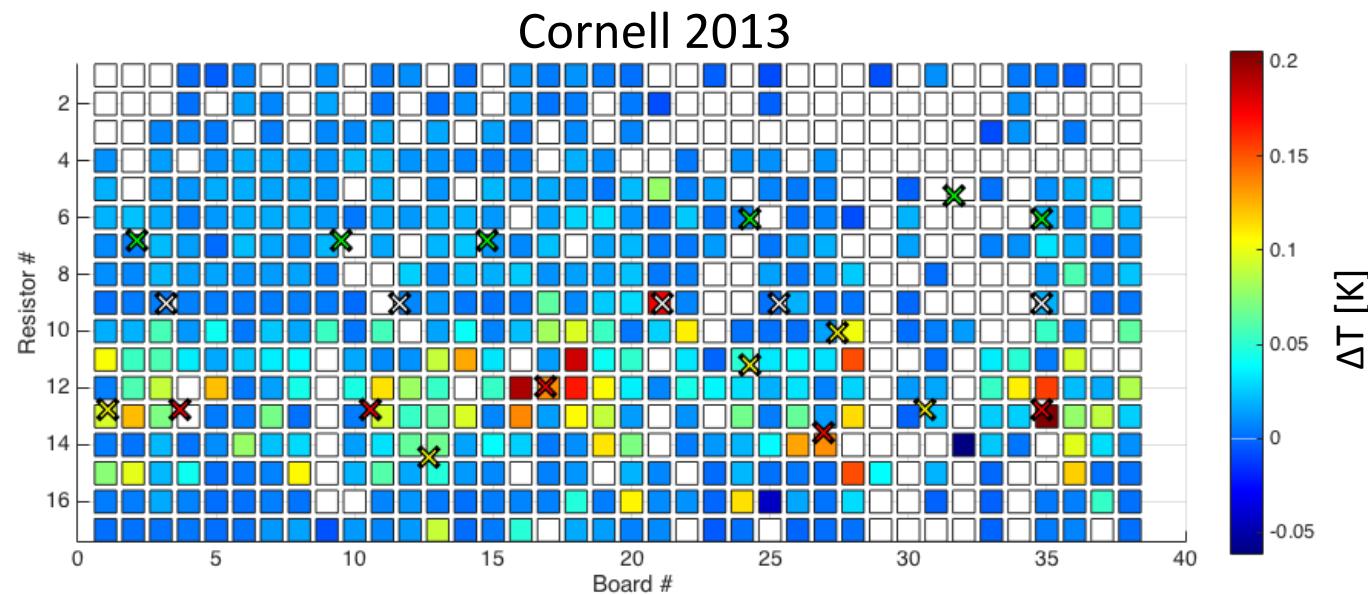
S. Posen, Ph.D. Thesis, Cornell  
University (2015).



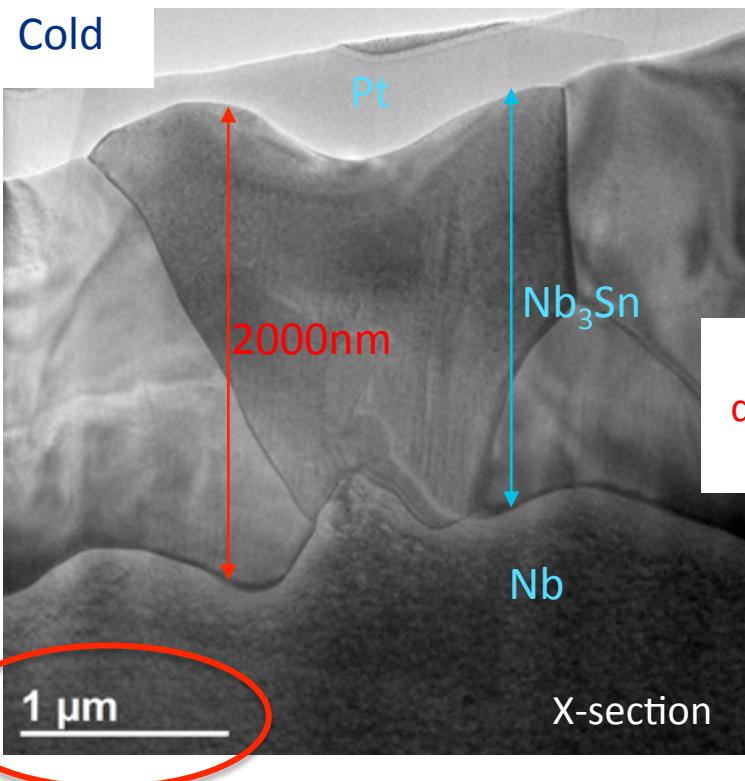
R. Porter, D. L. Hall, M. Liepe, J. T. Maniscalco,  
Proc. Linac Conference 2016, MOPRC027 (2016).

# Coupons from Poorly Performing Cavity

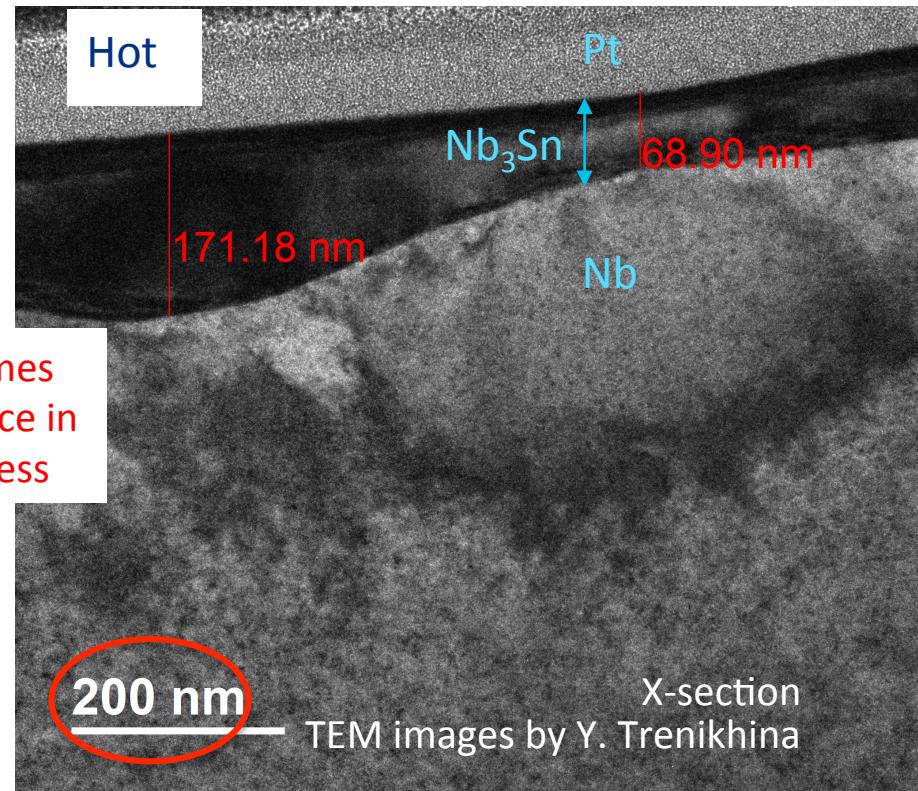
- Poorly performing cavity coated in 2013
- In collaboration with Cornell, both labs retested it and cut out coupons from regions that showed high  $R_s$  and low  $R_s$  (hot spots and cold spots)



# Thin Coatings in High Dissipation Hot Spots



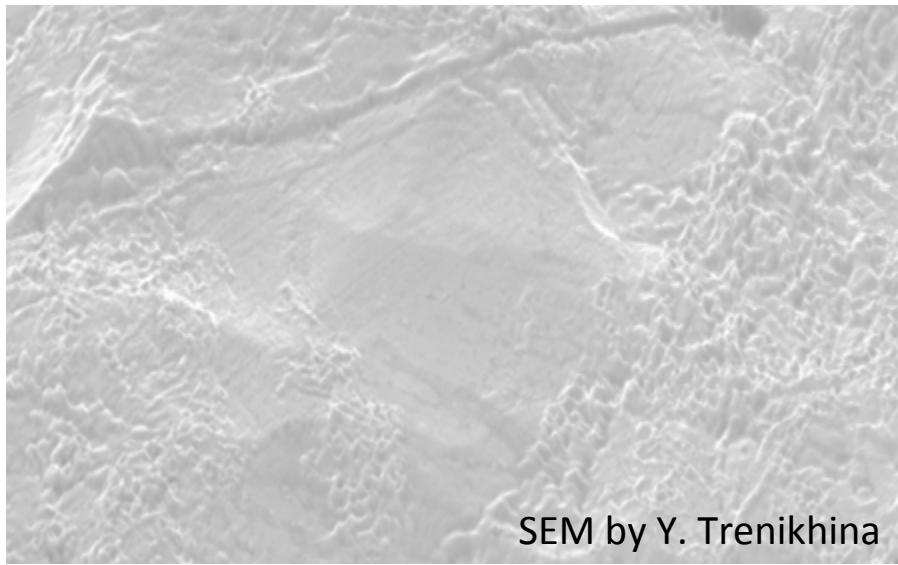
>10 times  
difference in  
thickness



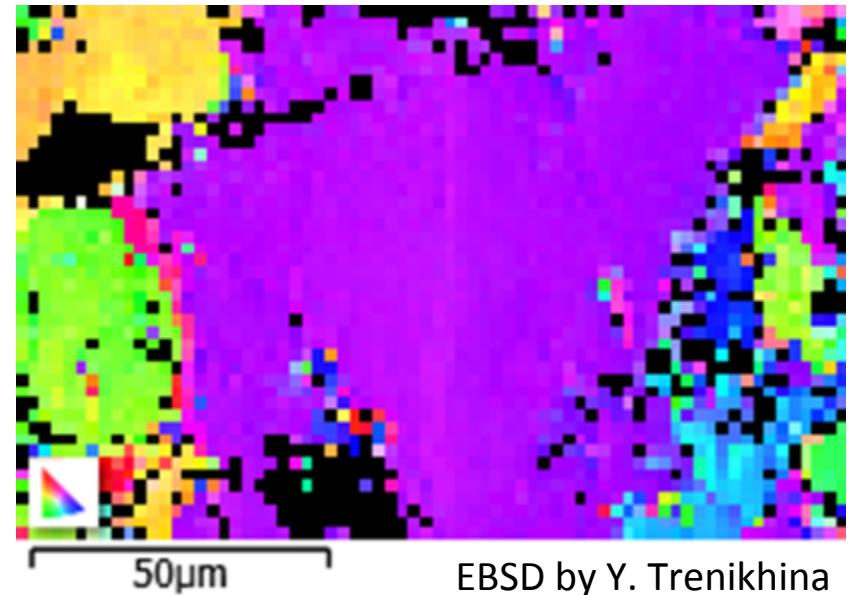
- Regions with highest dissipation show very thin coatings, not thick enough to fully screen RF currents from Nb and intermediate Nb-Sn phases below Nb<sub>3</sub>Sn layer

# Thin Regions are Unusually Large Grains

- EBSD analysis of grain orientation reveals that the thin regions in the hot spots are in fact large grains, with diameter ~100 microns vs ~1 micron for standard Nb<sub>3</sub>Sn grains



SEM by Y. Trenikhina

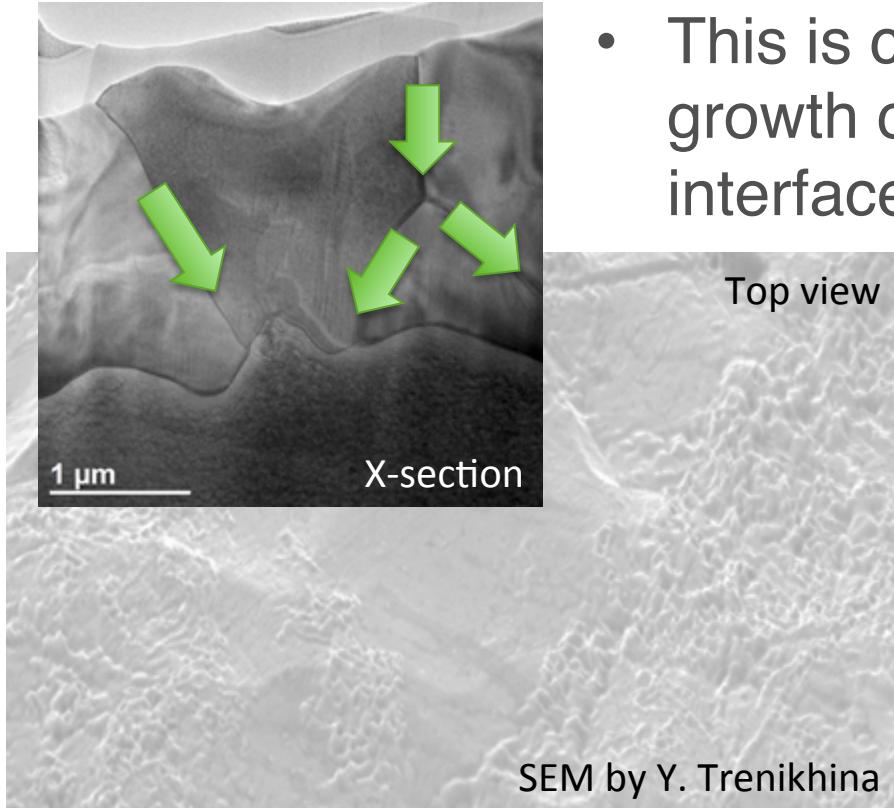


EBSD by Y. Trenikhina

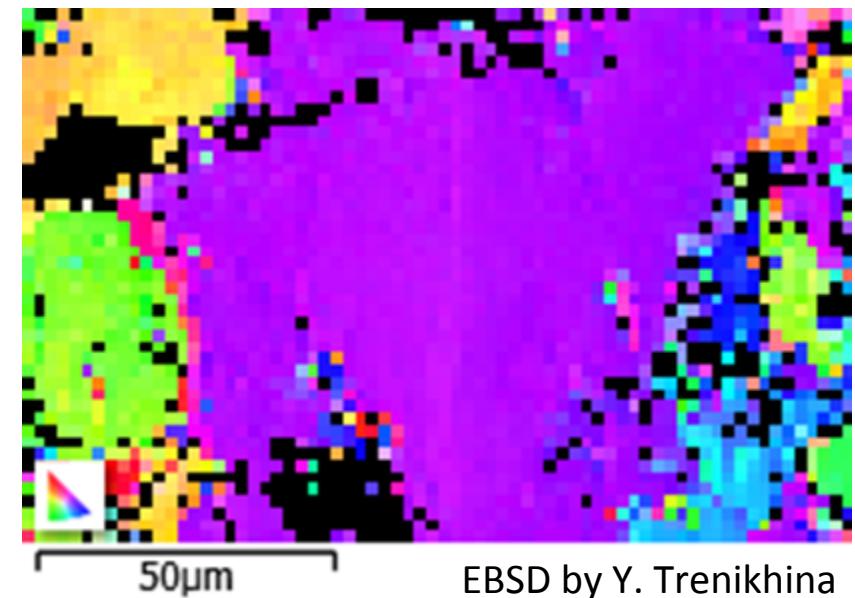


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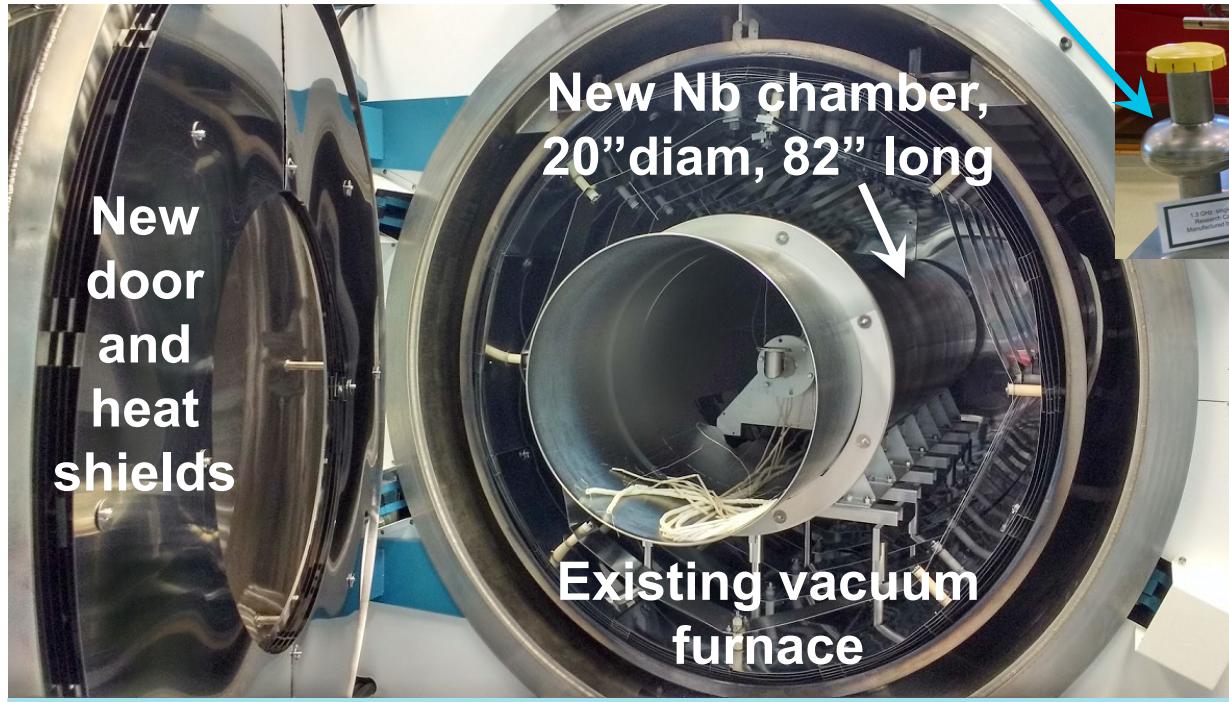
- This is consistent with mechanism for growth of grains: diffusion of tin to interface via grain boundaries



# Nb<sub>3</sub>Sn SRF Experimental Program at Fermilab

- Goals: 1) further improvement to  $Q_0$  and  $E_{acc}$  2) scale up to production-style cavities
- Large Nb<sub>3</sub>Sn SRF coating apparatus recently commissioned
- First samples coated Jan 30, 2017

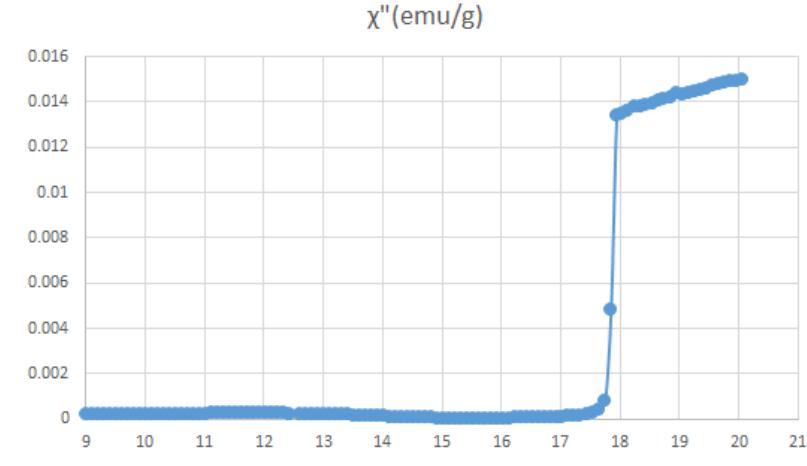
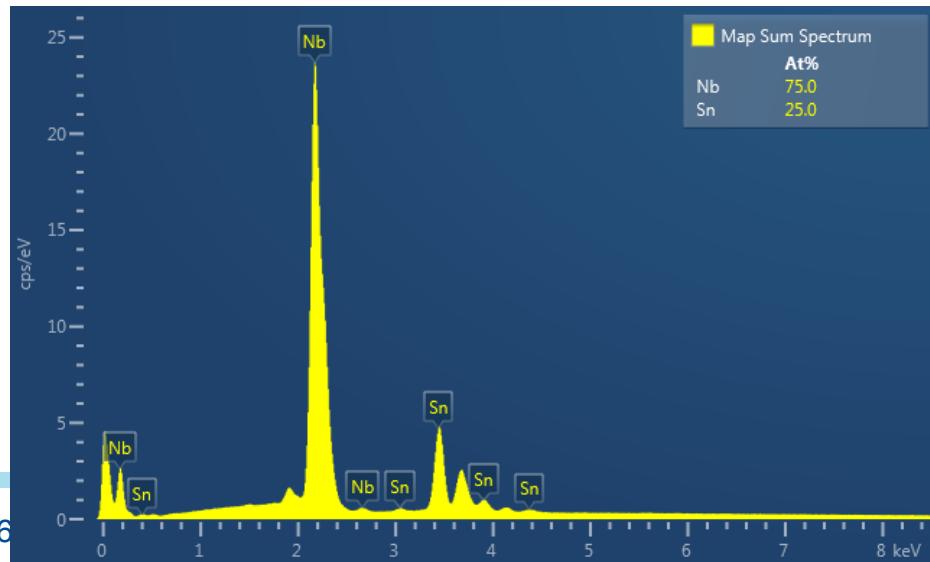
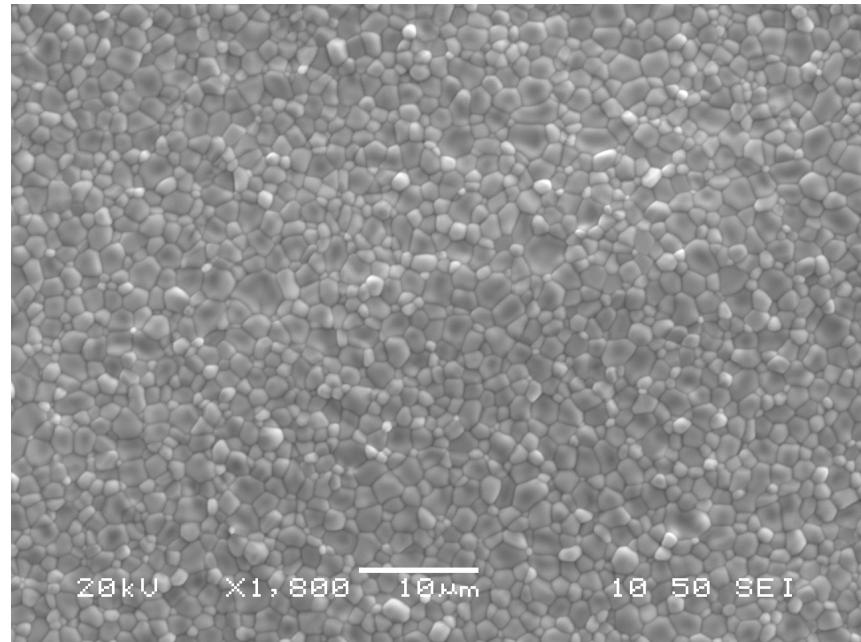
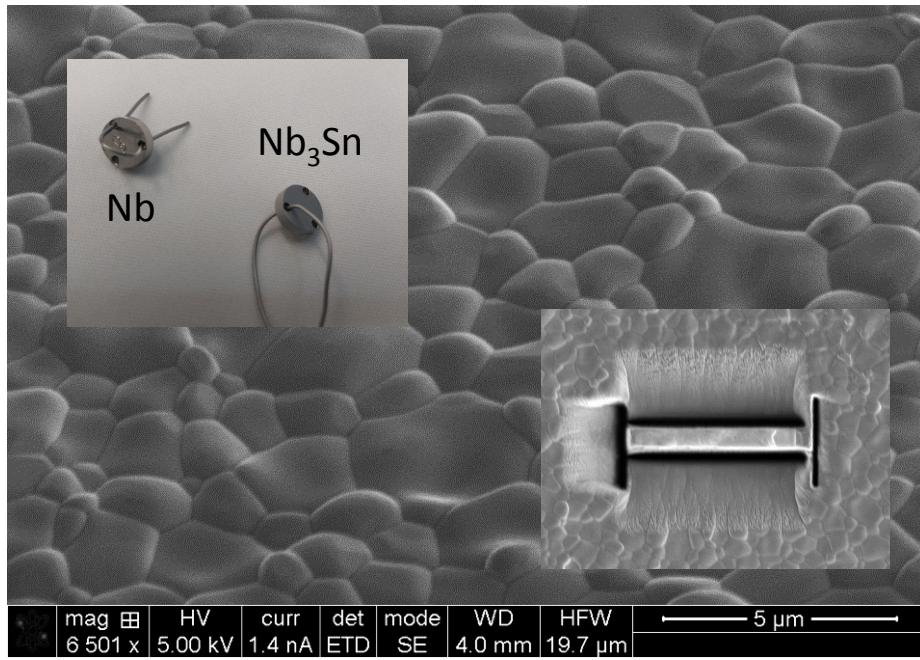
1.3 GHz 1-cell (current state of Nb<sub>3</sub>Sn R&D)



650 MHz 5-cell (future)



# First $\text{Nb}_3\text{Sn}$ Samples via Vapor Diffusion at FNAL

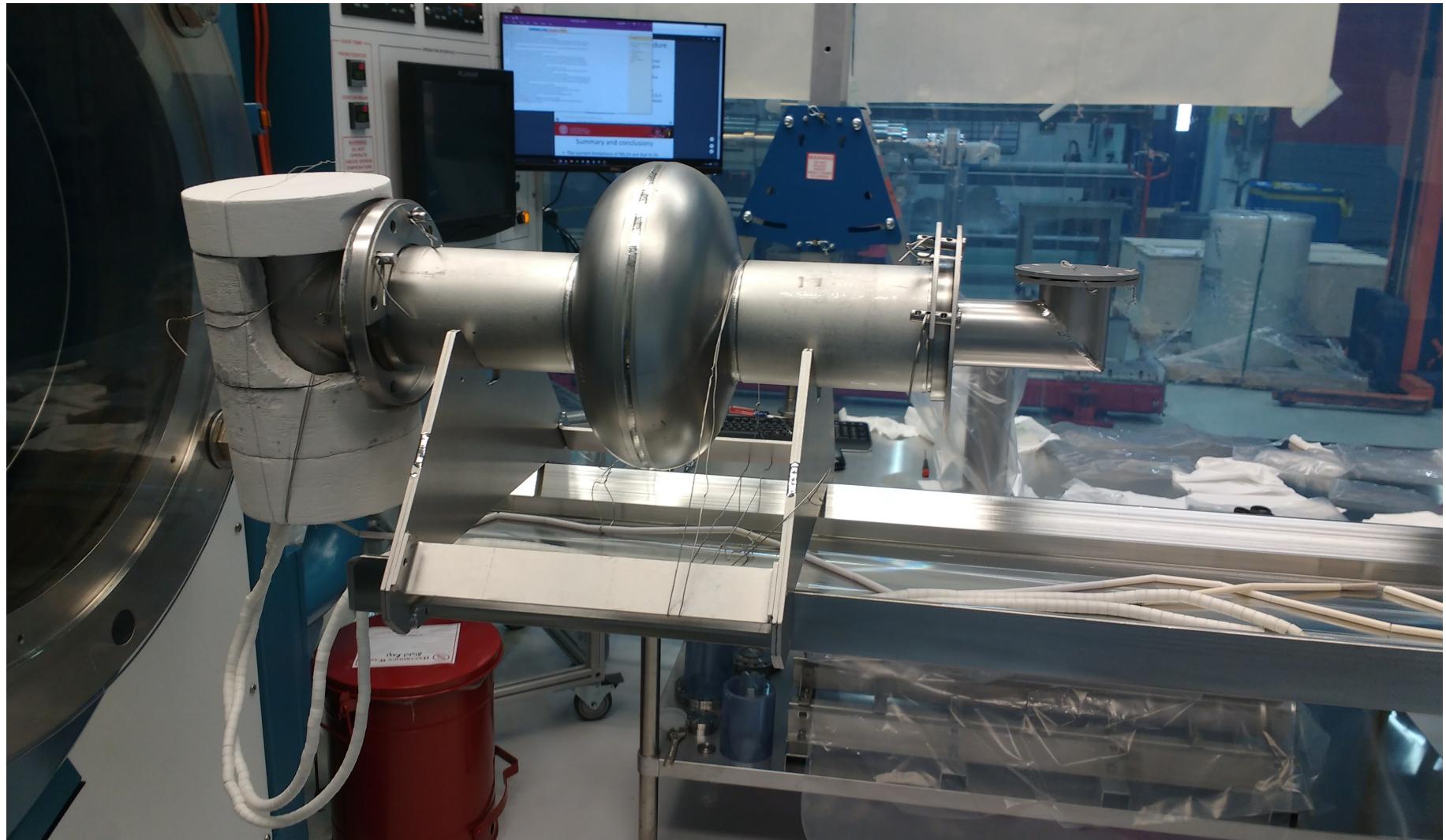


Fermilab  
Measurements by Yulia Trenikhina (FNAL),  
Jae-Yel Lee (Northwestern), and Zuhawn Sung (FNAL)

# Excitement Brewing for Nb<sub>3</sub>Sn SRF Coatings



# First Fermilab Nb<sub>3</sub>Sn Cavity Coated – RF Test Soon

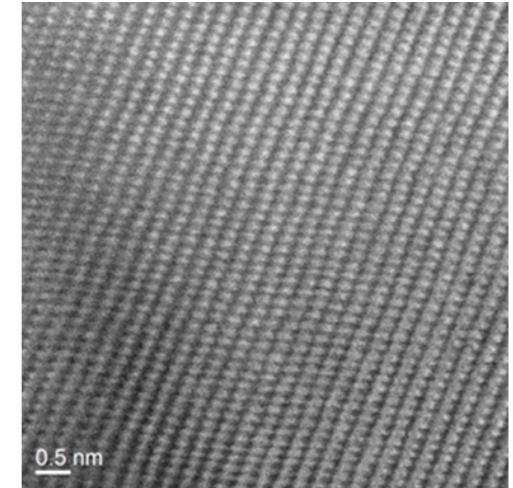


# Outline

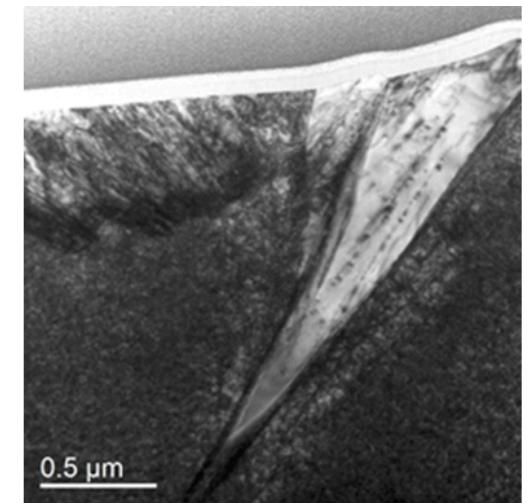
- High  $Q_0$  (medium  $E_{acc}$ )
  - Nitrogen doping
  - Flux expulsion
- High  $E_{acc}$  and high  $Q_0$ 
  - Nitrogen infusion
  - $\text{Nb}_3\text{Sn}$
  - Plasma cleaning



ILC cryomodule with record average gradient for FAST facility



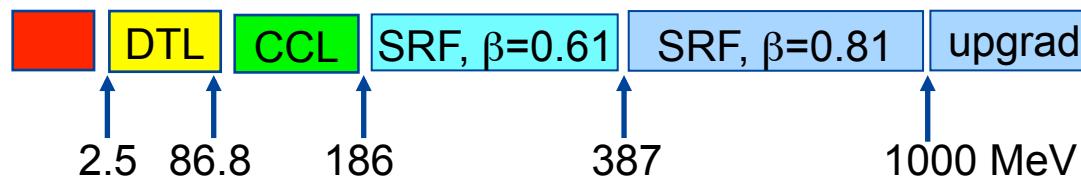
Aberration-corrected STEM image of the near-surface of Nb cavity - Y. Trenikhina



Niobium near-surface after the first step of nitrogen doping - Y. Trenikhina

# In-situ plasma processing at SNS

- Most cavities at SNS are limited by field emission (FE) leading to thermal instability in end-groups
  - Avg. Eacc are  $\sim$ 12 and 13 MV/m for the two cavity geometries
- In-situ plasma processing to reduce FE and increase accelerating gradients
  - Higher linac output energy adds margin for reliable operation at 1.4 MW
  - Aim is to increase high-beta SRF cavities gradient by 15%



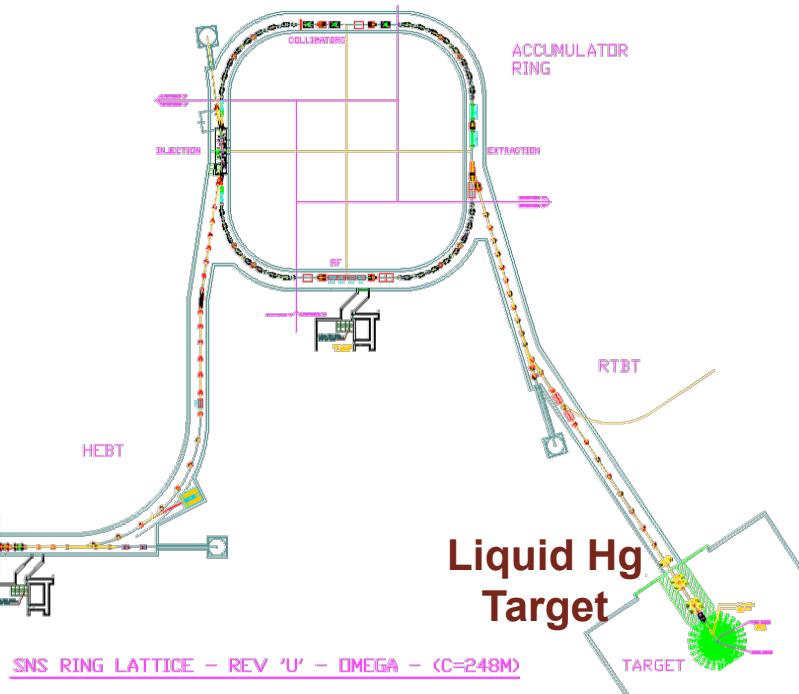
## Front-End:

1 msec long chopped H-beam at 60 Hz

## Linac:

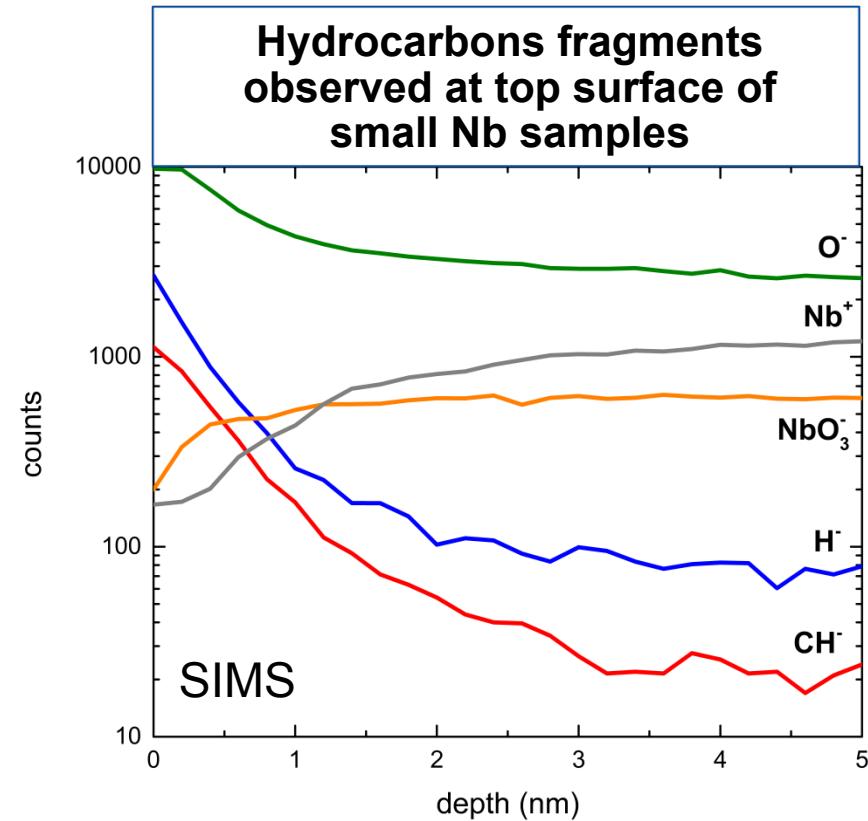
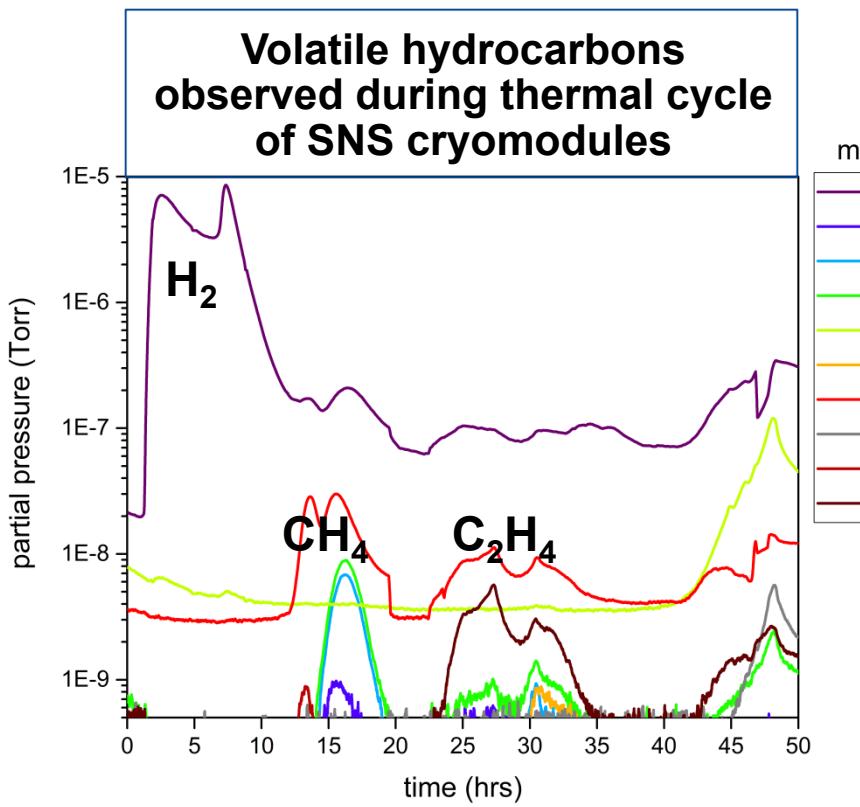
Accelerates beam to 1 GeV  
SRF linac: 23 cryomodules

Accumulator Ring:  
Compress 1 msec long pulse to 700 ns



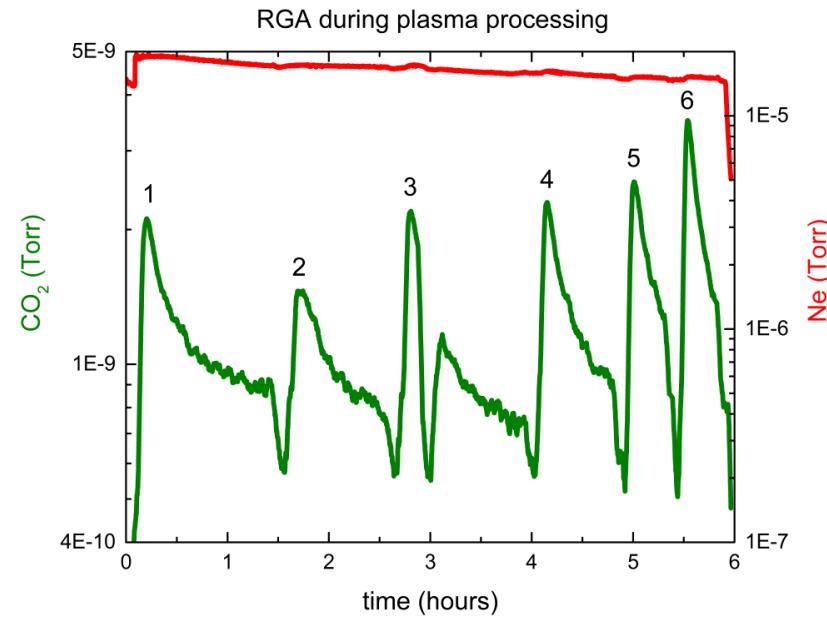
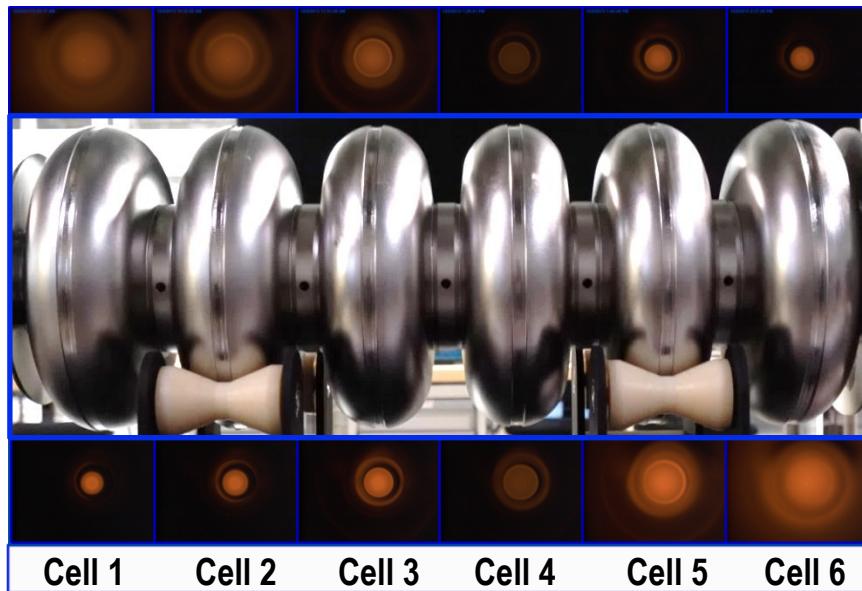
# Hydrocarbon contaminants on Nb surfaces

- Hydrocarbon contamination observed on various Nb surfaces
- Hydrocarbons lowers the work function of Nb surface
  - Lower work function aggravates field emission
  - In-situ plasma processing at SNS removes hydrocarbons from cavity RF surface

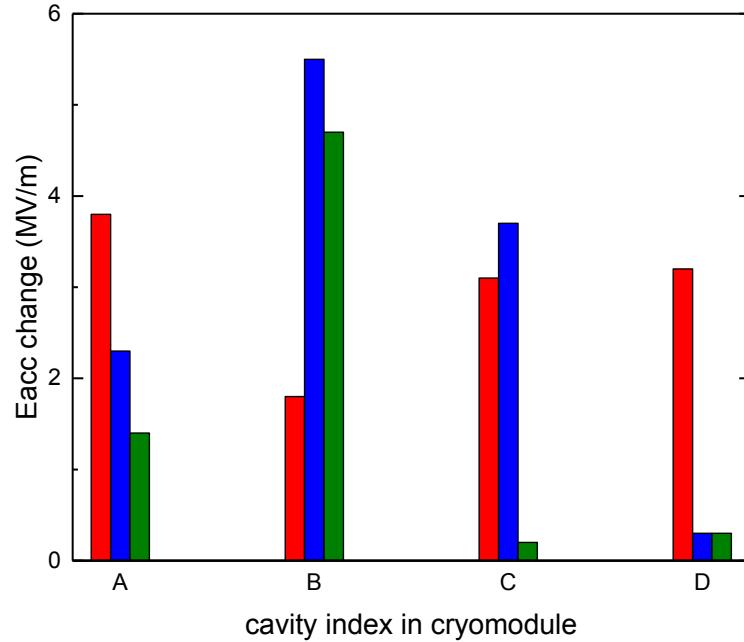
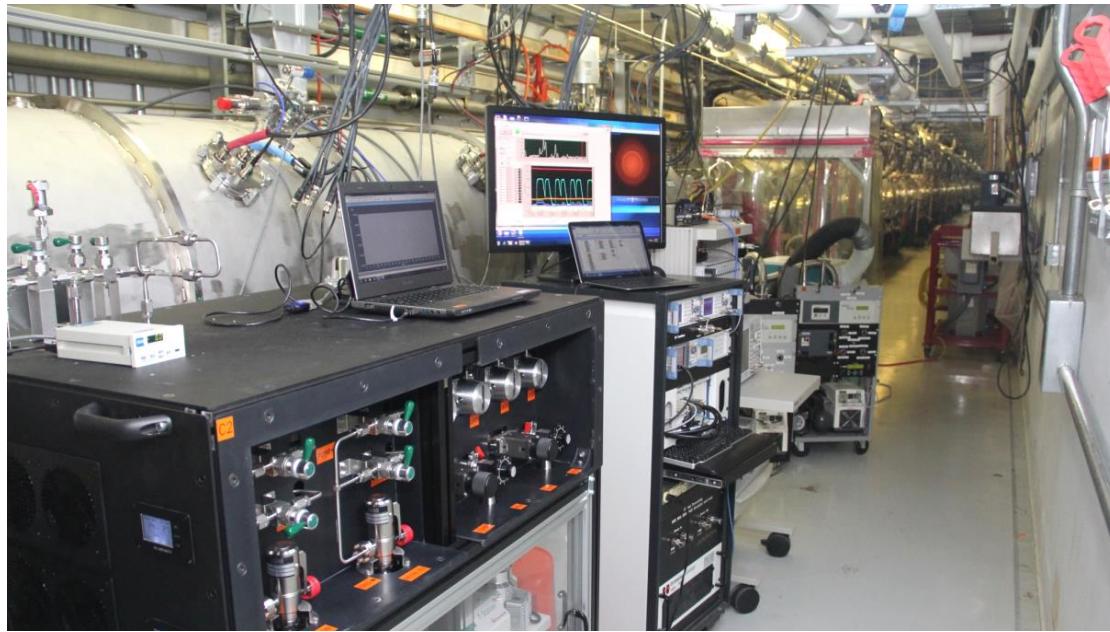


# Neon-oxygen cleaning applied to SNS HB cavities

- Reactive oxygen plasma at room-temperature
  - 150 mTorr neon gas with ~1% oxygen
- Hydrocarbons removed from top surface through oxidation and formation of volatile by-products such as CO<sub>2</sub>
- Residual gas analysis used to monitor plasma cleaning
  - Observed removal of ~monolayers equivalent of hydrocarbons
  - Six cells of SNS cavities cleaned sequentially



# Plasma processing in SNS tunnel started



- **Improvement of Eacc after plasma processing of 3 cryomodules**
  - Ranges from 0.2 MV/m to 5.5 MV/m
  - 2.5 MV/m increase on average so far (21%)
- **SNS linac**
  - Currently operating at 972 MeV
  - Highest energy on production target at 60 Hz to date
  - Plan to reach 1 GeV in FY17

# Mid-Term Goals: Plasma processing for LCLS-II

2017	2018	2019	2020
<b>Present</b>	<b>Goals</b>	<b>Goals</b>	<b>Goals</b>
Applicability of SNS plasma processing to LCLS-II	Plasma ignition in 9-cells cavity	Plasma processing in-situ in a cryomodule-like environment (HTS)	Plasma processing in-situ in LCLS-II cryomodules
Design of RF and vacuum system	Plasma processing and RF test of 9-cell cavities in VTS	Monitor of plasma ignition based on resonance shift	Improve maximum $E_{acc}$ of ~ 15-20 %
<b>Goals</b>			
Plasma processing of 1.3 GHz single-cell cavity	Improve maximum $E_{acc}$ of field emitting cavities		
RF test in VTS			

# State-of-the-Art SRF Technology

- Exploring the limits of  $Q_0$  and  $E_{acc}$  for accelerators
  - Impurity doping, Nb<sub>3</sub>Sn, flux expulsion, plasma cleaning
- Science of RF Superconductivity
  - Manipulation of mean free path and energy gap with impurities
  - Decrease of surface resistance with increasing field
  - Flux trapping at grain boundaries and dislocations
  - Ultra-fast pulses to outpace vortex dissipation
  - $Q_0$  at tiny gradients (quantum computing)
- Auxiliaries: tuners, couplers, resonance control...
- Accelerators
  - LCLS-II
  - SRF for intensity frontier experiments at Fermilab
  - Future collider (circular or linear)

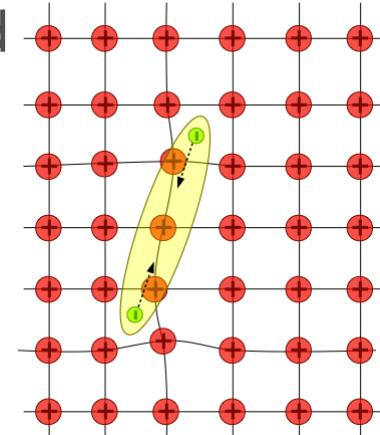
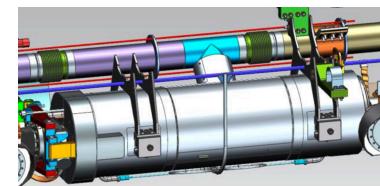


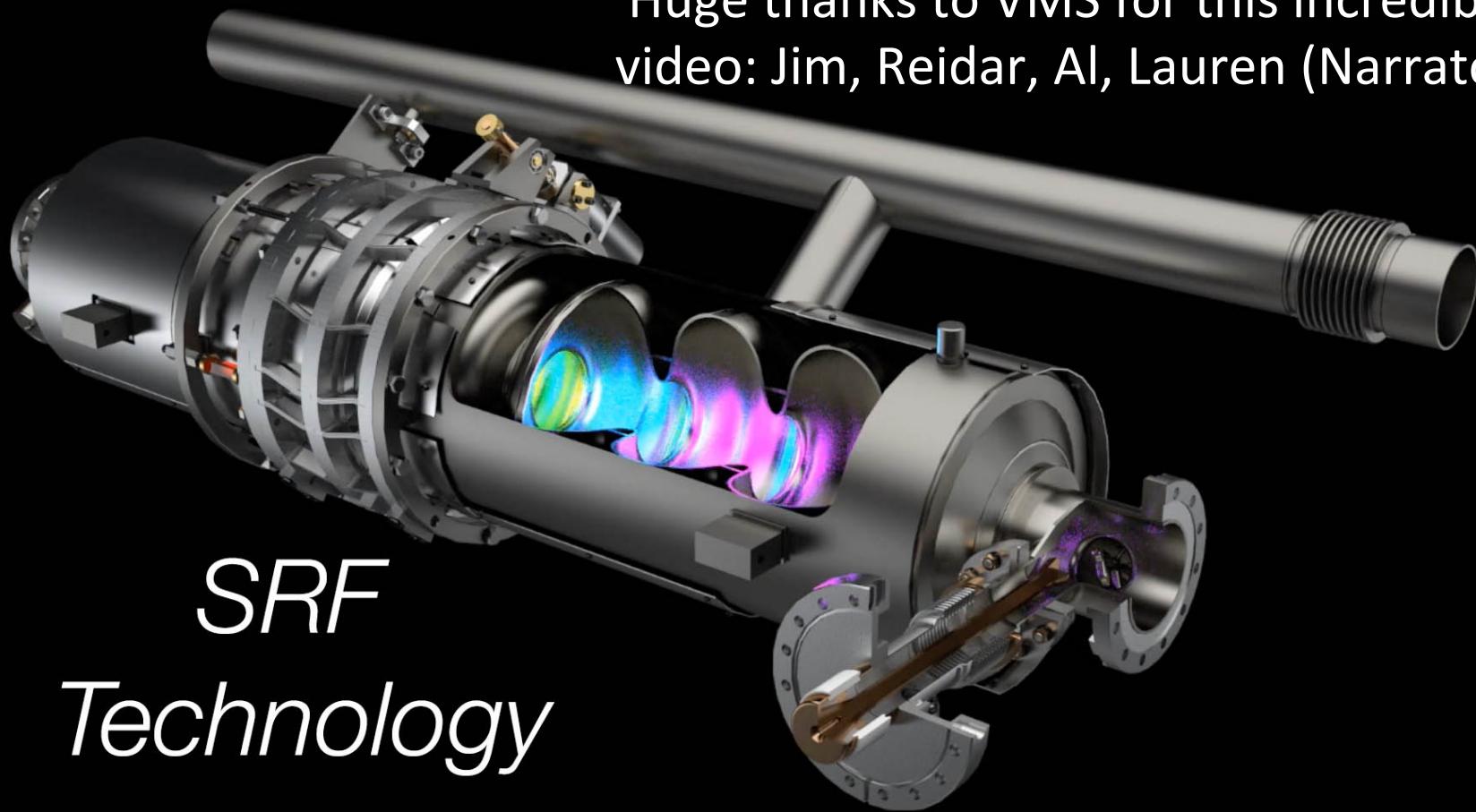
Image - arXiv:1208.5025



 Fermilab

# Video

Huge thanks to VMS for this incredible video: Jim, Reidar, Al, Lauren (Narrator)



*SRF  
Technology*

# SRF Technology Video

